Louisiana State University LSU Digital Commons

LSU Doctoral Dissertations

Graduate School

2008

Investigation of Antimonide Structure Types and the Structural Studies of Molybdates

Dixie Plaisance Gautreaux Louisiana State University and Agricultural and Mechanical College, dgautr4@lsu.edu

Follow this and additional works at: https://digitalcommons.lsu.edu/gradschool_dissertations Part of the <u>Chemistry Commons</u>

Recommended Citation

Gautreaux, Dixie Plaisance, "Investigation of Antimonide Structure Types and the Structural Studies of Molybdates" (2008). *LSU Doctoral Dissertations*. 2617. https://digitalcommons.lsu.edu/gradschool_dissertations/2617

This Dissertation is brought to you for free and open access by the Graduate School at LSU Digital Commons. It has been accepted for inclusion in LSU Doctoral Dissertations by an authorized graduate school editor of LSU Digital Commons. For more information, please contactgradetd@lsu.edu.

INVESTIGATION OF ANTIMONIDE STRUCTURE TYPES AND THE STRUCTURAL STUDIES OF MOLYBDATES

A Dissertation

Submitted to the Graduate Faculty of the Louisiana State University and Agricultural and Mechanical College in partial fulfillment of the requirements for the degree of Doctor of Philosophy

in

The Department of Chemistry

by Dixie Plaisance Gautreaux B.S., Nicholls State University, 2003 August 2008

ACKNOWLEDGEMENTS

First and foremost, I would like to thank my family for their continuous support throughout my graduate school career. To my husband, Jarred, without your support, guidance, and motivation this journey would not have been possible. To my daughter Elise Reneé, your beautiful smile and loving personality has motivated me more than anything else. Thank you to my parents, Joey and Kate Plaisance, for encouraging me to come to graduate school and supporting me in whatever I chose to do my entire life. Thanks also go to my little sister Josie Plaisance Eschete for always being there for me no matter what I needed.

I would like to thank my advisor, Professor Julia Y. Chan, for her guidance and advice throughout my years at LSU. Her belief in me as a scientist has opened many doors for me to go places I never thought I would. I am especially grateful for all of the opportunities that I was afforded as a direct result of her guidance and belief in me. I was able to travel to Colorado, San Francisco, Houston, and even Lindau, Germany to meet with some of the brightest minds in science today.

Many thanks also go to my fellow Chan group members both new and old. Special thanks go to Edem K. Okudzeto, Jung Y. Cho, and Kandace R. Thomas whom provided me with great advice and wonderful friendship throughout the years. A very special thank you also goes to Evan L. Thomas and Jasmine N. Millican who took time out of their busy schedules to teach me everything I needed to know about both research and life. Thank you to Catherine T. Alexander for our relaxing daily lunches and for being the best friend and confidant that I was lucky enough to find here at LSU.

Thanks to my committee members Professors George G. Stanley, Andrew W. Maverick, Jayne Garno, and Thomas Kutter for your advice and guidance throughout my graduate career. Special thanks to my collaborators Prof. David P. Young, Dr. Amar Karki, Dr. Monica Moldovan, Prof. John F. DiTusa, Dr. Cigdem Capan, Prof. Satoru Nakatsuji and Rieko Morisaki. Without your scientific discussions and collaborative efforts this dissertation would not be possible. Also, a very special thanks to Dr. Frank Fronczek for teaching me all you could about crystallography and always being there to answer questions even if you were buried under a pile of work! Finally I would like to thank the funding agencies that supported both myself and my research: Louisiana Board of Regents Fellowship, National Science Foundation, Alfred P. Sloan Fellowship, and Petroleum Research Fund-G.

TABLE OF CONTENTS

Acknowledgements	ii
List of Tables	vii
List of Figures	ix
Abstract	xiii
Chapter 1. Introduction	1
1.1 Research Focus	1
1.2 Synthesis	2
1.3 Characterization	4
1.3.1 Single Crystal X-Ray Diffraction	4
1.3.2 Powder X-Ray Diffraction	6
1.3.3 Neutron Powder Diffraction	7
1.3.4 Elemental Analysis	7
1.4 Property Measurements	8
1.4.1 Magnetic Property Measurements	8
1.4.2 Transport Property Measurements	9
1.5 Systems Investigated in this Document	9
1.6 References	10
Chapter 2 $LnNi(Sn Sh)_{2}$	12
2.1 Introduction	12
2.2 Experimental	12
2.2 Experimental	13
2.2.1 Synthesis	13
2.2.2 Single Crystal A-Ray Diffraction	17
2.2.5 Elemental Analysis	13
2.2.4 Thysical Property Weasurements	17
2.31 Structure	17
2.3.2 Physical Properties	
2.4 References	
Chapter 3. $CeNi_xCo_{1-x}Sb_3$	
3.1 Introduction	
3.2 Experimental	
3.2.1 Synthesis	
3.2.2 Single Crystal X-Ray Diffraction	
3.2.3 ICP-Optical Emission Spectroscopy	
3.2.4 Physical Property Measurements	
3.3 Results and Discussion	
3.3.1 Structure	
3.3.2 Physical Properties	

Chapter 4. $Ln(Cu_{1-x}Ni_x)_ySb_2$
4.1 Introduction 38 4.2 Experimental 39 4.2.1 Synthesis 39 4.2.2 Single Crystal X-Ray Diffraction 39 4.2.3 Energy Dispersive Spectroscopy 40 4.2.4 Physical Property Measurements 42 4.3 Results and Discussion 43 4.3.1 Structural Changes 43 4.3.2 Physical Properties 45 4.4 References 49 Chapter 5. Rb ₄ M(MoO ₄) ₃ 51 5.1 Introduction 51 5.2 Structural Studies by Single Crystal X-Ray Diffraction 52 5.2.1 Rb ₄ Mn(MoO ₄) ₃ 53 5.2.2 Rb ₄ Zn(MoO ₄) ₃ 56 5.2.3 Rb ₄ Cu(MoO ₄) ₃ 56
4.2Experimental394.2.1Synthesis394.2.2Single Crystal X-Ray Diffraction394.2.3Energy Dispersive Spectroscopy404.2.4Physical Property Measurements424.3Results and Discussion434.3.1Structural Changes434.3.2Physical Properties454.4References49Chapter 5. Rb ₄ $M(MoO_4)_3$ 515.1Introduction515.2Structural Studies by Single Crystal X-Ray Diffraction525.2.1Rb ₄ $M(MoO_4)_3$ 535.2.2Rb ₄ $Zn(MoO_4)_3$ 565.2.3Rb ₄ $Cu(MoO_4)_3$ 60
4.2.1 Synthesis394.2.2 Single Crystal X-Ray Diffraction394.2.3 Energy Dispersive Spectroscopy404.2.4 Physical Property Measurements424.3 Results and Discussion434.3.1 Structural Changes434.3.2 Physical Properties454.4 References49Chapter 5. Rb ₄ M (MoO ₄) ₃ 515.1 Introduction515.2 Structural Studies by Single Crystal X-Ray Diffraction525.2.1 Rb ₄ Mn(MoO ₄) ₃ 535.2.2 Rb ₄ Zn(MoO ₄) ₃ 565.2.3 Rb ₄ Cu(MoO ₄) ₃ 60
4.2.2 Single Crystal X-Ray Diffraction394.2.3 Energy Dispersive Spectroscopy404.2.4 Physical Property Measurements424.3 Results and Discussion434.3.1 Structural Changes434.3.2 Physical Properties454.4 References49Chapter 5. $Rb_4M(MoO_4)_3$ 5.1 Introduction515.2 Structural Studies by Single Crystal X-Ray Diffraction525.2.1 $Rb_4Mn(MoO_4)_3$ 535.2.2 $Rb_4Zn(MoO_4)_3$ 565.2.3 $Rb_4Cu(MoO_4)_3$ 60
4.2.3 Energy Dispersive Spectroscopy404.2.4 Physical Property Measurements424.3 Results and Discussion434.3.1 Structural Changes434.3.2 Physical Properties454.4 References49Chapter 5. $Rb_4M(MoO_4)_3$ 515.1 Introduction5.2 Structural Studies by Single Crystal X-Ray Diffraction5.2 Rb_4Zn(MoO_4)_3535.2 Rb_4Zn(MoO_4)_3565.2 3 Rb_4Cu(MoO_4)_360
4.2.4 Physical Property Measurements424.3 Results and Discussion434.3.1 Structural Changes434.3.2 Physical Properties454.4 References49Chapter 5. $Rb_4M(MoO_4)_3$ 515.1 Introduction515.2 Structural Studies by Single Crystal X-Ray Diffraction525.2.1 $Rb_4Mn(MoO_4)_3$ 535.2.2 $Rb_4Zn(MoO_4)_3$ 565.2.3 $Rb_4Cn(MoO_4)_3$ 60
4.3 Results and Discussion
4.3.1 Structural Changes
4.3.2 Physical Properties
4.4 References
Chapter 5. $Rb_4M(MoO_4)_3$.51 5.1 Introduction .51 5.2 Structural Studies by Single Crystal X-Ray Diffraction .52 5.2.1 $Rb_4Mn(MoO_4)_3$.53 5.2.2 $Rb_4Zn(MoO_4)_3$.56 5.2.3 $Rb_4Cu(MoO_4)_3$.56
5.1 Introduction 51 5.2 Structural Studies by Single Crystal X-Ray Diffraction 52 5.2.1 $Rb_4Mn(MoO_4)_3$ 53 5.2.2 $Rb_4Zn(MoO_4)_3$ 56 5.2.3 $Rb_4Cu(MoO_4)_3$ 56
5.2 Structural Studies by Single Crystal X-Ray Diffraction
5.2.1 $Rb_4Mn(MoO_4)_3$
5.2.2 $Rb_4Zn(MoO_4)_3$
$5.2.3 \text{ Bb}(Cu(MoO_1))_{a}$
5.2.5 K04Cu(W1004)3
5.3 References
Chapter 6. Conclusion
Appendix 1. Structure Determination of $LnPdSb_3$ ($Ln = La, Ce$)
A1.1 Introduction
A1.2 Experimental
A1.2.1 Synthesis Optimization
A1.2.2 Single Crystal and Powder X-Ray Diffraction
A1.3 Results and Discussion
A1.3.1 Structure
A1.4 References
Appendix 2. $EuCu_0Sn_4$ 75
A21 Introduction 75
A2.2 Experimental
A2.2 Experimental
A2.2.1 Synucsis
$\Lambda 2.2.2$ Single Crystal A-Ray Diffraction
A2.3 Results and Discussion 77
A2.3.1 Structure
A2.3.2 Physical Properties
A2.4 References

Appendix 3. Structural Determination of VB ₂	83
A3.1 Introduction	83
A3.2 Experimental and Results	83
A3.3 References	85
Appendix 4. $Y_{2-x}Ce_xTi_2O_7$	87
A4.1 Introduction	87
A4.2 Experimental and Results	87
A4.2.1 Synthesis	87
A4.2.2 Neutron Powder Diffraction	88
A4.2.3 Physical Properties	90
A4.3 References	92
Appendix 5. Unpublished Crystallographic Information Files	93
A5.1 $Rb_4Mn(MoO_4)_3$	93
A5.2 Rb ₄ Zn(MoO ₄) ₃	100
A5.3 Orthorhombic $Rb_4Cu(MoO_4)_3$	108
Appendix 6. Letters of Permission	115
Vita	120

LIST OF TABLES

Table 2.1	Crystallographic Data for $LnNi(Sn,Sb)_3$ ($Ln = Pr, Sm, Gd, or Tb$)	15
Table 2.2	Atomic Positions and Displacement Paramteres for $LnNi(Sn, Sb)_3$ ($Ln = La, Ce, Pr, Sm, Gd, or Tb; X = Sn/Sb$)	16
Table 2.3	Selected Interatomic Distances (Å) of $LnNi(Sn,Sb)_3$ ($Ln = La, Ce, Pr, Sm, Gd, or Tb; X = Sn/Sb$)	20
Table 2.4	Summary of Magnetic Susceptibility Data	23
Table 3.1	Attempted Crystal Growths of CeNi _x Co _{1-x} Sb ₃	29
Table 3.2	Crystallographic Data for α -CeNiSb ₃ and CeNi _x Co _{1-x} Sb ₃	30
Table 3.3	Atomic Positions and Displacement Parameters for CeNi _x Co _{1-x} Sb ₃	31
Table 4.1	Crystallographic Data for $Ln(Cu_{1-x}Ni_x)_ySb_2$ ($Ln = La \text{ or } Ce$)	41
Table 4.2	Atomic Positions and Displacement Parameters for $Ln(Cu_{1-x}Ni_x)_ySb_2$ ($Ln =$ La or Ce, $M =$ mixture of Ni and Cu)	41
Table 4.3	EDS Formula Compositions for $Ce(Cu_{1-x}Ni_x)_ySb_2$	42
Table 4.4	Selected Interatomic Distances (Å) and Angles (°) for $Ce(Cu_{1-x}Ni_x)_ySb_2$	45
Table 4.5	Summary of Magnetic Data for $Ce(Cu_{1-x}Ni_x)_ySb_2$ ($x = 0.8, 0.7, 0.6, and 0$)	46
Table 5.1	Crystallographic Data for Rb ₄ Mn(MoO ₄) ₃	54
Table 5.2	Atomic Positions and Displacement Parameters for Rb ₄ Mn(MoO ₄) ₃	55
Table 5.3	Crystallographic Data for Rb ₄ Zn(MoO ₄) ₃	57
Table 5.4	Atomic Positions and Displacement Parameters for Rb ₄ Zn(MoO ₄) ₃	57
Table 5.5	Selected Interatomic Distances (Å) for Rb ₄ Zn(MoO ₄) ₃	59
Table 5.6	Crystallographic Information for the Phases of Rb ₄ Cu(MoO ₄) ₃	61
Table 5.7	Atomic Coordinates and Anisotropic Displacement Parameters for Rb ₄ Cu(MoO ₄)	62
Table 5.8	Selected Interatomic Distances (Å) and Angles for Orthorhombic Rb ₄ Cu(MoO ₄) ₃	63

Table A1.1	Attempted Crystal Growths for CePdSb3	69
Table A1.2	Crystallographic Data for LaPdSb3 and CePdSb3	70
Table A1.3	Atomic Positions and Displacement Parameters for $LnPdSb_3$ ($Ln = La$ or Ce)	71
Table A2.1	Crystallographic Data for EuCu ₉ Sn ₄	76
Table A2.2	Atomic Positions and Displacement Parameters for EuCu ₉ Sn ₄	77
Table A2.3	Selected Interatomic Distances (Å) of EuCu ₉ Sn ₄ Subunits	79
Table A3.1	Crystallographic Data for VB ₂	84
Table A3.2	Atomic Positions and Displacement Parameters for VB ₂	85
Table A4.1	Experimental and Statistical Neutron Data for Y _{2-x} Ce _x Ti ₂ O ₇	88
Table A4.2	Atomic Positions and Thermal Parameters of Y _{2-x} Ce _x Ti ₂ O ₇	90

LIST OF FIGURES

Figure 1.1	Ni-Sn Phase Diagram adapted from Nash's Ni-Sn Binary Alloy Phase Diagram	3
Figure 1.2	Illustration of powder diffractometer geometry and sample holder	7
Figure 2.1	Polyhedral representation of α -CeNiSb ₃ and CeNi(Sb,Sn) ₃ , where the yellow spheres are the Ce atoms, the maroon spheres are Sb or (Sb,Sn) atoms, the green striped polyhedra are Ni1 octahedra, and the dark green polyhedra are Ni2 octahedra.	18
Figure 2.2	Environment of Ln sites of Ln Ni(Sn,Sb) ₃ as viewed down the <i>b</i> -axis. $Ln1$ adopts a square anti-prismatic environment, while $Ln2$ adopts a mono- capped square anti-prism.	19
Figure 2.3	Plot of Ln -X (X = Sn,Sb) distances as a function of lanthanide for both α - LnNiSb ₃ and Ln Ni(Sn,Sb) ₃	20
Figure 2.4	Magnetic susceptibility as a function of temperature between 2 K - 300 K for PrNi(Sn,Sb) ₃ ($H = 0.1$ T), NdNi(Sn,Sb) ₃ ($H = 0.5$ T), SmNi(Sn,Sb) ₃ ($H = 1$ T), and GdNi(Sn,Sb) ₃ ($H = 1$ T) where the red triangles, blue circles, green diamonds, and black squares refer to PrNi(Sn,Sb) ₃ , NdNi(Sn,Sb) ₃ , SmNi(Sn,Sb) ₃ , and GdNi(Sn,Sb) ₃ , respectively. The inset displays the magnetic measured at an applied field of 0.1 T of a 1.99mg single crystal of β -CeNiSb ₃ in three directions. The inset is the inverse susceptibility of the same plot. The data for SmNi(Sn,Sb) ₃ has been multiplied by 100 to fit the scale	21
Figure 2.5	Field dependent magnetization of single crystals of CeNi(Sn,Sb) ₃ ($T = 2$ K), PrNi(Sn,Sb) ₃ ($T = 5$ K) and NdNi(Sn,Sb) ₃ ($T = 4$ K), SmNi(Sn,Sb) ₃ ($T = 4$ K) and GdNi(Sn,Sb) ₃ ($T = 4$ K) where the purple open triangles, red triangles, blue circles, green diamonds, and black squares refer to CeNi(Sn,Sb) ₃ , PrNi(Sn,Sb) ₃ , SmNi(Sn,Sb) ₃ , NdNi(Sn,Sb) ₃ and GdNi(Sn,Sb) ₃ , respectively The data for the Sm- and Gd-analogues have been multiplied by 10 to fit the scale.	23
Figure 2.6	Temperature dependent resistivity of single crystals of $LnNi(Sn,Sb)_3$ ($Ln = La$, Ce, Pr, Nd, Sm, Gd) where the orange open diamonds, purple open triangles, red triangles, blue circles, green diamonds, and black squares refer to LaNi(Sn,Sb) ₃ , CeNi(Sn,Sb) ₃ , PrNi(Sn,Sb) ₃ , NdNi(Sn,Sb) ₃ , SmNi(Sn,Sb) ₃ , and GdNi(Sn,Sb) ₃ , respectively	25
Figure 2.7	Magnetoresistance of single crystals of $PrNi(Sn,Sb)_3$ (5 K), $NdNi(Sn,Sb)_3$ (5 K), $SmNi(Sn,Sb)_3$ (5 K), and $GdNi(Sn,Sb)_3$ (5 K). The purple open triangles, red triangles, blue circles, green diamonds, and black squares	

	refer to β -CeNiSb ₃ , PrNi(Sn,Sb) ₃ , NdNi(Sn,Sb) ₃ , SmNi(Sn,Sb) ₃ , and GdNi(Sn,Sb) ₃ , respectively. The data for β -CeNiSb ₃ (3 K) is located in the inset of the plot.	25
Figure 3.1	The structure of $\text{CeNi}_x\text{Co}_{1-x}\text{Sb}_3$ viewed down the <i>b</i> -axis. The yellow spheres represent Ce atoms, blue and green spheres represent Ni/Co atoms, and maroon spheres represent Sb atoms	32
Figure 3.2	X-ray diffraction powder patterns of CeNi _x Co _{1-x} Sb ₃ and α -CeNiSb ₃ . The pattern on the left is the full spectrum for each compound and the pattern to the right displays the shift seen in the 400 peak	33
Figure 3.3	The magnetic susceptibility (χ vs T) measured at an applied field of 0.2 T of CeNi _{0.780} Co _{0.220} Sb ₃	34
Figure 3.4	The magnetization as a function of field (M vs H) measured at 3 K of $CeNi_{0.780}Ce_{0.220}Sb_3$	34
Figure 3.5	The resistivity of CeNi _{0.780} Co _{0.220} Sb ₃ measured between 2 and 290 K	35
Figure 3.6	The magnetoresistance of CeNi _{0.780} Ce _{0.220} Sb ₃ at 3 K taken from 0 to 9 T	36
Figure 4.1	Crystal structure of $Ce(Cu_{1-x}Ni_x)_ySb_2$ as viewed down the <i>b</i> -axis where the yellow spheres refer to the Ce atoms, the green spheres refer to a mixture of Ni and Cu atoms and the maroon spheres refer to the Sb atoms	44
Figure 4.2	Magnetic susceptibility of Ce(Cu _{1-x} Ni _x) _y Sb ₂ measured at a field of 0.1 T where the green circles, black squares, blue triangles, and red diamonds refer to $x = 0, 0.25, 0.37$, and 0.46 respectively. The inset displays a close-up of the susceptibility from 2 – 20 K.	45
Figure 4.3	Magnetism of Ce(Cu _{1-x} Ni _x) _y Sb ₂ measured at 3 K where the green circles, black squares, blue triangles, and red diamonds refer to $x = 0, 0.25, 0.37$, and 0.46 respectively	47
Figure 4.4	Resistivity of Ce(Cu _{1-x} Ni _x) _y Sb ₂ where the green circles, black squares, blue triangles, and red diamonds refer to $x = 0, 0.25, 0.37, and 0.46$ respectively	48
Figure 4.5	Magnetoresistance of Ce(Cu _{1-x} Ni _x) _y Sb ₂ measured at 3 K where the green circles, black squares, blue triangles, and red diamonds refer to $x = 0, 0.25, 0.37, and 0.46$ respectively	48
Figure 4.6	Magnetoresistance of La(Cu _{1-x} Ni _x) _y Sb ₂ (nominal $x = 0.8$) measured at 3 K	49
Figure 5.1	Experimental (red) and calculated (black) powder patterns for Rb ₄ Mn(MoO ₄) ₃	53

Figure 5.2	(a) Crystal structure of $Rb_4Mn(MoO_4)_3$ where the blue, green, purple, and red spheres refer to Rb, Mn, Mo, and O atoms respectively. (b) The Mn bonding environment of $Rb_4Mn(MoO_4)_3$
Figure 5.3	(a) Crystal structure of $Rb_4Zn(MoO_4)_3$ as viewed down the <i>a</i> axis where the blue, green, purple, and red spheres refer to Rb, Zn, Mo, and O atoms respectively. (b) Zn bonding environment of $Rb_4Zn(MoO_4)_3$
Figure 5.4	(a) Crystal structure of $Rb_4Cu(MoO_4)_3$ as viewed down the <i>c</i> -axis where the blue, green, purple, and red spheres refer to Rb, Cu, Mo, and O atoms respectively. (b) Cu distorted square planar bonding environment of $Rb_4Cu(MoO_4)_3$
Figure A1.1	Crystal structure of <i>Ln</i> PdSb ₃ where the yellow spheres refer to the La or Ce atoms, the maroon spheres refer to the Sb atoms and the purple polyhedral refer to the distorted Pd octahedra
Figure A2.1	(a) Crystal structure of $EuCu_9Sn_4$ viewed down the <i>b</i> axis. (b) Images of environments of Cu3 icosahedra and Eu distorted snub-cubes
Figure A2.2	Magnetic Susceptibility of EuCu ₉ Sn ₄ measured with an applied field of 0.1 T from $2 - 300$ K. Data from $2 - 50$ K were shown to enhance the ordering seen below 20 K. The inset displays the inverse susceptibity79
Figure A2.3	Magnetization of EuCu ₉ Sn ₄ as a function of field measured at 2 K80
Figure A2.4	Resistivity measurements of EuCu ₉ Sn ₄ as a function of temperature measured at 0 T, 0.05 T, and 9 T81
Figure A2.5	Change in resistivity of $EuCu_9Sn_4$ from 0 T to 9 T measured with field oriented in two directions: parallel to the <i>ab</i> plane and parallel to the <i>c</i> axis
Figure A3.1	(a) Layered crystal structure of VB_2 viewed in the [110] direction. (b) View down the <i>c</i> -axis of the crystal structure of VB_2
Figure A4.1	Neutron powder diffraction patterns of (a) $Y_2Ti_2O_7$, (b) $Y_{1.66}Ce_{0.34}Ti_2O_7$, and (c) $Y_{1.37}Ce_{0.63}Ti_2O_7$ where the red crosses are the observed NPD pattern, solid black tick marks are the calculated NPD profiles of $Y_{2-x}Ce_xTi_2O_7$, solid red tick marks are the calculated NPD profiles of rutile TiO ₂ , and magenta patterns are the difference NPD profiles for $Y_{2-x}Ce_xTi_2O_7$
Figure A4.2	Magnetic susceptibility of $Y_{1.66}Ce_{0.3394}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ measured at 0.1 T where the red triangles and blue circles are $Y_{1.66}Ce_{0.34}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ respectively

Magnetization of Y _{1.66} Ce _{0.3394} Ti ₂ O ₇ and Y _{1.37} Ce _{0.63} Ti ₂ O ₇ measured at 3 K	
where the red triangles and blue circles are $Y_{1.66}Ce_{0.34}Ti_2O_7$ and	
$Y_{1.37}Ce_{0.63}Ti_2O_7$ respectively	91
	Magnetization of $Y_{1.66}Ce_{0.3394}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ measured at 3 K where the red triangles and blue circles are $Y_{1.66}Ce_{0.34}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ respectively

ABSTRACT

This dissertation highlights the investigation of ternary lanthanide antimonide structure types and their physical properties. In particular, these ternary phases allow for the systematic investigation of the structure in an effort to correlate structure and properties. The ternary antimonides are layered structures with two-dimensional square sheets or nets, which influence the properties of these materials. In an effort to determine how structural changes influence the physical properties, various single crystals of compounds relating to the orthorhombic CeNiSb₃ structure have been grown and characterized. The layered CeNiSb₃ structure consists of Sb sheets, NiSb₆ distorted octahedra, and CeSb₉ monocapped square anti-prisms. *Ln*Ni(Sn,Sb)₃ and *Ln*PdSb₃ differ slightly from the CeNiSb₃ structure in the packing of the transition metal layer. The structures and physical properties of *Ln*Ni(Sn,Sb)₃ (*Ln* = La-Nd, Sm, Gd, Tb) are studied as a function of lanthanide. The stability of the CeNiSb₃ structure was investigated by the substitution of Co or Cu for Ni in CeNiSb₃ resulting in CeNi_xCo_{1-x}Sb₃ and *Ln*(Ni_{1-x}Cu_x)_ySb₂ compounds. Also, the effect of Ni substitution for Cu in Ce(Cu_{1-x}Ni_x)Sb₂ ($0 \le x \le 0.8$) compounds on the magnetoresistance is investigated.

This dissertation also explores the different structure types of molybdates $Rb_4M(MoO_4)_3$ (M = Mn, Zn, and Cu). Each analogue adopts a different structure type and contain similar subunits. The full structure determinations of each of these compounds are important to be able to understand the promising magnetic and electrical properties.

CHAPTER 1 – INTRODUCTION

1.1 Research Focus

Our research focus is on the interface of chemistry and physics, specifically the solidstate crystal growth of various materials for structure determination and physical properties of the new materials. One of our primary goals is to identify structural features in extended solids that favor signature behaviors such as magnetoresistance, superconductivity, heavy-fermions, electrocatalysts, and multiferroics. Gaining a better understanding of structural effects on the physical properties of highly correlated compounds will help enable the rational design of materials of the future.

The growth of high quality single crystals is essential to the discovery of new materials and their applications. Only with high quality single crystal can detailed property measurements be done. As Paul Canfield states, "the key is to search for materials with specific properties in a phase space that favors finding such compounds."¹ This directly refers to our goal of understanding structural features that may be predominate in materials that possess the desired properties. Once specific structural features have been identified, tuning of the physical properties of that material can begin by methods such as applying chemical pressure by substitution or doping other elements into the structure.

Many antimonides also possess unique structural features such as two-dimensional square sheets or nets and highly layered structures, which promote unusual physical properties.² Ternary rare earth (Ln) - transition metal - antimonides display unusual bonding and interesting physical properties such as magnetoresistance. In particular, these ternary phases allow one to study the systematics in an effort to correlate structure and properties. The magnetic rare earth element contributes to the magnetism and the coupling of *f*-electrons with a transition metal sublattice may lead to exotic properties. The transition metal adds conduction electrons to the magnetic structure as well as another structural layer. The addition of the main group element antimony, which resides along the metal – insulating border, makes this phase space attractive to investigate.

1.2 Synthesis

Crystal growth requires significant planning involving starting materials, the temperature profile, reaction vessel, and the stoichiometric ratios of each element involved. The primary crystal growth technique used in our lab is the self flux growth method, where the flux is a specific metal that acts as a "solution" to allow the melting of the other elements at high temperatures. The flux should melt at relatively low temperatures relative to the high melting metals so that the reaction mixture can be cooled to allow the desired phase to crystallize out of solution.³ As the melt is slowly cooled, the desired phase will crystallize and excess flux can be removed via centrifugation or chemical etching.^{3,4}

Other parameters to consider include atmosphere, the heat treatment of the sample, as well as the container used during the growth. Most metals will oxidize in high temperature environments so it is important to have an oxygen-free atmosphere. At or N_2 atmospheres are generally used to ensure that no O_2 is present within the sample. The reaction vessel used in the reaction must not react with any of the elements present and also must not melt at the temperatures achieved in the reaction. Examples of typical reaction vessels include Ta, Al_2O_3 , Nb, Mo, steel, or W crucibles.⁵ The crucible may then be sealed in a fused silica tube under an inert atmosphere.³

Phase diagrams are useful guides for determining stoichiometric ratios. To avoid unwanted binaries when synthesizing a ternary phase, temperatures and compositions of binary phases must be determined. If a ternary phase involving Ce-Ni-Sb is to be synthesized using Sn flux, one should consider the examination of Ce-Ni, Ni-Sb, Ce-Sb, Ce-Sn, Ni-Sn, and Sb-Sn phase diagrams. Figure 1.1 shows the Ni-Sn binary temperature-composition phase diagram.⁶ To avoid the synthesis of Ni_3Sn_4 , the molar ratio of Sn should be high enough for the reaction to be in the liquidus state. We note that Sn melts at 232 °C, and hence to only isolate the desired phase without Sn encapsulation, one would either remove the reaction from the furnace above the melting point of Sn or etch the Sn from the surface of the samples.

An alternative to the flux growth method commonly used in our laboratory is an arcmelting technique. Arc-melting is essentially a "brute-force" welding technique. This technique



Figure 1.1 Ni-Sn Phase Diagram adapted from Nash's Ni-Sn Binary Alloy Phase Diagram

is sometimes used when multiple flux-growth experiments have not yielded the desired results. It is also an easy way to bypass the thermodynamic effects that allow undesired phases to form in your reaction mixture. Constituent elements are weighed out on stoichiometry to the desired phase. The elements are then placed together in an electric arc which rapidly melts and binds the elements together into a button. Then, the arc-melted button is annealed at high temperatures under vacuum in our furnaces. Occasionally, single crystals are obtained directly from the annealing process. However, most samples obtained from this method are polycrystalline in nature. Typically, the polycrystalline sample is then placed in an alumina crucible and a flux is then added and the reaction vessel undergoes the flux-growth method described above.

Another synthetic technique is used to synthesize polycrystalline oxide samples. Samples are prepared using a combination of grinding and mixing the constituent oxide powders. The amounts of oxide powder used are based on the stoichiometry of a solid – state reaction yielding the desired product. The resulting mixture is then pressed into a small pellet. The pellet is then heat treated at high temperatures for a predetermined period of time. The resulting pellet is then ground and remixed again followed by a higher temperature heat treatment. Between each heat treatment, a powder XRD pattern is taken to identify the phase. This process is continued until the solid solution is reached with no unreacted oxides remaining. The unreacted oxides show up as extra peaks in the XRD powder pattern. This technique typically yields only polycrystalline samples.

1.3 Characterization

1.3.1 Single Crystal X-Ray Diffraction

Single crystal X-ray diffraction is an indispensable technique for determining the crystal structure of highly crystalline compounds. A beam of X-rays are collinated at the sample and after impact, the X-rays are scattered in various directions by the electrons and atoms in the lattice.⁷ When Bragg's law ($\lambda = 2d\sin\theta$, where λ is the wavelength of the X-rays, *d* is the distance between adjacent planes, and θ is the Bragg angle) is satisfied, diffraction occurs.⁸ The scattered X-rays are then recorded by a detector. X-rays are a form of electromagnetic radiation and possess both amplitude and a phase. The current detectors can record only the amplitude, so

only half of the diffraction information needed to calculate electron density is recorded. This is a well known problem known as the "Phase Problem". Different techniques have been developed to overcome the phase problem, and direct methods is the technique used in our group to solve our structures. Space group, lattice parameters, and atomic positions are obtained from successfully refined structural models. Structural information such as bond distances, bond angles, site occupancy, and disorder can also be acquired and are invaluable to fully understanding the structure.

The Enraf Nonius Kappa CCD Diffractometer was used for all single crystal work in this document. The X-rays are generated by a Mo K_{α} X-ray tube where $\lambda = 0.71073$ Å. A crystal is mounted onto the tip of a glass fiber of the goniometer with epoxy and/or vacuum grease. Temperature is regulated with a cooled nitrogen gas stream produced by an Oxford Cryostream Cooler. The unit cell parameters were determined from images taken at a rotation of 15 ° φ . The structures were solved using the SIR97 direct methods program.⁹ The preliminary model of the structures were then refined using the SHELXL97 program package.¹⁰ Refinement of the model of the structure allows for the correction of many aspects of a crystal structure such as the addition of extinction coefficients, anisotropic parameters, size, temperature, site occupancy, and disorder. This part of the process can produce the most correct model for that particular structure based on the data collected.

Occasionally special sample handling is necessary, particularly if the crystals are airsensitive or hygroscopic. In these cases, air exposure must be limited to protect the integrity of the crystals. The crystals are placed in either mineral oil or paratone-N oil to protect the crystal surface. Typically, a cooled nitrogen gas stream produced by an Oxford Cryostream Cooler is used to regulate the temperature of the crystal. For sensitive crystals, the cooled nitrogen gas stream serves as an additional protective barrier and is used even for room temperature data collections. At low temperatures (typically below 250 K) the epoxy used to secure the crystal to the tip of the goniometer becomes brittle. For low temperature data collections, the crystal is simply placed on the tip of the goniometer using either mineral oil or Paratone-N oil. Both of these oils harden at low temperatures and do not allow the crystal to move while on the tip of the goniometer. Low temperature data collections are typically used to search for phase transitions. However, low temperature data is sometimes better than room temperature because the thermal vibrations of atoms within the crystal are reduced at lower temperatures.

1.3.2 Powder X-Ray Diffraction

Each crystalline sample has a unique powder diffraction pattern. X-ray powder data are displayed as a pattern with intensity as a function of 2θ . The angles are dependent on the lattice parameters, lattice type, and wavelength of radiation. The intensity of each peak is dependent on the scattering of the elements present as well as the amount of sample. Most samples are compared to the powder patterns in the database from the Joint Committee on Powder Diffraction Standards (JCPDS) to check for known phases. An unknown sample can be identified by comparing the pattern to a calculated pattern from a refined model of the new structure.

X-ray powder diffraction data were collected on a Bruker D8 Advance Powder Diffractometer with monochromatic Cu K_{α} radiation ($\lambda = 1.540562$ Å) at room temperature. Data analysis was accomplished using DIFFRAC^{*plus*} Evaluation Program.¹¹ The ground, polycrystalline sample is placed onto a no-background holder. It is essential that the powder sample be flat to avoid errors associated with sample displacement. Figure 1.2 shows the setup of a powder diffractometer as well as the no-background sample holder used to collect data.



Figure 1.2 Illustration of powder diffractometer geometry and sample holder

1.3.3 Neutron Powder Diffraction

Neutron powder diffraction is a complementary technique used when X-ray diffraction cannot provide sufficient information. The scattering power of neutrons is advantageous because the atomic nuclei rather than the electrons are responsible for scattering the radiation. It is extremely useful in locating light atoms and is able to distinguish between atoms that have similar scattering. Magnetic structure analysis is also possible with neutron powder diffraction because the magnetic dipole moment of neutrons may interact with unpaired electrons in the structure. Neutron powder diffraction (NPD) data were collected at National Institute of Standards and Technology (NIST) Center for Neutron Research on the powder diffractometer BT-1. A Cu(311) monochromator with a wavelength (λ) of 1.5403 Å was used.

1.3.4 Elemental Analysis

Because X-ray diffraction cannot distinguish between elements with similar *Z*, alternative characterization techniques must be used. The first elemental analysis method used is inductively coupled plasma-optical emission spectroscopy (ICP-OES) on a Perkin Elmer Optima Model 5300V. The plasma excites each of the atoms present and upon relaxation light is emitted and with a polychromatic detector, the amount of each element present can be determined. The second elemental analysis method employed is energy dispersive spectroscopy. A Hitachi S-3600N extra-large chamber variable pressure Scanning Electron Microscope (VP-SEM) with an

integrated energy dispersive (EDS) feature was used to collect data. The electrons at ground state are excited by the beam and an electron from the inner shell is ejected. Then a higherenergy electron fills the hole left by the inner shell electron and an X-ray is emitted which has characteristics specific to the element from which it was emitted. This technique is capable of giving quantitative elemental information and is an excellent complementary technique to X-ray crystallography.

1.4 Property Measurements

1.4.1 Magnetic Property Measurements

Magnetic susceptibility data (M vs T) were measured by a Quantum Design Physical Property Measurement System, where M is the magnetization and T is the temperature. Inverse susceptibility data above the ordering temperature are fitted to Curie-Weiss law to obtain the magnetic moment and the Weiss temperature, θ .¹² The Curie Weiss law is $\chi = \frac{M}{H} = \frac{C}{T - \theta}$, where χ is the magnetic susceptibility, C is the Curie constant, T is the temperature, and θ is the Weiss constant. Occasionally, a modified version of this law is used when the inverse susceptibility deviates from Curie-Weiss behavior and an additional constant, χ_0 , is subtracted from the magnetic susceptibility. The modified Curie-Weiss equation is $\chi - \chi_0 = \frac{M}{H} = \frac{C}{T - \theta}$, where χ_0 is the temperature-independent contribution to the susceptibility. For most of the magnetic materials in this document χ_0 is negligible.

The magnetization as a function of field (*M* vs *H*) was also measured by a Quantum Design Physical Property Measurement System, where *M* is the magnetization and *H* is the applied magnetic field. The saturation moment from this data is compared to a calculated value. The calculated saturation moment, $\mu_{sat} = -g\mu_B \mathbf{J}$, where *g* is given by the Landé equation, μ_B is a bohr magneton, and **J** is the sum of the orbital and spin angular momenta.¹² The Landé equation is defined as $g = 1 + \frac{J(J+1) + S(S+1) - L(L+1)}{2J(J+1)}$ for a free atom. Typically, the magnetization

curve for a ferromagnet displays hysteresis.

1.4.2 Transport Property Measurements

Resistivity as a function of temperature is typically measured on a single crystal and is defined as the resistance generated by collisions of electrons with phonons or impurities in the crystal lattice.¹² Electrical resistivity is defined as $\rho = R \frac{A}{L}$, where *R* is the resistance, *A* is the area of the crystal, and *L* is the length of the crystal. A sudden drop in the resistivity to zero indicates a superconducting transition. Identifying and understanding materials with these superconducting transitions may lead to the design of materials with superconducting behavior at room temperature. Magnetoresistance is defined as $\frac{\rho - \rho_0}{\rho_0} \times 100\%$ and is plotted as a function of changing field.¹² The magnetoresistance of a typical metal is on the order of ~10 %. Materials that possess larger magnetoresistance behavior at room temperature have potential applications as various spintronic materials. Understanding both of these transport property behaviors are important in understanding and designing new materials.

1.5 Systems Investigated in This Document

The systems that are discussed in this dissertation focus on the structural studies of selected antimonides and double molybdates. Chapter 2 will focus on the synthesis, structure determination, and physical properties of $LnNi(Sb,Sn)_3$ (Ln = La-Nd, Sm, Gd, Tb). The relationship of this structure type to other similar antimonide structure types will be explored. Chapter 3 will discuss the ramifications of substituting Co for Ni in both the structure and physical properties of CeNi_xCo_{1-x}Sb₃. Chapter 4 involves the systematic substitution of Ni for Cu in Ce(Cu_{1-x}Ni_x)_ySb₂ and focuses on the effects on the magnetoresistance behavior. Structural

effects and magnetic properties are also explored. Chapter 5 presents a structural study of the effects of transition metal substitution of double molybates $Rb_4M(MoO_4)_3$ (M = Mn, Zn, and Cu). The Zn and Cu analogues both adopt new structure types. Temperature dependent phase transitions are explored for all analogues. Chapter 6 provides brief conclusions and general overview of the dissertation. The appendices include structural studies of various side projects. Appendix 1 focuses on the structural determination of $LnPdSb_3$, which is a new structure type. Appendix 2 discusses the structure and physical properties of $EuCu_9Sn_4$. Appendix 3 presents the structural confirmation of VB_2 . Accurate lattice parameters were necessary for energy band calculations. Appendix 4 provides structural data from neutron powder diffraction and magnetic properties of $Y_{2-x}Ce_xTi_2O_7$. Appendix 5 contains unpublished crystallographic information files for the molybdates discussed in Chapter 5. Letters of permission to reuse published work are provided in Appendix 6.

1.6 References

- (1) Canfield, P. C. *Nature* **2008**, *4*, 167-169.
- (2) Papoian, G. A.; Hoffmann, R. Angew. Chem. Int. Ed. 2000, 39, 2409-2448.
- (3) Canfield, P. C.; Fisk, Z. *Philos. Mag. B* **1992**, *65*, 1117-23.
- (4) Kanatzidis, M. G.; Pöttgen, R.; Jeitschko, W. Angew. Chem. Int. Ed. 2005, 44, 6996-7023.
- (5) Fisk, Z.; Remeika, J. P. *Handbook on the Physics and Chemistry of Rare Earths*; Elsevier: Amsterdam, 1989; Vol. 12.
- (6) Nash, P.; Nash, A. Bull. Alloy Phase Diagrams 1985, 6, 350-359.
- (7) Cullity, B. D. *Elements of X-Ray Diffraction*; 2nd ed.; Addison-Wesley Publishing Company, Inc: Reading, Massachusetts, 1978.
- (8) Clegg, W.; Blake, A. J.; Gould, R. O.; Main, P. *Crystal Structure Analysis Principles and Practice*; Oxford University Press: Oxford, NY, 2001.

- Altomare, A.; Burla, M. C.; Camalli, M.; Cascarno, G. L.; Giacovazzo, A.; Guagliardi, A.; Moliterni, A. G. G.; Polidori, G.; Spagna, R. J. J. Appl. Crystallogr. 1999, 32, 115-119.
- (10) Sheldrick, G. M.; University of Gottingen: Germany, 1997.
- (11) 6.0 ed.; Bruker, AXS: Karlsruhe, West Germany, 2000.
- (12) Kittel, C.; 7th ed.; John Wiley & Sons, Inc.: New York, 1995.

CHAPTER 2 – *Ln*Ni(Sn,Sb)₃

2.1 Introduction

Ternary rare earth antimonides show unusual bonding and interesting physical properties such as large magnetoresistance and Kondo behavior.¹⁻³ The systematic studies of these ternary phases allow correlation of structure and properties. Structural features such as two-dimensional square sheets or nets and highly layered structures promote unusual physical properties.⁴ The Ce, Pr, Nd and Sm analogues of *Ln*CrSb₃, which crystallize in the orthorhombic space group *Pbcm* with lattice parameters of $a \sim 12$ Å, $b \sim 6$ Å, $c \sim 6$ Å, each display two different magnetic transitions due to the Cr and lanthanide sublattices.⁵⁻¹⁰ However, the Gd, Tb, and Dy analogues of *Ln*CrSb₃ each show only one magnetic transition due to the lanthanide.^{6,11,12} YbCrSb₃, where Yb is divalent, was found to have a long range ferromagnetic ordering at $T_{\rm C} \sim 280$ K.¹⁴ α -CeNiSb₃, which crystallizes in the orthorhombic space group *Pbcm* with lattice parameters of *a* ~12 Å, $b \sim 6$ Å, $c \sim 18$ Å, orders ferromagnetically at 6 K while the other lanthanide analogues of α -*Ln*NiSb₃ (*Ln* = Pr, Nd and Sm) all order antiferromagnetically below 5 K.¹⁵⁻¹⁷ The Dy and Ho analogues of the layered *Ln*NiSb₂ display large magnetoresistance (MR) of ~ 115 % and ~ 165 % respectively, while the Y analogue is linear up to ~150 % at 3 K and 9 T.¹⁸

Tin flux was used in our efforts to grow larger crystals of CeNiSb₃ for magnetic and transport measurements and a new polymorph of this phase was discovered, previously known as β -CeNiSb₃.¹⁹ β -CeNiSb₃ adopts the CePdSb₃ structure type with the orthorhombic space group *Pbcm* and lattice parameters $a \sim 12$ Å, $b \sim 6$ Å, $c \sim 12$ Å.^{20,21} β -CeNiSb₃ orders ferromagnetically below 6 K and Kondo lattice behavior is observed.¹⁹ To determine the structural stability of this structure type, we grew several lanthanide analogues. Further

¹³ Portions of this chapter reprinted by permission of Elsevier: Gautreaux, D.P.; Capan, C.; DiTusa, J.F.; Young, D.P.; Chan, J.Y.; "Synthesis, structure, and physical properties of $LnNi(Sn,Sb)_3$ (Ln = Pr, Nd, Sm, Gd, Tb)", *J. Solid State Chem.* **2008**, In Press.

investigation of this structure led to the discovery that Sn was incorporated into the crystal structure. The crystal growth, structure, magnetic properties of $LnNi(Sn,Sb)_3$ (Ln = La, Ce, Pr, Nd, Sm, Gd, and Tb) are reported herein.

2.2 Experimental

2.2.1 Synthesis

Single crystals of *Ln*Ni(Sn,Sb)₃ (*Ln* = La, Ce, Pr, Nd, Sm, Gd, or Tb) were prepared using excess Sn as the flux. La, Ce, Pr, Nd, Sm, Gd, or Tb pieces (99.9%, Alfa Aesar), Ni powder (99.999%, Alfa Aesar), Sb shot (99.999%, Alfa Aesar), and Sn shot (99.8%, Alfa Aesar) were placed in an alumina crucible in a 1:2:3:15 molar ratio. The crucible was sealed into an evacuated fused-silica tube. The reaction vessel was heated to 1150 °C where the temperature was held constant for 24 h and then cooled 5 °C h⁻¹ to 300 °C. After dwelling at 300 °C, the excess Sn flux was removed by centrifugation. The reaction mixtures contained silver plate-like crystals with dimensions up to 0.08 x 3 x 5 mm³ for all analogues except Tb which contained plate-like crystals with dimensions up to 0.08 x 0.5 x 0.5 mm³. Most samples also contained silver rod shaped crystals with dimensions of 1 x 1 x 5 mm³. The plates were determined to be the desired product, while the predominant phase is the rod-shaped binary, Ni₃Sn₄. When exposed to air and moisture, there is no visible surface degradation to both compounds over a period of months.

Flux growth syntheses with other molar ratios such as 1:1:3:20 and 1:1:3:15 for the latter rare earth analogues with Sn flux were investigated; however, yield was less than 10%. The addition of excess Ni (1:2:3:15) resulted in an increased yield of *Ln*Ni(Sn,Sb)₃. We note that smaller lanthanide metals, Dy and Yb, yielded binary phases. Adjusting the spin temperature from 300 °C to 670 °C or 450 °C, also yielded different results. At 670 °C, CeNi(Sn,Sb)₃ and CeSb were obtained while at 450 °C CeNi(Sn,Sb)₃, CeSb, and Ni₃Sn₄ were obtained. However,

the yield of the desired CeNi(Sn,Sb)₃ was lower at both 670 °C and 450 °C than at 300 °C. Arcmelting the constituent elements Ce, Ni, and Sb (1:1:3) without Sn yields the α -CeNiSb₃ structure type, therefore α -CeNiSb₃ must be a line compound. Arc-melting Ce:Ni:Sb with 5 or 10% Sn followed by annealing at 1150 °C for 3 days in an evacuated fused-silica tube, allows for the substitution of Sn within the α -CeNiSb₃ structure. This is determined by an increase of the lattice parameters obtained from single-crystal X-ray diffraction. Single crystals of α -CeNiSb₃ can be "transformed" into CeNi(Sn,Sb)₃.¹⁹ Unground single crystals of α -CeNiSb₃ were placed into an alumina crucible with a 20 fold excess of Sn flux. After placing the crucible into an evacuated fused-silica tube, the reaction vessel underwent the heat treatment described above and was removed from the furnace at 300 °C. Approximately half of the crystals were "transformed" into CeNi(Sn,Sb)₃ while the other half maintained the α -CeNiSb₃ structure type. These results were confirmed by single crystal X-ray diffraction.

2.2.2 Single Crystal X-ray Diffraction

A typical crystal with dimensions of ~ 0.08 x 0.08 x 0.1 mm³ was mounted onto a glass fiber of a goniometer with epoxy and placed on a Nonius Kappa CCD X-ray diffractometer (MoK_a = 0.71073 Å). Data collection parameters and crystallographic data are listed in Table 2.1 for $LnNi(Sn,Sb)_3$ (Ln = Pr, Sm, Gd, Tb). The unit cell parameters were determined from images taken at a rotation of 15 ° φ . The model of the structure was refined by direct methods using SHELXL97.²² The data were corrected for absorption and the displacement parameters were refined as anisotropic. Atomic coordinates and anisotropic displacement parameters are provided in Table 2.2. The R-factors for all compounds are reasonable with the exception of the Nd analogue. After multiple data collections, it was determined that this analogues has lower crystal quality based on higher chi² values.

	La	Ce	Pr	Nd	Sm	Gd	Tb
Space Group	Pbcm	Pbcm	Pbcm	Pbcm	Pbcm	Pbcm	Pbcm
<i>a</i> (Å)	13.0970(2)	12.9170(2)	12.843(3)	12.771(2)	12.651(1)	12.565(2)	12.450(1)
b (Å)	6.1400(4)	6.1210(5)	6.105(7)	6.093(4)	6.083(2)	6.072(3)	6.060(2)
<i>c</i> (Å)	12.1270(4)	12.0930(6)	12.056(6)	12.021(4)	11.994(2)	11.973(4)	11.935(2)
$V(\text{\AA}^3)$	975.20(4)	956.13(9)	945.3(12)	935.4(7)	923.0(3)	913.5(6)	900.5(3)
Size (mm ³)	0.02/0.05/0.05	0.08/0.08/0.1	0.01/0.04/0.05	0.08/0.08/0.01	0.01/0.03/0.05	0.02/0.05/0.05	0.01/0.03/0.06
Ζ	8	8	8	8	8	8	8
Temp (°C)	25(2)	25(2)	24(2)	25(2)	25(2)	25(2)	25(2)
Density(g cm ⁻¹)	7.668	7.837	7.938	8.069	8.266	8.452	8.599
θ Range (°)	1.55-30.03	3.15-29.99	3.17-30.08	3.19-29.97	3.22-30.04	3.25-29.98	3.27-30.01
$\mu (\text{mm}^{-1})$	28.573	29.728	30.747	31.755	33.655	35.670	37.163
R _{int}	0.0396	0.0181	0.0610	0.0626	0.0629	0.0557	0.0478
Collected Ref.	2677	2601	2541	2384	2492	2434	2469
Unique Ref.	1491	1445	1439	1400	1400	1377	1380
h	$-17 \le h \le 17$	$-17 \le h \le 17$	$-17 \leq h \leq 17$ -	$17 \le h \le 17$			
k	$-8 \le k \le 8$	$-8 \le k \le 8$	$-8 \le k \le 8$	$-8 \le k \le 8$			
l	- 16 ≤ <i>l</i> ≤ 16	$-16 \le l \le 16$	$-16 \le l \le 16$	$-16 \le l \le 16$			
$\Delta \rho_{\rm max}$ (e Å ⁻³)	7.531	5.514	4.551	9.921	6.822	8.931	7.860
$\Delta \rho_{\rm min}$ (e Å ⁻³)	-5.625	-1.705	-3.704	-10.886	-12.674	-8.063	-12.168
Extinction	0.0056(5)	0.00030(7)	0.00050(10)	0.0014(3)	0.0064(5)	0.00057(19)	0.0064(5)
$a^{a}R[F^{2}>2\sigma(F^{2})]$	0.0627	0.0282	0.0522	0.0970	0.0745	0.0855	0.0618
^b $wR_2(F^2)$	0.1779	0.0716	0.1314	0.2639	0.1832	0.2092	0.1621

Table 2.1 Crystallographic Data for $LnNi(Sn,Sb)_3$ (Ln = Pr, Sm, Gd, or Tb)

 $\overline{a} R_{\mathrm{I}}(F) = \sum \left\| F_{\mathrm{0}} \right\| - \left| F_{\mathrm{c}} \right\| / \sum \left| F_{\mathrm{0}} \right|$

^b $R_w(F_0^2) = \sum [w(F_0^2 - F_c^2)] / \sum [w(F_0^2)^2]^{1/2}; w = 1 / [\sigma^2(F_0^2) + (0.1403P)^2 + 1.2003P],$

 $w = 1/[\sigma^{2}(F_{0}^{2}) + (0.0140P)^{2} + 12.8728P] \quad w = 1/[\sigma^{2}(F_{0}^{2}) + (0.0697P)^{2} + 8.8849P], \quad w = 1/[\sigma^{2}(F_{0}^{2}) + (0.1728P)^{2}], \\ w = 1/[\sigma^{2}(F_{0}^{2}) + (0.1232P)^{2} + 2.3454P], \quad w = 1/[\sigma^{2}(F_{0}^{2}) + (0.1586P)^{2}], \quad w = 1/[\sigma^{2}(F_{0}^{2}) + (0.1078P)^{2} + 9.3692P] \\ \text{for La, Ce, Pr, Nd, Sm, Gd, and Tb respectively}$

2.2.3 Elemental Analysis

Elemental analysis using EDX was performed using a Hitachi S-3600N variable pressure scanning electron microscope (VP-SEM) and a stoichiometry of $LnNiSnSb_2$ was obtained. Elemental analysis of the Sn:Sb composition of the crystals was performed using Optical Emission Spectroscopy (ICP-OES) on a Perkin Elmer Optima Model 5300V for all analogues (Pr, Nd, Sm, Gd, Tb). The Sn:Sb compositions obtained for each analogue are as follows: Pr – Sn_{0.97}Sb_{2.03}, Nd – Sn_{0.92}Sb_{2.08}, Sm – Sn_{1.24}Sb_{1.76}, Gd – Sn_{0.99}Sb_{2.01}, Tb – Sn_{0.59}Sb_{2.41}. This confirms the presence of Sn in the structure and is consistent with the EDX results previously mentioned.

			,		
Atom	Wyckoff site	x	у	Z	$U_{\rm eq} ({\rm \AA}^2)^a$
La1	4c	0.69985(7)	1/4	0	0.0077(3)
La2	4d	0.30410(7)	0.26099(11)	3⁄4	0.0077(3)
Ni1	8e	0.10248(10)	0.0302(2)	0.86359(9)	0.0105(4)
X1	4c	0.97547(8)	1/4	0	0.0128(3)
X2	4d	0.78994(8)	0.25128(12)	3⁄4	0.0080(3)
X3	8e	0.50131(5)	0.50751(9)	0.87603(4)	0.0087(3)
X4	4c	0.21497(8)	1/4	0	0.0079(3)
X5	4d	0.94673(7)	0.88313(14)	3⁄4	0.0121(3)
Cel	4 <i>c</i>	0.69921(4)	1⁄4	0	0.0070(1)
Ce2	4d	0.30482(4)	0.26209(7)	3⁄4	0.0068(1)
Ni1	8 <i>e</i>	0.10429(6)	0.0302(1)	0.86352(6)	0.0094(2)
X1	4c	0.97482(5)	1/4	0	0.0112(2)
X2	4d	0.78593(5)	0.25134(8)	3⁄4	0.0075(2)
X3	8 <i>e</i>	0.50154(3)	0.50804(6)	0.8759(3)	0.0081(1)
X4	4c	0.21859(5)	1/4	0	0.0074(2)
X5	4 <i>d</i>	0.94614(4)	0.8837(1)	3⁄4	0.0109(2)
Pr1	40	0 69919(7)	1/4	0	0.0123(3)
Pr2	4 <i>d</i>	0.30501(7)	0.26236(17)	3/4	0.0120(3)
Ni1	8e	0.10491(13)	0.0301(3)	0.86371(14)	0.0120(3) 0.0146(4)
X1	40	0.97501(10)	1/4	0	0.0164(3)
X2	4 <i>d</i>	0.78459(9)	0.2512(2)	3/4	0.0131(3)
X3	8e	0.70157(6)	0.2012(2) 0.50801(14)	0.87592(6)	0.0130(3)
X4	40	0.22006(9)	1/4	0	0.0126(3)
X5	4 <i>d</i>	0.94559(9)	0.8841(2)	3⁄4	0.0167(3)
Nd1	4 <i>c</i>	0.69855(10)	1/4	0	0.0057(4)
Nd2	4d	0.30558(9)	0.26297(17)	3/4	0.0058(4)
Ni1	8e	0.10590(13)	0.0304(3)	0.86355(15)	0.0075(5)
X1	40	0.97456(11)	1/4	0	0.0082(5)
X2	4d	0.78284(12)	0.25064(19)	3/4	0.0058(5)
X3	8e	0 50177(6)	0.50821(15)	0.87595(7)	0.0068(5)
X4	4c	0.22184(12)	1/4	0	0.0000(5) 0.0058(5)
X5	4 <i>d</i>	0.94564(9)	0.8848(2)	3⁄4	0.0087(5)
Sm1	40	0.69875(6)	1/4	0	0.0078(3)
Sm2	4 <i>d</i>	0.30574(6)	0.26435(13)	3⁄4	0.0078(3)
Ni1	8e	0.10733(10)	0.0297(2)	0.86354(11)	0.0092(4)
X1	40	0.97476(8)	1/4	0	0.0107(3)
X2	4 <i>d</i>	0.77989(9)	0.25034(14)	3⁄4	0.0081(3)
X3	8e	0.50213(4)	0.50858(11)	0.87599(6)	0.0090(3)
X4	$\frac{3c}{4c}$	0.20213(1) 0.22485(9)	1/4	0	0.0079(3)
X5	4 <i>d</i>	0.94515(7)	0.88488(16)	3⁄4	0.0106(3)
Gd1	4c	0.69800(8)	1/4	0	0.0077(4)
Gd?	4d	0 30634(8)	0.26474(17)	3/4	0.0077(4)
Ni1	ти 8 <i>0</i>	0.3003 + (0) 0.10870(16)	0.2077(17)	0.86342(14)	0.0077(-7)
X1	$\frac{3c}{4c}$	0.97487(11)	1/4	0	0.0105(3)
X2	4 <i>d</i>	0.77844(12)	0.2497(2)	3⁄4	0.0086(4)
		······································	······································		

Table 2.2 Atomic Positions and Displacement Parameters for $LnNi(Sn,Sb)_3$ (Ln = La, Ce, Pr, Sm, Gd, or Tb; X = Sn/Sb)

Table 2.2	(cont.)
-----------	---------

Atom	Wyckoff site	x	у	z	$U_{\rm eq}({\rm \AA}^2)^a$
X3	8 <i>e</i>	0.50226(7)	0.50904(15)	0.87588(7)	0.0099(4)
X4	4c	0.22648(12)	1/4	0	0.0081(4)
X5	4d	0.94488(11)	0.8846(2)	3⁄4	0.0116(4)
Tb1	4 <i>c</i>	0.69785(7)	1/4	0	0.0068(3)
Tb2	4d	0.30665(7)	0.26545(13)	3⁄4	0.0064(3)
Ni1	8 <i>e</i>	0.11013(12)	0.0288(3)	0.86377(12)	0.0085(4)
X1	4c	0.97497(9)	1⁄4	0	0.0097(3)
X2	4d	0.77590(10)	0.24843(16)	3⁄4	0.0073(3)
X3	8 <i>e</i>	0.50259(5)	0.50885(12)	0.87582(6)	0.0075(3)
X4	4c	0.22913(10)	1⁄4	0	0.0070(3)
X5	4d	0.94480(8)	0.88451(18)	3⁄4	0.0106(3)

 ${}^{a}U_{eq}$ is defined as one-third of the trace of the orthogonalized U_{ij} tensor.

2.2.4 Physical Property Measurements

Magnetic measurements on single crystals of *Ln*Ni(Sn,Sb)₃ oriented in the same direction were performed using a Quantum Design MPMS Superconducting Quantum Interference Device (SQUID) magnetometer. Temperature-dependent susceptibility data were measured with applied fields of 0.1 T, 0.5 T, 1 T or 5 T from 2 K to 300 K. Magnetization as a function of field was measured up to 5 T at 4 K or 5 K. The resistivity (between 2 K - 300 K) and magnetoresistance (up to 9 T) was measured on single crystals employing the standard four wires and AC lock-in techniques (with thin Pt wires attached using silver epoxy) in a Quantum Design Physical Property Measurement System (PPMS) at ambient pressure.

2.3. Results and Discussion

2.3.1 Structure

LnNi(Sn,Sb)₃ (Ln = Pr, Nd, Sm, Gd, Tb) crystallizes in the CePdSb₃ structure type with lattice parameters $a \sim 12$ Å, $b \sim 6$ Å, $c \sim 12$ Å.²¹ The use of Sn flux allowed crystal growth to occur over a greater temperature range thus stabilizing the new compounds. The structure is an intermediate between the CeCrSb₃ and α -CeNiSb₃ structure types based on the lattice parameters and the arrangement and distortion of the subunits. The polyhedral representation of the structures of α -CeNiSb₃ and CeNi(Sn,Sb)₃ are shown in Figure 2.1. The two compounds differ



Figure 2.1 Polyhedral representation of α -CeNiSb₃ and CeNi(Sb,Sn)₃, where the yellow spheres are the Ce atoms, the maroon spheres are Sb or (Sb,Sn) atoms, the green striped polyhedra are Ni1 octahedra, and the dark green polyhedra are Ni2 octahedra.

in the packing of the transition metal layer. This difference in the packing leads to the difference in the *c*-axis of the unit cell. Because we cannot determine the exact location of Sn within the CeNi(Sn,Sb)₃ structure, the nomenclature X, where X = Sn/Sb, will be used to refer to the main group site. This structure consists of layers of nearly square sheets of X atoms, with a layer of square anti-prismatic LnX_8 and mono-capped square anti-prismatic LnX_9 both above and below the Sn/Sb square sheets. There are Ln atoms in the capping position of LnX_8 square anti-prisms, however the inter-atomic distance is too far to be considered bonding as seen in Figure 2.2. Layers of distorted face- and edge- sharing NiX₆ octahedra are located next to the Ln layers. The compounds that adopt the LaPdSb₃ structure with lattice parameters ~ 12 Å x 6 Å x 12 Å are related to the α -LnNiSb₃ (~12 Å x 6 Å x 18 Å) structure type and the main variation is in the stacking of the transition metal subunits.^{5,15,19}

A decrease in volume, consistent with lanthanide contraction, was also observed in the α -LnNiSb₃ analogues (Ln – Ce, Pr, Nd, Sm).¹⁷ Figure 2.3 displays the Ln-X distances between the Ln atoms and X-sheets for both α -LnNiSb₃ and LnNi(Sn,Sb)₃ as a function of ionic radii. As the



Figure 2.2 Environment of Ln sites of $LnNi(Sn,Sb)_3$ as viewed down the *b*-axis. Ln1 adopts a square anti-prismatic environment, while Ln2 adopts a mono-capped square anti-prism.

lanthanide radii decreases, the distance between the *Ln* atoms and Sb or Sn/Sb nets decreases. Selected interatomic distances of *Ln*Ni(Sn,Sb)₃ (*Ln* = La-Nd, Sm, Gd, or Tb) are shown in Table 2.3. As expected, the *Ln*-X distances along the *a*-axis decrease as a function of smaller lanthanide. In *Ln*Ni(Sn,Sb)₃, the Sn/Sb net layer is formed by four-bonded X3 atoms while in the α -phase, the Sb square net is formed by four Sb1 and Sb3 atoms and is highly distorted.¹⁵ As smaller lanthanides are substituted into the structure, the X - X distances within the sheets decrease slightly, and the angles are slightly more distorted. Under our growth conditions, the *Ln*Ni(Sn,Sb)₃ phase can be adopted for Ce, Pr, Nd, Sm, Gd, and Tb while only Ce, Pr, Nd, and Sm analogues can be adopted for the α -*Ln*NiSb₃ structure type. It is also important to note that for smaller rare earth elements, Gd – Er, and Y, the tetragonal *Ln*Ni(Sn,Sb)₃ the experimental yield was extremely small and the crystal size was almost microscopic. This is further indication that the structure type is strained and leads to the more stable $LnNiSb_2$ structure type.



Figure 2.3 Plot of *Ln*-X (X = Sn,Sb) distances as a function of lanthanide for both α -*Ln*NiSb₃ and *Ln*Ni(Sn,Sb)₃.

Table 2.3	Selected I	Interatomic	Distances	(Å)	of LnNi	(Sn,Sb) ₃	(Ln	= La,	Ce,	Pr,	Sm,	Gd,	or
Tb; $X = Sn/$	/Sb)												

,	La	Ce	Pr	Nd	Sm	Gd	Tb
Ln1-X1	3.6099(13)	3.501(8)	3.5423(17)	3.5249(18)	3.4918(12)	3.4789(17)	3.4501(14)
<i>Ln</i> 1-X2 (x2)	3.2533(5)	3.2241(3)	3.2074(15)	3.1923(11)	3.1693(6)	3.1593(11)	3.1380(7)
<i>Ln</i> 1-X3 (x2)	3.3791(9)	3.3419(5)	3.3269(15)	3.3074(14)	3.2906(9)	3.2681(13)	3.2496(10)
<i>Ln</i> 1-X3 (x2)	3.3942(9)	3.3562(3)	3.3408(15)	3.3188(14)	3.2976(9)	3.2759(13)	3.2506(10)
<i>Ln</i> 1-X4 (x2)	3.2672(5)	3.2395(3)	3.224(3)	3.212(2)	3.1914(11)	3.1808(15)	3.1634(11)
Ln2-X2	3.2526(10)	3.2159(7)	3.198(4)	3.179(2)	3.1485(15)	3.131(2)	3.1021(16)
Ln2-X2	3.3633(10)	3.3388(7)	3.326(4)	3.320(2)	3.3091(15)	3.304(2)	3.2974(16)
<i>Ln</i> 2-X3 (x2)	3.3545(9)	3.3158(6)	3.2994(16)	3.2795(14)	3.2575(9)	3.2351(13)	3.2115(10)
<i>Ln</i> 2-X3 (x2)	3.3613(10)	3.3232(6)	3.3055(15)	3.2867(14)	3.2654(9)	3.2453(13)	3.2221(10)
<i>Ln</i> 2-X4 (x2)	3.2503(5)	3.2228(3)	3.2063(15)	3.1908(11)	3.1695(7)	3.1582(11)	3.1374(7)
Ln2-X5	3.3697(12)	3.3261(7)	3.3032(17)	3.2930(17)	3.2576(12)	3.2394(17)	3.2126(13)
X3-X3	3.0083(11)	3.0020(7)	2.994(2)	2.985(2)	2.9772(14)	2.9748(19)	2.9667(15)
X3-X3	3.0568(11)	3.0464(7)	3.036(2)	3.028(2)	3.0221(15)	3.0142(19)	3.0034(15)
X3-X3	3.0702(2)	3.0607(6)	3.053(4)	3.047(2)	3.0420(10)	3.0365(15)	3.0307(10)
Ni-X1	2.25957(13)	2.5901(8)	2.584(2)	2.582(2)	2.5790(15)	2.580(2)	2.5730(17)
Ni-X1	2.7066(14)	2.7456(15)	2.699(2)	2.701(2)	2.6997(15)	2.701(2)	2.6968(17)
Ni-X2	2.6105(14)	2.6093(9)	2.606(2)	2.605(2)	2.6033(16)	2.596(2)	2.5968(18)
Ni-X4	2.5927(13)	2.5913(8)	2.586(2)	2.583(2)	2.5857(15)	2.580(2)	2.5760(17)
Ni-X5	2.6217(15)	2.6193(9)	2.619(2)	2.615(2)	2.6153(15)	2.618(2)	2.6163(18)
Ni-X5	2.6477(14)	2.6444(10)	2.641(3)	2.638(2)	2.6390(17)	2.636(2)	2.638(2)
Ni-Ni	2.755(2)	2.7459(15)	2.742(4)	2.730(4)	2.724(3)	2.716(3)	2.716(3)

2.3.2 Physical Properties

The magnetic susceptibility (χ vs *T*) measured at applied fields of 0.1 T, 0.5 T, 1 T or 5T for several single crystals of PrNi(Sn,Sb)₃, NdNi(Sn,Sb)₃, SmNi(Sn,Sb)₃ and GdNi(Sn,Sb)₃, respectively are shown in Figure 2.4. The inset of Figure 2.4 shows the magnetic susceptibility (M vs T) measured at an applied field of 0.1 T of a 1.99mg single crystal of CeNi(Sn,Sb)₃ in



Figure 2.4 Magnetic susceptibility as a function of temperature between 2 K - 300 K for PrNi(Sn,Sb)₃ (H = 0.1 T), NdNi(Sn,Sb)₃ (H = 0.5 T), SmNi(Sn,Sb)₃ (H = 1 T), and GdNi(Sn,Sb)₃ (H = 1 T) where the red triangles, blue circles, green diamonds, and black squares refer to PrNi(Sn,Sb)₃, NdNi(Sn,Sb)₃, SmNi(Sn,Sb)₃, and GdNi(Sn,Sb)₃, respectively. The inset displays the magnetic measured at an applied field of 0.1 T of a 1.99mg single crystal of β -CeNiSb₃ in three directions. The inset is the inverse susceptibility of the same plot. The data for SmNi(Sn,Sb)₃ has been multiplied by 100 to fit the scale.

three directions. The magnetic field is applied parallel to the bc – plane of the crystals for all analogues with the exception of Ce which the field was oriented in three different directions and are labeled as such on the figure. The properties of TbNi(Sn,Sb)₃ were not measured due to small yield. A summary of the resulting magnetic data and fit parameters are shown in Table 2.4. A ferromagnetic transition is observed for CeNi(Sn,Sb)₃ at ~ 6 K in each direction which is similar to the $\chi(T)$ of the α -form.²³ From the inverse susceptibility along the *a*, *b* and *c*-axes, the experimental effective moments of 1.80, 2.45 and 2.38 $\mu_{\rm B}$ and Weiss temperatures (θ) of 22.8, 8.6 and 1.4 K respectively along each axis obeys Curie-Weiss law. The average μ_{eff} of 2.23 μ_{B} is slightly smaller than the calculated 2.54 $\mu_{\rm B}$ for the Ce³⁺ ion. PrNi(Sn,Sb)₃ does not appear to order down to 2 K. However, the possibility remains that this sample may order below 2 K as signs of ordering can be seen in the magnetization near 2 K. An effective moment of 3.65 $\mu_{\rm B}$ and a Weiss temperature (θ) of ~ -1 K were obtained from a modified Curie Weiss fit $\chi = \chi_0 +$ C/(T+ θ) between 100 K – 300 K. The μ_{eff} of 3.68 μ_B is slightly larger than the calculated moment of 3.57 $\mu_{\rm B}$ for the Pr³⁺ ion and is consistent with the magnetic contribution coming solely from the Pr. NdNi(Sn,Sb)₃ is paramagnetic down to 2 K. Fits to the inverse susceptibility between 2 K – 300 K reveal an effective moment of 3.93 $\mu_{\rm B}$ and a Weiss temperature, $\theta \sim -4$ K. The experimental moment of 3.93 $\mu_{\rm B}$ is slightly larger than the calculated moment of 3.62 $\mu_{\rm B}$ for the Nd³⁺ ion. SmNi(Sn,Sb)₃ appears be paramagnetic down to 2.5 K. An effective moment of 0.65 $\mu_{\rm B}$ and a Weiss temperature (θ) of ~ -19 K were obtained with a Curie-Weiss fit from 50 – 300 K. The experimental moment is slightly smaller than the expected moment of 0.84 $\mu_{\rm B}$ for Sm³⁺. GdNi(Sn,Sb)₃ is also paramagnetic down to 2 K and an effective moment of 7.47 μ_B and a Weiss temperature (θ) of ~ -403 K were obtained from the modified Curie-Weiss fit. The expected moment for Gd^{3+} is 7.94 μ_{B} which is slightly larger than the experimental moment. The fact that these analogues (Pr, Nd, Sm, Gd) do not seem to order while CeNi(Sn,Sb)₃ orders ferromagnetically at 6 K, and α -LnNiSb₃ orders antiferromagnetically for Ln = Pr, Nd, Sm with $T_{\text{Neel}} \leq 5$ K, is quite surprising.¹⁹ The evolution of the Curie-Weiss temperatures (except Gd) follows the de Gennes factors across the Ln series as expected²⁴, and are close to the values found in the α -analogues.
	Ce	Pr	Nd	Sm	Gd
<i>H</i> (T)	0.1	1	0.5	1	1
χο	N/A	-0.0001	-0.0035	0.000937	-0.00059
C	N/A	1.69	1.93	0.053	6.94
$\theta(\mathbf{K})$	8.6	-0.97	-3.92	-19.33	-403.51
$\mu_{\text{calc}}(\mu_{\text{B}})$	2.54	3.57	3.62	0.84	7.94
$\mu_{\rm eff}$ ($\mu_{\rm B}$)	2.23	3.68	3.93	0.65	7.45

 Table 2.4
 Summary of Magnetic Susceptibility Data

The magnetization of single crystals of PrNi(Sn,Sb)₃, NdNi(Sn,Sb)₃, SmNi(Sn,Sb)₃ and GdNi(Sn,Sb)₃ as a function of field (*M* vs *H*) at temperatures of 5 K or 4 K are shown in Figure 2.5 and the magnetization of β -CeNiSb₃ is shown in the inset. At ~1.5 T, the magnetization of CeNi(Sn,Sb)₃ shows obvious signs of saturation and the calculated saturation moment (μ_{sat}) for



Figure 2.5 Field dependent magnetization of single crystals of CeNi(Sn,Sb)₃ (T = 2 K), PrNi(Sn,Sb)₃ (T = 5 K) and NdNi(Sn,Sb)₃ (T = 4 K), SmNi(Sn,Sb)₃ (T = 4 K) and GdNi(Sn,Sb)₃ (T = 4 K) where the purple open triangles, red triangles, blue circles, green diamonds, and black squares refer to CeNi(Sn,Sb)₃, PrNi(Sn,Sb)₃, SmNi(Sn,Sb)₃, NdNi(Sn,Sb)₃ and GdNi(Sn,Sb)₃, respectively The data for the Sm- and Gd-analogues have been multiplied by 10 to fit the scale.

Ce is 2.14 $\mu_{\rm B}$ /Ce. The magnetization of PrNi(Sn,Sb)₃ begins to show signs of saturation at around 4 T, well below the theoretical saturation moment of 3.2 $\mu_{\rm B}$. The difference points to the importance of short range correlations in the proximity of a magnetic instability in this compound, as also evidenced by the anomalous behavior of resistivity (see below). The magnetization for the other analogues is nearly linear up to fields of 5 T. The diamagnetic background contribution is less than 3 % of the total signal for all samples. Moreover, the magnetization values at 5 T are consistent with the corresponding α -analogues, suggesting similar magneto-crystalline anisotropy and crystal field splitting in both structure types. The magnetization of the Gd-analogue, however, is anomalously small. This, coupled to the small effective moment, suggests either a strong anisotropy or partial screening of the Gd moments by conduction electrons.

The resistivity as a function of temperature for $LnNi(Sn,Sb)_3$ (Ln = Pr, Nd, Sm, Gd) is displayed in Figure 2.6. All analogues display simple metallic behavior with a small ratio of room temperature to low temperature resistivity. The Ce analogue displays metallic Kondo behavior, with a resistivity minimum around 20 K and a pronounced drop below the Curie temperature (6 K) while the La analogue displays simple metallic behavior.¹⁹ The resistivity of the Ce analogue differs slightly from the previous report and is more representative of the compound. There is also a superconducting transition seen in all samples ~ 3.5 K which we attribute to Sn flux on the surface of the crystals (not shown). We also note that the resistivity of the Pr analogue has a quasi-linear temperature dependence below 50 K. This, together with a small Curie-Weiss temperature, suggests that PrNi(Sn,Sb)₃ is close to a magnetic instability.

The magnetoresistance (MR) as a function of field for $LnNi(Sn,Sb)_3$ (Ln = Pr, Nd, Sm, Gd) is shown in Figure 2.7. All analogues show a small positive MR at T = 5 K with a nearly quadratic field dependence and no signs of saturation up to 9 T, with a similar magnitude as the



Figure 2.6 Temperature dependent resistivity of single crystals of $LnNi(Sn,Sb)_3$ (Ln = La, Ce, Pr, Nd, Sm, Gd) where the orange open diamonds, purple open triangles, red triangles, blue circles, green diamonds, and black squares refer to $LaNi(Sn,Sb)_3$, $CeNi(Sn,Sb)_3$, $PrNi(Sn,Sb)_3$, $NdNi(Sn,Sb)_3$, $SmNi(Sn,Sb)_3$, and $GdNi(Sn,Sb)_3$, respectively.



Figure 2.7 Magnetoresistance of single crystals of $PrNi(Sn,Sb)_3$ (5 K), $NdNi(Sn,Sb)_3$ (5 K), $SmNi(Sn,Sb)_3$ (5 K), and $GdNi(Sn,Sb)_3$ (5 K). The purple open triangles, red triangles, blue circles, green diamonds, and black squares refer to β -CeNiSb₃, $PrNi(Sn,Sb)_3$, $NdNi(Sn,Sb)_3$, $SmNi(Sn,Sb)_3$, and $GdNi(Sn,Sb)_3$, respectively. The data for β -CeNiSb₃ (3 K) is located in the inset of the plot.

La analogue. This indicates that the MR is mostly dominated by the positive contribution, although one cannot exclude that a small negative contribution, due to the quenching of spin fluctuations by magnetic field, still persists at low temperatures. Indeed, the MR at H = 9 T changes sign upon warming and a negative MR is recovered at temperatures above 100 K in all compounds (not shown). Assuming localized *f*-electrons, these compounds should have a similar density of charge carriers. In this case, the difference between the compounds is presumably due to the interplay between the orbital and the spin contributions. In contrast, the positive MR in the magnetic phase of CeNi(Sn,Sb)₃ at T = 3 K, above the saturation field, also shown in Figure 2.7, is an order of magnitude larger and saturates around 6 T. The positive non-saturating MR is reminiscent of other planar materials including structurally related $LnSb_2$ (Ln = La, Pr, Sm, Nd) whose structure also contains square Sb sheets, however the analogues investigated here have a significantly smaller magnetoresistance than these other compounds.²⁵

2.4 References

- (1) Mills, A. M.; Lam, R.; Ferguson, M. J.; Deakin, L.; Mar, A. Coord. Chem. Rev. 2002, 233-234, 207-222.
- (2) Sologub, O.; Salamakha, P. S. *Handbook on the Physics and Chemistry of Rare Earths*; Elsevier: Netherlands, 2003; Vol. 33.
- (3) Kauzlarich, S. M. *Chemistry, Structure, and Bonding in Zintl Phases and Ions*; VCH Publishers: New York, 1996.
- (4) Papoian, G. A.; Hoffmann, R. Angew. Chem. Int. Ed. 2000, 39, 2409-2448.
- (5) Hartjes, K.; Jeitschko, W.; Brylak, M. J. Magn. Magn. Mater. 1997, 173, 109-116.
- (6) Leonard, M.; Saha, S.; Ali, N. J. Appl. Phys. 1999, 85, 4759-4561.
- (7) Leonard, M. L.; Dubenko, I. S.; Ali, N. J. Alloys Compd. 2000, 303-304, 265-269.
- (8) Jackson, D. D.; Torelli, M.; Fisk, Z. Phys. Rev. B 2001, 65, 014421.
- (9) Deakin, L.; Ferguson, M. J.; Mar, A. Chem. Mater. 2001, 13, 1407-1412.

- (10) Jackson, D. D.; Fisk, Z. J. Magn. Magn. Mater. 2003, 256, 106-116.
- (11) Jackson, D. D.; Fisk, Z. J. Alloys Compd. 2004, 377, 243-247.
- (12) Deakin, L.; Mar, A. Chem. Mater. 2003, 15, 3343-3346.
- (13) Gautreaux, D. P.; Capan, C.; DiTusa, J. F.; Young, D. P.; Chan, J. Y. J. Solid State Chem. 2008, In Press.
- (14) Crerar, S. J.; Deakin, L.; Mar, A. Chem. Mater. 2005, 17, 2780-2784.
- (15) Macaluso, R. T.; Wells, D. M.; Sykora, R. E.; Albrecht-Schmitt, T. E.; Mar, A.; Nakatsuji, S.; Lee, H.; Fisk, Z.; Chan, J. Y. J. Solid State Chem. 2004, 177, 293-298.
- (16) Siderov, V. A.; Bauer, E. D.; Lee, H.; Nakatsuji, S.; Thompson, J. D.; Fisk, Z. Phys. Rev. B 2005, 71, 094422-1 - 094422-4.
- (17) Thomas, E. L.; Macaluso, R. T.; Lee, H.; Fisk, Z.; Chan, J. Y. J. Solid State Chem. 2004, 177, 4228-4236.
- (18) Thomas, E. L.; Moldovan, M.; Young, D. P.; Chan, J. Y. *Chem. Mater.* **2005**, *17*, 5810-5816.
- (19) Thomas, E. L.; Gautreaux, D. P.; Lee, H. O.; Fisk, Z.; Chan, J. Y. *Inorg. Chem.* **2007**, *46*, 3010-3016.
- (20) Thamizhavel, A.; Nakashima, H.; Shiromoto, T.; Obiraki, Y.; Matsuda, T. D.; Haga, Y.; Ramakrishnan, S.; Takeuchi, T.; Settai, R.; Onuki, Y. J. Phys. Soc. Jpn. 2005, 74, 2617-2621.
- (21) Thomas, E. L.; Gautreaux, D. P.; Chan, J. Y. Acta Crystallogr. Sect. E: Struct. Rep. Online 2006, E62, i96-i98.
- (22) Sheldrick, G. M.; University of Gottingen: Germany, 1997.
- (23) Lee, H.-O.; Nakatsuji, S.; Chen, Y.; Bao, W.; Hundley, M. F.; Macaluso, R. T.; Chan, J. Y.; Carter, B.; Klavins, P.; Schlottmann, P.; Fisk, Z.
- (24) Jensen, J.; Mackintosh, A. R. *Rare Earth Magnetism Structure and Excitations*; Clarendon Press: Oxford, 1991.
- (25) Bud'ko, S. L.; Canfield, P. C.; Mielke, C. H.; Lacerda, A. H. *Phys. Rev. B* **1998**, *57*, 13624-13638.

CHAPTER 3 – CeNi_xCo_{1-x}Sb₃

3.1 Introduction

Doping is a method of introducing an element into a known compound to modify the compound's physical properties and structure. Co is one of the five naturally occurring ferromagnetic elements and has a Curie temperature of 1388 K.¹ Fe and Ni are also ferromagnetic below their Curie temperatures of 1043 K and 627 K respectively.¹ Lanthanide – cobalt compounds have also demonstrated a phenomenon known as itinerant electron metamagnetism (IEM) where a first order transition from a nonmagnetic state to a ferromagnetic state occurs.³ This transition is caused by the ordering of the Co sublattice and generally occurs in addition to the local magnetic moment caused by the rare earth element.⁴ FeSi, a narrow-gap semiconductor has been doped with Co to produce a compound with extraordinary magnetoconductance.⁵ Another study showed that when FeSi is doped with Co a Curie temperature of 53 K is obtained along with a very high Hall conductance which are important developments for spintronics materials.⁶ By substituting Co for Ni in α -CeNiSb₃, the number of carriers might change which can affect the magnetic or transport behavior. The crystal growth and structure as well as physical properties of CeNi_xCo_{1-x}Sb₃ are reported herein.

3.2 Experimental

3.2.1 Synthesis

Single crystals of CeNi_xCo_{1-x}Sb₃, where x = 0.8, were prepared using an excess Sb flux growth method. Ce ingot (99.9%, Alfa Aesar), Ni powder (99.999%, Alfa Aesar), Co powder (99.999%, Alfa Aesar), and Sb shot (99.999%, Alfa Aesar) were placed in an alumina crucible in a 1:0.8:0.2:20 molar ratio. The crucible was sealed into an evacuated fused-silica tube. The

² Portions of this chapter reprinted by permission of Elsevier: Gautreaux, D.P.; Parent, M.; Moldovan, M.; Young, D.P.; Chan, J.Y.; "Magnetization and Transport Properties of CeNi_{0.78}Co_{0.22}Sb₃", *Physica B.* **2008**, *403*, 5-9.

reaction vessel was heated to 1150 °C where the temperature was held constant for 24 h and then cooled 5 °C h⁻¹ to 670 °C. After dwelling at 670 °C, the excess Sb flux was removed by centrifugation. Silvery, metallic plates with dimensions of approximately 0.5 x 0.5 x 0.025mm were obtained. When exposed to air and moisture, there is no visible surface degradation to both compounds over a period of months.

Though the focus will be $\text{CeNi}_x\text{Co}_{1-x}\text{Sb}_3$ where x = 0.8, the attempted syntheses of $\text{CeNi}_x\text{Co}_{1-x}\text{Sb}_3$ compounds where x = 0.5 - 0.9 and the results are shown in Table 3.1. When x = 0.7 or 0.5, no crystals of the $\text{CeNi}_x\text{Co}_{1-x}\text{Sb}_3$ were obtained. When x = 0.9, $\text{CeNi}_x\text{Co}_{1-x}\text{Sb}_3$ crystals were obtained however the lattice was similar to $\text{CeNi}_x\text{Co}_{1-x}\text{Sb}_3$ when x = 0.8.

Sample	Ce:Ni:Co:Sb Ratio	Growth Conditions	Result
MP001	1:0.8:0.2:20	1150 °C for 24 h, slow-	CeNi _x Co _{1-x} Sb ₃
		cooled 5 °C/h to 670 °C	
MP002	1:0.5:0.5:20	1150 °C for 24 h, slow-	CeSb ₂ binary
		cooled 5 °C/h to 670 °C	
MP003	1:0.2:0.8:20	1150 °C for 24 h, slow-	no crystals
		cooled 5 °C/h to 670 °C	
MP004	1:1:0:15	1150 °C for 24 h, slow-	α -CeNiSb ₃
		cooled 5 °C/h to 670 °C	
MP007	1:0.8:0.2:20	1150 °C for 24 h, slow-	$CeNi_xCo_{1-x}Sb_3$
		cooled 5 °C/h to 670 °C	
MP008	1:1:1:20	1150 °C for 24 h, slow-	CeSb ₂ binary
		cooled 5 °C/h to 670 °C	
MP010	1:0.9:0.1:20	1150 °C for 24 h, slow-	$CeNi_xCo_{1-x}Sb_3$
		cooled 5 °C/h to 670 °C	
MP011	1:0.7:0.3:20	1150 °C for 24 h, slow-	polycrystalline material
		cooled 5 °C/h to 670 °C	

Table 3.1Attempted Crystal Growths of CeNi_xCo_{1-x}Sb₃

3.2.2 Single Crystal X-Ray Diffraction

A plate-shaped crystal with dimensions of $0.04 \ge 0.04 \ge 0.01 \text{ mm}^3$ was mounted onto a glass fiber of a goniometer with epoxy and placed on a Nonius Kappa CCD X-ray diffractometer

(Mo $K_{\alpha} = 0.71073$ Å). Data were collected at 25 °C. Data collection parameters and crystallographic data are listed in Table 3.2. The unit cell parameters were determined from images taken at a rotation of 15 ° φ . The structure was solved by direct methods using SHELXL97.⁷ The transition metal sites could be refined as either Ni or Co and not affect the overall R value or thermal parameters. After refinement of the structure was complete, the data were corrected for absorption and the displacement parameters were refined as anisotropic. Atomic coordinates and anisotropic displacement parameters are provided in Table 3.3.

α-CeNiSb ₃	$CeNi_xCo_{1-x}Sb_3$
564.08	564.11
Pbcm	Pbcm
12.65200(10)	12.6480(2)
6.2120(3)	6.2060(4)
18.4190(5)	18.3860(8)
1447.63(8)	1443.18(11)
0.025 x 0.045 x 0.050	0.010 x 0.040 x 0.040
12	12
25(2)	25(2)
2.74 - 30.03	2.74 - 30.06
29.452	21.868
3921	3938
2165	2165
$-17 \le h \le 17$	$-17 \le h \le 17$
$-8 \le k \le 8$	$-8 \le k \le 8$
$-25 \le l \le 25$	$-25 \le l \le 25$
5.871	6.565
-4.994	-4.142
0.00053(10)	0.00018(4)
0.0604	0.0515
0.1742	0.1330
	α -CeNiSb ₃ 564.08 Pbcm 12.65200(10) 6.2120(3) 18.4190(5) 1447.63(8) 0.025 x 0.045 x 0.050 12 25(2) 2.74 - 30.03 29.452 3921 2165 -17 $\leq h \leq 17$ -8 $\leq k \leq 8$ -25 $\leq l \leq 25$ 5.871 -4.994 0.00053(10) 0.0604 0.1742

Table 3.2 Crystallographic Data for α -CeNiSb₃ and CeNi_xCo_{1-x}Sb₃

 ${}^{a}R_{I}(F) = \sum ||F_{o}| - |F_{c}|| / \sum |F_{o}|$ ${}^{b}R_{w}(F_{o}^{2}) = \sum [w(F_{o}^{2} - F_{c}^{2})] / \sum [w(F_{o}^{2})^{2}]^{2}; \text{ where } w = 1 / [\sigma^{2}(F_{o}^{2}) + (0.1335P)^{2} + 3.6415P] \text{ and}$ $w = 1 / [\sigma^{2}(F_{o}^{2}) + (0.0837P)^{2} + 6.6619P] \text{ respectively}$

Atom	Wyckoff site	x	у	Z.	$U_{\rm eq} ({\rm \AA}^2)^a$
Ce1	4d	0.30507(7)	0.55270(16)	1/4	0.0089(2)
Ce2	8 <i>e</i>	0.29910(5)	0.02420(11)	0.41677(3)	0.0084(2)
$M1^{b}$	4c	0.89836(16)	1/4	1/2	0.0105(4)
$M2^{\rm b}$	8 <i>e</i>	0.90174(12)	0.8252(3)	0.17577(9)	0.0116(4)
Sb1	8 <i>e</i>	0.50321(5)	0.78945(13)	0.33405(4)	0.0097(2)
Sb2	4d	0.21816(8)	0.04743(19)	1/4	0.0096(3)
Sb3	4c	0.50359(8)	1⁄4	1/2	0.0102(3)
Sb4	8 <i>e</i>	0.22288(6)	0.52308(13)	0.41567(4)	0.0091(2)
Sb5	8 <i>e</i>	0.97368(6)	0.54075(13)	0.41329	0.0116(2)
Sb5	4d	0.07541(8)	0.68314(18)	1/4	0.0110(3)

 Table 3.3
 Atomic Positions and Displacement Parameters for CeNi_xCo_{1-x}Sb₃

 ${}^{a}U_{eq}$ is defined as one-third of the trace of the orthogonalized U_{ij} tensor. ${}^{b}M1$ and M2 represent a mixture of Ni and Co

3.2.3 ICP-Optical Emission Spectroscopy

Elemental analysis of CeNi_xCo_{1-x}Sb₃ using inductively coupled plasma-optical emission spectroscopy (ICP-OES) was performed at Galbraith Laboratories. This analysis was performed due to the similar X-ray scattering of Ni and Co. X-ray diffraction cannot distinguish between elements with similar Z. Optical emission spectroscopy excites each of the atoms present and upon relaxation light is emitted and with a polychromatic detector, the amount of each element present can be determined. This analysis was performed for Ni and Co and a stoichiometry of CeNi_{0.780}Co_{0.220}Sb₃ was obtained. This is similar to the nominal composition of CeNi_{0.80}Co_{0.20}Sb₃.

3.2.4 Physical Property Measurements

Magnetic susceptibility data (between 2 K - 300 K) at an applied field of 0.1 T and magnetization (up to 9 T) at 3 K were measured using a Quantum Design Physical Property Measurement System (PPMS). The resistivity (between 2 K - 300 K) was measured on a single crystal using the standard four wires and AC lock-in techniques (with thin Pt wires attached

using silver epoxy) in a Quantum Design Physical Property Measurement System (PPMS) at ambient pressure.

3.3 Results and Discussion

3.3.1 Structure

 $CeNi_{0.80}Co_{0.20}Sb_3$ crystallizes in the CeNiSb_3 structure type.⁸ The structure of $CeNi_{0.80}Co_{0.20}Sb_3$ is shown in Figure 3.1. The structure consists of layers of mono-capped square anti-prismatic CeSb₉ above and below a layer of Sb square nets. Layers of distorted face- and edge- sharing MSb_6 octahedra are located between the CeSb₉ layers. The transition metal site will be referred to as *M*1 and *M*2 which will be a mixture of Ni and Co on each site. Figure 3.2



Figure 3.1 The structure of $\text{CeNi}_x\text{Co}_{1-x}\text{Sb}_3$ viewed down the *b*-axis. The yellow spheres represent Ce atoms, blue and green spheres represent Ni/Co atoms, and maroon spheres represent Sb atoms.

shows the X-ray powder patterns of $\text{CeNi}_x\text{Co}_{1-x}\text{Sb}_3$ and α -CeNiSb₃. Each reflection is indexed according to the structural data from single crystal X-ray diffraction. The atomic radius of Co is slightly larger than that of Ni so a peak shift to the left is expected and observed. The second

pattern in Figure 3.2 displays the 400 reflection and the slight shift once Co is introduced into the α -CeNiSb₃ structure type.



Figure 3.2 X-ray diffraction powder patterns of $\text{CeNi}_x\text{Co}_{1-x}\text{Sb}_3$ and α -CeNiSb₃. The pattern on the left is the full spectrum for each compound and the pattern to the right displays the shift seen in the 400 peak.

3.3.2 Physical Properties

The magnetic susceptibility (χ vs T) measured at an applied field of 0.2 T for 10 mg of single crystals of CeNi_{0.78}Co_{0.22}Sb₃ is shown in Figure 3.3. The magnetic field is oriented along the *c*-axis of the crystals. A ferromagnetic transition is observed at ~ 4.6 K which is lower than the 6 K ordering temperature of the α -CeNiSb₃.⁹ Although the Ni atoms in pure CeNiSb₃ do not contribute directly to the magnetism, the insertion of Co into this sublattice may disrupt the overall magnetic moment. From the inverse susceptibility versus temperature plot from 50 K – 150 K, the experimental effective moment of 2.43 $\mu_{\rm B}$ /Ce and a Weiss temperature (θ) of 41 K were obtained. The $\mu_{\rm eff}$ of 2.43 $\mu_{\rm B}$ is close to the calculated 2.54 $\mu_{\rm B}$ for the Ce³⁺ ion.¹ This is consistent with the magnetic contribution due solely to the Ce³⁺. The average effective moment of α -CeNiSb₃ is 2.58 $\mu_{\rm B}$ /Ce and the values for the Weiss constant, θ are -156 along the *ab* plane and 29 K along the *c*-axis.⁹

The magnetization as a function of vield (M vs H) measured at 3 K on the same sample



Figure 3.3 The magnetic susceptibility (M vs T) measured at an applied field of 0.2 T of CeNi_{0.780}Co_{0.220}Sb₃.

of CeNi_{0.78}Co_{0.22}Sb₃ is shown in Figure 3.4. At $H \sim 1$ T, the magnetization begins to show signs of slow saturation well below the theoretical saturation moment of 2.14 $\mu_{\rm B}$ for Ce³⁺. A similar result is observed in the pure material, which has a large magnetocrystalline anisotropy and shows evidence for a modest Kondo interaction, with the ground state being a crystal-field-split doublet of Ce.⁹



Figure 3.4 The magnetization as a function of field (M vs H) measured at 3 K of $CeNi_{0.780}Ce_{0.220}Sb_3$.

The resistivity as a function of temperature for a single crystal of $\text{CeNi}_{0.78}\text{Co}_{0.22}\text{Sb}_3$ is shown in Figure 3.5. The current has been applied along the *b*-axis (in-plane). The overall shape of the curve is similar to that of α -CeNiSb₃⁸ and is weakly temperature dependent and characteristic of Kondo systems. However, the minimum observed near 27 K is much deeper here than it is for pure CeNiSb₃, which could be due to more Kondo-like behavior of the doped



Figure 3.5 The resistivity of $CeNi_{0.780}Co_{0.220}Sb_3$ measured between 2 and 290 K.

sample. This effect is analogous to the physical pressure effects observed in another Kondo lattice system, $CeAl_2$.¹⁰ Below ~ 5 K (T_c) the resistivity decreases very quickly, in response to the reduction in the spin disorder scattering.

The magnetoresistance at 3 K of $\text{CeNi}_{0.78}\text{Co}_{0.22}\text{Sb}_3$ is shown in Figure 3.6. Unlike usual ferromagnets, the magnetoresistance is positive, increasing to over 10% by 9 T. The shape of the magnetoresistance essentially tracks the magnetization of the sample for the field applied along the same direction which may be due to the magnetic anisotropy of the crystal.

The slightly lower ferromagnetic ordering temperature, smaller saturation moment, and deeper minimum in the resistivity data summarize the effects of Co substitution on pure CeNiSb₃ for this concentration.



Figure 3.6. The magnetoresistance of $CeNi_{0.780}Ce_{0.220}Sb_3$ at 3 K taken from 0 to 9 T.

3.4 References

- (1) Kittel, C.; 7th ed.; John Wiley & Sons, Inc.: New York, 1995.
- (2) Gautreaux, D. P.; Parent, M.; Moldovan, M.; Young, D. P.; Chan, J. Y. *Physica B* **2008**, *403*, 1005-1006.
- (3) Duc, N. H.; Goto, T. *Handbook on the Physics and Chemistry of Rare Earths*; Elsevier Science: Netherlands, 1999; Vol. vol. 26.
- (4) Duc, N. H.; Hien, T. D.; Brommer, P. E.; Franse, J. J. M. J. Magn. Magn. Mater. 1992, 104-107, 1252.
- (5) Manyala, N.; Sidis, Y.; DiTusa, J. F.; Aeppli, G.; Young, D. P.; Fisk, Z. *Nature* **2000**, *404*, 581-584.
- (6) Manyala, N.; Sidis, Y.; DiTusa, J. F.; Aeppli, G.; Young, D. P.; Fisk, Z. *Nature Mater*. **2004**, *3*, 255-262.

- (7) Sheldrick, G. M.; University of Gottingen: Germany, 1997.
- (8) Macaluso, R. T.; Wells, D. M.; Sykora, R. E.; Albrecht-Schmitt, T. E.; Mar, A.; Nakatsuji, S.; Lee, H.; Fisk, Z.; Chan, J. Y. *J. Solid State Chem.* **2004**, *177*, 293-298.
- (9) Siderov, V. A.; Bauer, E. D.; Lee, H.; Nakatsuji, S.; Thompson, J. D.; Fisk, Z. *Phys. Rev. B* **2005**, *71*, 094422-1 094422-4.
- (10) Nicolas-Francillon, M.; Percheron, A.; Achard, J. C. Solid State Comm. 1972, 11, 845-849.

CHAPTER 4 – $Ln(Cu_{1-x}Ni_x)_ySb_2$

4.1 Introduction

Antimonide compounds have been a focus of many research groups because of the interesting structural features and physical properties they possess.¹⁻⁴ All analogues of LnSb₂ (Ln = La – Nd, Sm) show positive, linear magnetoresistance at 2 K.⁵ Also of notable interest is LaSb₂, which has a positive, linear magnetoresistance below 10 K greater that 8,500 % with no signs of saturation up to 45 T.⁶ Adopting a similar layered structure, $LnNi_{1-x}Sb_2$ (Ln = Y, Dy, and Ho) analogues have large positive magnetoresistance above 100 % at 3 K.⁷ Single crystalline CeNiSb₂ is reported to order ferromagnetically at 6 K and has a Sommerfeld coefficient (γ) of 55 mJ mol⁻¹ K^{-2.8} It is important to note that the full structural determination has not been reported for CeNiSb₂ and the physical properties are similar to the fully characterized orthorhombic CeNiSb₃ which orders ferromagnetically at 6 K and has a Sommerfeld coefficient (γ) of ~50 mJ mol⁻¹ K^{-2,4,9} CeMSb₂ (M = Ni, Cu, Pd, and Ag) show dense Kondo behavior and polycrystalline CeNiSb₂ shows an enhanced electron mass.¹⁰ The magnetoresistance of polycrystalline CeCuSb₂ has been reported to be ~12.5 % at 4.5 T and 4.5 K.¹¹ CeCuSb₂, both in the polycrystalline and single-crystalline form, orders antiferromagnetically between $7 - 8 \text{ K.}^{8,10,12-15}$ CeCuSb₂ is also a heavy fermion with reported Sommerfeld coefficients (γ) of 94, 100, and 200 mJ mol⁻¹ K⁻².^{8,10,14,15}

In an effort to further determine structural stability of ternary Ce - Ni - Sb and Ce - Cu - Sb compounds, single crystals of various compositions of $Ce(Cu_{1-x}Ni_x)_ySb_2$ were obtained. The crystal structure, elemental analysis, magnetic and transport properties of $Ce(Cu_{1-x}Ni_x)_ySb_2$ (x = 0, 0.25, 0.37, and 0.46) are reported herein.

4.2 Experimental

4.2.1 Synthesis

High quality single crystals of $Ln(Cu_{1-x}Ni_x)_ySb_3$ were synthesized via flux growth by placing fragments of La or Ce rod (99.9% Alfa Aesar), Ni powder (99.999% Alfa Aesar), Cu powder (99.999% Alfa Aesar) and Sb shot (99.999% Alfa Aesar) in an alumina crucible. The nominal composition used was 1 : x : 1 - x : 20 (x = 0, 0.6, 0.7, 0.8) for Ce : Ni : Cu : Sb, where excess Sb was included as the flux. For the La analogue, the nominal composition of 1: 0.8: 0.2: 20 for La : Ni : Cu : Sb was used. Silica wool was placed on top of the crucible and was sealed under vacuum in a fused silica tube and placed in a furnace. The reaction vessel was heated to 1150 °C and held constant for 48 hours, then cooled to 670 °C at a rate of 5 °C h⁻¹. Excess flux was removed by centrifugation. Single crystals were extracted with sizes up to $0.5 \times 1 \times 2 \text{ mm}^3$ although the crystals tend to grow into larger, layered aggregates. The tetragonal plates are silver with a metallic luster. However, at lower concentrations of Cu, crystals gain a dull, bluegray iridescence and begin to resemble crystals of CeNiSb₃.⁴ The crystals are stable in air over a period of months. It is important to note that under our growth conditions, where the nominal value of x > 0.8, single crystals of CeNiSb₃ were grown. This will be discussed more in depth in the structural analysis section.

4.2.2 Single Crystal X-Ray Diffraction

A typical crystal with dimensions of ~ 0.05 x 0.10 x 0.175 mm³ was mounted onto a glass fiber of a goniometer with epoxy and placed on a Nonius Kappa CCD X-ray diffractometer (MoK_{α} = 0.71073 Å). After choosing the tetragonal space group *P4/nmm* (No. 129), the initial structural model was generated by SIR97¹⁶ and the model was then refined by direct methods using SHELXL97.¹⁷ Due to the similarity of *Z* for Ni and Cu, *X*-rays cannot accurately distinguish between the two. Therefore, the mixed transition metal site was refined as pure Cu for continuity and is designated as M. After refinement, the data were corrected for absorption and the displacement parameters were refined as anisotropic. An extinction coefficient was added and refined through multiple least squares cycles. A disagreeable thermal parameter for the transition metal site was observed and the site was allowed to be partially occupied. This is consistent with the partial transition metal occupancy observed in most other analogues of the HfCuSi₂ structure type. For simplicity, the exact partial occupancy will not be defined in the text for each compound as each value differs. It will be designated as y and the exact values will be listed in the crystallographic tables. Data collection parameters and crystallographic data are listed in Table 4.1. Atomic coordinates, anisotropic displacement parameters, and site occupancies are provided in Table 4.2.

4.2.3 Energy Dispersive Spectroscopy

Elemental analysis was performed on multiple single crystalline samples using the Hitachi S-3600N extra-large chamber variable pressure Scanning Electron Microscope (VP-SEM) with an integrated energy dispersive (EDS) feature. Data were collected over a small flux-free area on the surface of the crystals using an accelerating voltage of 20 kV and 50 s acquisition times. This analysis was performed due to the similar X-ray scattering of Ni and Cu. X-ray diffraction cannot distinguish between elements with similar Z and it is important to know the exact amounts of Ni and Cu in the sample. The transition metal site occupancy is consistent with the occupancy determined from single crystal X-ray diffraction data and formula compositions are located in Table 4.3. Is is important to note that the nominal and exact Ni/Cu concentrations do not agree, however there is a systematic increase of Ni in both the nominal and exact compositions. From this point on, the actual EDS compositions will be used.

Nominal <i>x</i>	0	0.6	0.7	0.8	0.8
SC Formula	$CeCu_{0.841}Sb_2$	$CeM_{0.707}Sb_2$	$CeM_{0.738}Sb_2$	$CeM_{0.665}Sb_2$	$LaM_{0.779}Sb_2$
Space Group	P4/nmm	P4/nmm	P4/nmm	P4/nmm	P4/nmm
<i>a</i> (Å)	4.3650(2)	4.3790(2)	4.3780(3)	4.3800(2)	4.4000(2)
<i>c</i> (Å)	10.0010(6)	9.8480(7)	9.8160(8)	9.7900(6)	10.0490(9)
$V(\text{\AA}^3)$	190.551(17)	188.842(18)	188.14(2)	187.815(17)	194.55(2)
Crystal size (mm ³)	0.05/0.13/0.17	0.05/0.13/0.13	0.05/0.10/0.13	0.08/0.13/0.15	0.05/0.08/0.10
Ζ	2	2	2	2	2
Temperature (°C)	25(2)	25(2)	25(2)	25(2)	25(2)
Density $(g \text{ cm}^{-1})$	7.793	8.897	8.930	8.945	8.615
θ Range (°)	2.04-30.02	2.07-29.93	2.07-29.94	2.08-30.02	2.03-29.98
μ (mm-1)	30.989	36.104	36.239	36.302	34.326
R _{int}	0.0386	0.0420	0.0613	0.0379	0.0360
Collected Reflections	541	466	356	489	460
Unique Reflections	204	203	181	194	207
h	$-6 \le h \le 6$	$-6 \le h \le 6$	$-6 \le h \le 6$	$-6 \le h \le 6$	$-6 \le h \le 6$
k	$-4 \le k \le 4$	$-4 \le k \le 4$	$-4 \le k \le 3$	$-4 \le k \le 4$	$-4 \le k \le 4$
l	- 14 ≤ <i>l</i> ≤ 14	$-10 \le l \le 13$	$-13 \le l \le 9$	$-13 \le l \le 2$	$-14 \le l \le 10$
$\Delta \rho_{\rm max}$ (e Å ⁻³)	3.005	3.4666	2.957	5.730	2.117
$\Delta \rho_{\min} (e \text{ Å}^{-3})$	-1.709	-5.727	-5.933	-4.593	-1.959
Extinction coefficient	0.050(6)	0.051(7)	0.22(2)	0.090(16)	0.029(3)
^a $R[F^2 > 2\sigma(F^2)]$	0.0379	0.0499	0.0466	0.0618	0.0286
^b $wR_2(F^2)$	0.1007	0.1207	0.1207	0.1661	0.0732

Table 4.1 Crystallographic Data for $Ln(Cu_{1-x}Ni_x)_{\nu}Sb_2$ (Ln = La or Ce)

 $\overline{{}^{a} R_{I}(F)} = \sum ||F_{0}| - |F_{c}|| / \sum |F_{0}|$

^b $R_w(F_0^2) = \sum [w(F_0^2 - F_c^2)] / \sum [w(F_0^2)^2]^{1/2}; w = 1/[\sigma^2(F_0^2) + (0.0547P)^2 + 3.3374P],$ $w = 1/[\sigma^2(F_0^2) + (0.1045P)^2 + 7.0979P], w = 1/[\sigma^2(F_0^2) + (0.0613P)^2 + 1.7761P],$ $w = 1/[\sigma^2(F_0^2) + (0.0840P)^2 + 3.5287P], w = 1/[\sigma^2(F_0^2) + (0.0358P)^2 + 3.9432P]$ for x = 0, 0.8, 0.7, 0.6, and 0.8(La) respectively

Table 4.2 Atomic Positions and Displacement Parameters for $Ln(Cu_{1-x}Ni_x)_ySb_2$ (Ln = La or Ce, M = mixture of Ni and Cu)

	Atom	Wyckoff site	x	у	Z.	$U_{\rm eq}({ m \AA}^2)^a$	Occupancy
CeCu _{0.841} Sb ₂							
x = 0	Ce1	2c	1⁄4	1⁄4	0.75381(8)	0.0066(4)	1
	Cu1	2a	3⁄4	1⁄4	0	0.0103(8)	0.841(10)
	Sb1	2c	1⁄4	1⁄4	0.14829(12)	0.0100(5)	1
	Sb2	2b	3⁄4	1⁄4	1/2	0.0079(4)	1

	Atom	Wyckoff site	X	У	Ζ.	$U_{ m eq}({ m \AA}^2)^a$	Occupancy
$CeM_{0.665}Sb_2$							
<i>x</i> = 0.8	Ce1	2c	1⁄4	1⁄4	0.75909(15)	0.0073(8)	1
	M1	2a	3⁄4	1⁄4	0	0.0063(14)	0.665(17)
	Sb1	2c	1⁄4	1⁄4	0.1367(8)	0.0136(8)	1
	Sb2	2b	3⁄4	1⁄4	1/2	0.0091(8)	1
$CeM_{0.738}Sb_2$							
<i>x</i> = 0.7	Ce1	2c	1⁄4	1⁄4	0.24163(9)	0.0062(6)	1
	M1	2a	3⁄4	1⁄4	0	0.0103(10)	0.738(10)
	Sb1	2c	1⁄4	1⁄4	0.86089(13)	0.0123(7)	1
	Sb2	2b	3⁄4	1⁄4	1/2	0.0075(7)	1
$CeM_{0.707}Sb_2$							
<i>x</i> = 0.6	Ce1	2c	1⁄4	1⁄4	0.75771(11)	0.0081(6)	1
	M1	2a	3⁄4	1⁄4	0	0.0083(10)	0.707(11)
	Sb1	2c	1⁄4	1⁄4	0.14063(16)	0.0139(6)	1
	Sb2	2b	3⁄4	1⁄4	1/2	0.0092(6)	1
$LaM_{0.779}Sb_2$							
<i>x</i> = 0.8	La1	2c	1⁄4	1⁄4	0.75641(11)	0.0067(4)	1
	M1	2a	3⁄4	1⁄4	0	0.0091(9)	0.779(10)
	Sb1	2c	1⁄4	1⁄4	0.13948(14)	0.0129(4)	1
	Sb2	2b	3⁄4	1⁄4	1/2	0.0082(4)	1

Table 4.2 (cont.)

 ${}^{a}U_{eq}$ is defined as one-third of the trace of the orthogonalized U_{ij} tensor.

Table 4.3 EDS Formula Compositions for $Ce(Cu_{1-x}Ni_x)_ySb_2$

Nominal Composition	Single Crystal Formula	EDS Formula
x = 0.8	$Ce(M)_{0.665}Sb_2$	$Ce(Ni_{0.46}Cu_{0.54})_{0.67}Sb_{2.16}$
x = 0.7	$Ce(M)_{0.738}Sb_2$	$Ce(Ni_{0.37}Cu_{0.63})_{0.74}Sb_{1.86}$
x = 0.6	$Ce(M)_{0.707}Sb_2$	$Ce(Ni_{0.25}Cu_{0.75})_{0.69}Sb_{2.16}$

4.2.4 Physical Property Measurements

Magnetic measurements on single crystals of $Ce(Cu_{1-x}Ni_x)_ySb_2$ oriented in the same direction were performed using a Quantum Design Physical Property Measurement System (PPMS). Temperature-dependent susceptibility data were measured with an applied field of 0.1 T from 2 K to 300 K. Magnetization as a function of field was measured at 3 K up to 9 T. The

resistivity from 2 K – 300K and magnetoresistance at 3 K (up to 9 T) were measured using the standard four probe-AC method in the Quantum Design PPMS at ambient pressure.

4.3 **Results and Discussion**

4.3.1 Structural Changes

 $Ln(Cu_{1-x}Ni_x)_{y}Sb_2$ (Ln = La, Ce) crystallizes in the tetragonal space group P4/nmm with the HfCuSb₂ structure type.¹⁸ As indicated in Tables 4.1 and 4.3, the nominal and exact compositions of Ni and Cu do not agree. However, there is a systematic increase of Ni in both the nominal and exact compositions. For consistency throughout this document, the compounds will be referred to by their actual compositions. We believe that there is a limit to the amount of Ni that can occupy the transition metal site when there is a large rare earth cation such as Ce present in the structure under our growth conditions. When too much Ni is added to the reaction mixture, the tetragonal structure can no longer be supported and the stable phase that forms is the CeNiSb₃ structure type.⁴ This theory is supported by earlier work where pure $LnNiSb_2$ can only be formed in the presence of smaller rare earth cations (Gd – Er, Y).⁷ In the presence of larger rare earth ions such as Ce – Sm, the orthorhombic $LnNiSb_3$ structure is formed using the Sb flux growth method.^{4,19} We note that other experimental techniques such as arc-melting have yielded $LnNiSb_2$ (Ln = Pr, Nd, Sm).¹²

As previously stated, $Ln(Cu_{1-x}Ni_x)_ySb_2$ (Ln = La, Ce) crystallizes in the tetragonal space group *P4/nmm*. The structure consists of alternating layers of Sb2 square nets capped by Ln1square antiprismatic layers and *M*1-Sb1 tetrahedral layers as shown in Figure 4.1. The Ln atoms are coordinated to four Sb1 atoms from the *M* tetrahedral layer and four Sb2 atoms from the net layer, forming a slightly distorted square antiprism. The *M* atoms are surrounded by four Sb1 atoms adopting a somewhat distorted tetrahedral geometry. This layered antimonide structure is similar to the orthorhombic $LnSb_2$ structure type which also includes alternating layers of Sb nets and $LnSb_8$ square antiprismatic layers.²⁰



Figure 4.1 Crystal structure of $Ce(Cu_{1-x}Ni_x)_ySb_2$ as viewed down the *b*-axis where the yellow spheres refer to the Ce atoms, the green spheres refer to a mixture of Ni and Cu atoms and the maroon spheres refer to the Sb atoms.

Table 4.4 contains selected interatomic distances and Sb2 – M1 – Sb2 tetrahedral angles. As more Ni is introduced into the structure, the overall volume decreases which is expected because Ni has a slightly smaller radius (1.15 Å) than Cu (1.17 Å). Also, the M1 tetrahedra show more distortion as the amount of Ni added to the structure is increased as indicated by the Sb2 – M1 – Sb2 angles listed in Table 4.4. As expected, the M1 – Sb2 distances decrease as a function of additional Ni introduced into the structure. The M1 – Sb2 distances range from 2.6387(7) Å for pure CeCu_{0.84}Sb₂ to 2.5668(12) Å for Ce(Cu_{0.54}Ni_{0.46})_{0.67}Sb₂. The addition of Ni has very little effect on the Sb2 square nets as the Sb2 – Sb2 distances show hardly any change (3.08652(14) Å – 3.09713(14) Å), and there is no visible distortion as the Ni content increases.

				•
	<i>x</i> = 0.46	<i>x</i> = 0.37	<i>x</i> = 0.25	x = 0
Ce1-Sb1(x4)	3.2607(9)	3.2552(5)	3.2543(6)	3.2381(4)
Ce1-Sb2(x4)	3.3511(12)	3.3502(7)	3.3519(8)	3.2902(6)
<i>M</i> 1-Sb1(x4)	2.5668(12)	2.5800(7)	2.5907(9)	2.6387(7)
Sb2 - Sb2(x4)	3.09713(14)	3.0957(2)	3.09642(14)	3.08652(14)
Sb1 - M1 - Sb1(x2)	117.12(9)	116.09(5)	115.37(6)	111.61(4)
Sb1 - M1 - Sb1(x4)	105.79(4)	106.27(2)	106.60(3)	108.41(2)

Table 4.4 Selected Interatomic Distances (Å) and Angles (°) for $Ce(Cu_{1-x}Ni_x)_ySb_2$

4.3.2 Physical Properties

The magnetic susceptibility of $Ce(Cu_{1-x}Ni_x)_ySb_2$ (x = 0, 0.25, 0.37, 0.46) measured at an applied magnetic field of 0.1 T is shown in Figure 4.2. The actual compositions of x will be used to describe the samples in this section and the value of y is ~ 0.7. The Ni substituted $Ce(Cu_{1-x}Ni_x)_ySb_2$ analogues (x = 0.25, 0.37) appear to be paramagnetic down to 2 K. For $Ce(Cu_{1-x}Ni_x)_ySb_2$ (x = 0.46), a sharp kink in the data is observed at 11 K. This feature is consistent with



Figure 4.2 Magnetic susceptibility of $Ce(Cu_{1-x}Ni_x)_ySb_2$ measured at a field of 0.1 T where the green circles, black squares, blue triangles, and red diamonds refer to x = 0, 0.25, 0.37, and 0.46 respectively. The inset displays a close-up of the susceptibility from 2 - 20 K.

the onset of long-range antiferromagnetic order. CeCu_{0.84}Sb₂ (x = 0) orders antiferromagnetically at ~ 6 K which is consistent with literature reports.^{8,10,12-15} The effective moments for each sample were calculated using a modified Curie-Weiss equation, $\chi = \chi_0 + C/(T - \theta)$, where χ is the magnetic susceptibility, χ_0 is the temperature-independent contribution, *C* is the Curie constant, *T* is the temperature, and θ is the Weiss constant. Experimental effective moments of 2.32 μ_B , 2.44 μ_B , 2.38 μ_B , and 2.31 μ_B were calculated for compounds with x = 0.46, 0.37, 0.25, and 0 respectively, and all are in agreement with the calculated moment of 2.54 μ_B for the free Ce³⁺ ion. Curie temperatures of ~ -62, -35, -25, and -225 were observed for compounds with x = 0.46, 0.37, 0.25, and 0, respectively and indicate that there are antiferromagnetic correlations within the structures. A summary of the magnetic data are located in Table 4.5.

Table 4.5	able 4.5 Summary of Magnetic Data for $Ce(Cu_{1-x}Ni_x)_ySb_2$ ($x = 0.8, C$							
x^a	0.46	0.37	0.25	0				
Fit Range	50 – 275 K	50 – 275 K	100 – 275 K	75 – 250 K				
$T_N(\mathbf{K})$	11	-	-	8				
χο	0.00125	0.000578	0.00296	0.00102				
С	0.6716	0.7455	0.7058	0.6685				
θ (K)	-62.54	-34.593	-24.72	-225.17				
$\mu_{ m calc}$ ($\mu_{ m B}$)	2.32	2.44	2.38	2.31				
$\mu_{\mathrm{eff}}\left(\mu_{\mathrm{B}}\right)$	2.54	2.54	2.54	2.54				
a ·	$\cdot 1 \cdot 1$		1 .					

Table 4.5 Summary of Magnetic Data for $Ce(Cu_{1-x}Ni_x)_ySb_2$ (x = 0.8, 0.7, 0.6, and 0)

 $x^{*} =$ composition as obtained from elemental analysis

The magnetization of Ce(Cu_{1-x}Ni_x)_ySb₂ (x = 0.46, 0.37, 0.25, and 0) as a function of field (up to 9 T) measured at 3 K are shown in Figure 4.3. The magnetization of pure CeCu_{0.84}Sb₂ is linear with field, consistent with antiferromagnetism below 6K. None of the Ni-substituted compounds show any signs of saturation. The calculated saturation moment for a Ce³⁺ free ion is 2.14 μ_B . The magnetization of each analogue follows the same general curvature. There are no signs of any hysteresis in any of the compounds measured. The magnetization of all

analogues measured is small which suggests either a strong anisotropy or partial screening of the Ce moments by conduction electrons.



Figure 4.3 Magnetism of Ce(Cu_{1-x}Ni_x)_ySb₂ measured at 3 K where the green circles, black squares, blue triangles, and red diamonds refer to x = 0, 0.25, 0.37, and 0.46 respectively.

Resistivity data were measured as a function of temperature for each analogue and are displayed in Figure 4.4. All of the analogues display broad shoulders in the resistivity data as the temperature decreases which is indicative of Kondo behavior. Also, the classic upturn of the resistivity at low temperatures is seen for Ce(Cu_{1-x}Ni_x)_ySb₂ (x = 0.37 and 0.25). The resistivity data coupled with the screening of the Ce³⁺ moment seen in the magnetization data are signals that these compounds are more Kondo-like. A sharp kink in the resistivity data for the x = 0 and x = 0.46 samples is observed at their ordering temperatures, consistent with a decrease in the spin-disorder scattering (Figure 4.4, arrows).

The magnetoresistance at fields up to 9 T measured at 3 K is displayed in Figure 4.5 for the Ce analogues. The magnetoresistance for all analogues is larger than typical metals. The magnetoresistance of $CeCu_ySb_2$ increases quickly up to ~ 1 T then increases at a slower rate up



Figure 4.4 Resistivity of $Ce(Cu_{1-x}Ni_x)_ySb_2$ where the green circles, black squares, blue triangles, and red diamonds refer to x = 0, 0.25, 0.37, and 0.46 respectively.



Figure 4.5 Magnetoresistance of $Ce(Cu_{1-x}Ni_x)_ySb_2$ measured at 3 K where the green circles, black squares, blue triangles, and red diamonds refer to x = 0, 0.25, 0.37, and 0.46 respectively.

to ~165 % at 9 T. The magnetoresistance increases quickly up to ~ 1 T then begins to saturate at 77 %, and 80 % for x = 0.25, and 0.37 respectively. The magnetoresistance for Ce(Cu_{1-x}Ni_x)_ySb₂

(x=0.46) is similar to the other analogues up to ~ 1 T, then the behavior deviates and increases with no signs of saturation up to 100 % at 9 T. The magnetoresistance is not proportional to H^2 for all analogues, indicating that the magnetoresistive behavior is not classical. The magnetoresistance of nominal La(Cu_{0.2}Ni_{0.8})_ySb₂ measured at 3 K up to fields of 9 T is displayed in Figure 4.6. The magnetoresistance is significantly larger than the Ce analogues with the magnetoresistance saturating at ~ 300 %. This is not surprising as many La analogues have larger magnetoresistive behavior than other rare earth analogues such as LaSb₂.^{5,6}



Figure 4.6 Magnetoresistance of $La(Cu_{1-x}Ni_x)_ySb_2$ (nominal x = 0.8) measured at 3 K.

4.4 References

- (1) Mills, A. M.; Lam, R.; Ferguson, M. J.; Deakin, L.; Mar, A. Coord. Chem. Rev. 2002, 233-234, 207-222.
- (2) Sologub, O.; Salamakha, P. S. *Handbook on the Physics and Chemistry of Rare Earths*; Elsevier: Netherlands, 2003; Vol. 33.
- (3) Kauzlarich, S. M. Chemistry, Structure, and Bonding in Zintl Phases and Ions; VCH Publishers: New York, 1996.
- (4) Macaluso, R. T.; Wells, D. M.; Sykora, R. E.; Albrecht-Schmitt, T. E.; Mar, A.; Nakatsuji, S.; Lee, H.; Fisk, Z.; Chan, J. Y. *J. Solid State Chem.* **2004**, *177*, 293-298.

- (5) Bud'ko, S. L.; Canfield, P. C.; Mielke, C. H.; Lacerda, A. H. *Phys. Rev. B* **1998**, *57*, 13624-13638.
- (6) Young, D. P.; Goodrich, R. G.; DiTusa, J. F.; Guo, S.; Adams, P. W.; Chan, J. Y.; Hall, D. *Appl. Phys. Lett.* **2003**, *82*, 3713-3715.
- (7) Thomas, E. L.; Moldovan, M.; Young, D. P.; Chan, J. Y. *Chem. Mater.* **2005**, *17*, 5810-5816.
- (8) Thamizhavel, A.; Takeuchi, T.; Okubo, T.; Yamada, M.; Asai, R.; Kirit, S.; Galatanu, A.; Yamamoto, E.; Ebihara, T.; Inada, Y.; Settai, R.; Onuki, Y. *Phys. Rev. B* **2003**, *68*, 54427.
- (9) Siderov, V. A.; Bauer, E. D.; Lee, H.; Nakatsuji, S.; Thompson, J. D.; Fisk, Z. Phys. Rev. B 2005, 71, 094422-1 - 094422-4.
- (10) Muro, Y.; Takeda, N.; Ishikawa, M. J. Alloys Compd. 1997, 257, 23-29.
- (11) Lakshmi, K. V.; Menon, L.; Nigam, A. K.; Das, A.; Malik, S. K. *Physica B* **1996**, 223 & 224, 289-291.
- (12) Sologub, O.; Hiebl, K.; Rogl, P.; Noël, H.; Bodak, O. J. Alloys Compd. **1994**, 210, 153-157.
- (13) Flandorfer, H.; Sologub, O.; Godart, C.; Hiebl, K.; Leith-Jasper, A.; Rogl, P.; Noel, H. *Solid State Commun.* **1996**, *97*, 561-565.
- (14) Koyama, T.; Matsumoto, M.; Wada, S.; Muro, Y.; Ishikawa, M. J. Phys. Soc. Jpn. 2001, 70, 3667-3672.
- (15) Thamizhavel, A.; Okubo, T.; Yamada, M.; Galatanu, A.; Yamamoto, E.; Inada, Y.; Ebihara, T.; Onuki, Y. *Physica B* **2003**, *327*, 374-377.
- (16) Altomare, A.; Burla, M. C.; Camalli, M.; Cascarno, G. L.; Giacovazzo, A.; Guagliardi, A.; Moliterni, A. G. G.; Polidori, G.; Spagna, R. J. J. Appl. Crystallogr. 1999, 32, 115-119.
- (17) Sheldrick, G. M.; University of Gottingen: Germany, 1997.
- (18) Andrukhiv, L. S.; Lysenko, L. O.; Yarmolyuk, Y. P.; Hladyshevsky, E. I. Dopov. Akad. Nauk Ukr. RSR, Ser. A 1975, 7, 645-648.
- (19) Thomas, E. L.; Macaluso, R. T.; Lee, H.; Fisk, Z.; Chan, J. Y. J. Solid State Chem. 2004, 177, 4228-4236.
- (20) Wang, R.; Steinfink, H. Inorg. Chem. 1967, 6, 1685-1692.

CHAPTER $5 - Rb_4 M(MoO_4)_3$

5.1 Introduction

The existence of ferroelectricity and magnetism in a single material has generated interest in recent years because the two phenomena were previously thought to not coexist in the same material. This new, exciting field has been termed multiferroics and researchers are working to understand the mechanisms by which these two phenomena can coexist simultaneously. This research is fueled by the promise of numerous practical applications such as conventional actuators, transducers, data storage, or memory media.¹

One of the more well known mechanisms for ferroelectricity in a perovskite such as BaTiO₃, has the Ti⁴⁺ ion shifted towards the corner of the unit cell which creates electric polarization inducing a charge transfer from filled oxygen 2p orbitals into the empty d-orbitals of the transition metal.^{1,2} Empty *d*-orbitals are necessary for magnetism to exist, so this mechanism is not conducive to multiferroism. Another mechanism for off-center distortion of the transition metal site is found in materials with a ns^2 lone pair which displaces the parent cation leading to the loss of inversion symmetry.¹ There are both proper and improper inversion symmetry breaking mechanisms.³ Covalent bonding between $3d^0$ transition metal and oxygen seen in BaTiO₃ and $6s^2$ lone pair polarization seen in compounds such as BiMnO₃, BiFeO₃, and $Pb(Fe_{2/3}W_{1/3})O_3$ are examples of the proper mechanism for losing inversion symmetry.³ Examples of improper loss of inversion symmetry mechanisms include structural transitions as seen in K₂SeO₄, Cs₂CdI₄, and hexagonal RMnO₃, charge ordering as seen in LuFe₂O₄, and magnetic ordering as seen in RMn₂O₅, CoCr₂O₄, and the orthorhombic RMnO₃.³ These mechanisms apply only to ferroelectricity and typically do not allow for the simultaneous presence of a magnetic moment.

Multiferroic materials were in short supply until 2003, when Kimura *et al.* discovered that spin frustration causes antiferromagnetic ordering in TbMnO₃.⁴ This rekindled interest in multiferroic materials and the quest was on to understand and discover more of these intriguing materials with frustrated spin systems. In 2007, another mechanism came to light in frustrated magnets where a magnetic spiral structure breaks inversion symmetry and leads to the presence of electric polarization.^{3,5} In 2008 CuO, a centrosymmetric material, was identified as an induced-multiferroic which has a proper-screw magnetic.⁶ This new mechanism will be useful in identifying other possible multiferroic materials.

As indicated above, crystal symmetry plays an integral role in predicting and understanding multiferroic behavior in materials. This is the motivation for the present work. Full structural determination, understanding temperature induced phase transitions, and the analyses of disorder in crystals are important in understanding the properties of these materials. The crystal structural studies of the possible multiferroic double molybdates, $Rb_4M(MoO_4)_3$, (*M* = Mn, Zn, Cu) are reported herein.

5.2 Structural Studies by Single Crystal X-Ray Diffraction

The single crystal X-ray diffraction data of Rb₄M(MoO₄)₃ (M = Mn, Zn, and Cu) were collected at various temperatures. Due to the extremely hygroscopic nature of the samples, the crystals were placed in Paratone-N oil to protect the sample from exposure to air and moisture. A crystal with approximate dimensions of ~ 0.05 x 0.125 x 0.125 mm³ was mounted onto a glass fiber of the goniometer with epoxy and/or vacuum grease and placed on a Nonius Kappa CCD X-ray diffractometer (MoK_{α} = 0.71073 Å). Temperature was regulated with a cooled nitrogen gas stream produced by an Oxford Cryostream Cooler. The unit cell parameters were determined from images taken at a rotation of 15 ° φ . Initial structural models were solved by

SIR97⁷ and refined by direct methods using SHELXL97⁸. The data were corrected for absorption and the displacement parameters were refined as anisotropic.

5.2.1 $Rb_4Mn(MoO_4)_3$

The single crystal X-ray diffraction data was collected at various temperatures for Rb₄Mn(MoO₄)₃. Data were collected at 298 K, 270 K, and 100 K. The crystal measured had dimensions of ~ 0.05 x 0.125 x 0.125 mm³. There were two suitable structural models in two different, hexagonal space group choices: $P\overline{6}2c$ (# 190) and $P6_3/mmc$ (# 194). $P\overline{6}2c$ (# 190) is a non-centrosymmetric space group while $P6_3/mmc$ (# 194) is a centrosymmetric space group. The main difference between the two space groups is the presence of three mirrors perpendicular to the rotation axis in the higher symmetry space group. The systematic absences are the same for both space groups. Powder patterns were calculated from the single crystal models and both patterns were identical and matched the experimental powder pattern as shown in Figure 5.1.



Figure 5.1 Experimental (red) and calculated (black) powder patterns for $Rb_4Mn(MoO_4)_3$.

Previous structural reports indicate acceptable structural models in three hexagonal space groups: $P6_3/mmc$, $P6_3mc$, and $P\overline{6}2c$. However, the centrosymmetric $P6_3/mmc$ was ruled out due to piezoelectric effects.⁹ We chose the higher symmetry $P6_3/mmc$ model because the data was in slightly better agreement than the lower symmetry $P\overline{6}2c$ model based on R-factors of 2.88 % for the $P6_3/mmc$ model and 4.04 % for the $P\overline{6}2c$ model. Also, because the polarization measurements have not been measured on our crystals, we cannot use that as reasoning for choosing the non-centrosymmetric structural model. The crystallographic information for Rb₄Mn(MoO₄)₃ is located in Table 5.1 and the atomic parameters are located in Table 5.2.

Sample	dixie67	dixie68	dixie69
Formula	$Rb_4Mn(MoO_4)_3$	$Rb_4Mn(MoO_4)_3$	$Rb_4Mn(MoO_4)_3$
Formula units (amu)	876.64	876.64	876.64
Space Group	$P6_3/mmc$	$P6_3/mmc$	<i>P</i> 6 ₃ / <i>mmc</i>
a (Å)	6.0989(2)	6.0919(3)	6.0529(4)
<i>b</i> (Å)	6.0989(2)	6.0920(3)	6.0529(4)
<i>c</i> (Å)	23.7107(6)	23.7248(9)	23.7010(10)
$V(\text{\AA}^3)$	763.80(4)	762.51(6)	752.01(8)
Crystal size (mm ³)	0.025/0.075/0.075	0.025/0.075/0.075	0.025/0.075/0.075
Ζ	2	2	2
Temperature (K)	298	270	100
Density (g cm ^{-1})	3.812	3.818	3.871
θ Range (°)	3.44-29.98	3.43-30.02	3.44-30.00
$\mu (\text{mm}^{-1})$	15.923	15.950	16.173
R _{int}	0.0531	0.0725	0.0907
Collected Reflections	2762	2510	2530
Unique Reflections	489	489	482
h	$-8 \le h \le 8$	$-8 \le h \le 8$	$-8 \le h \le 8$
k	$-6 \le k \le 6$	$-6 \le k \le 6$	$-6 \le k \le 6$
l	$-32 \le l \le 32$	$-33 \le l \le 25$	$-28 \le l \le 33$
$\Delta \rho_{\rm max}$ (e Å ⁻³)	0.892	1.514	1.380
$\Delta \rho_{\rm min} ({\rm e}{\rm \AA}^{-3})$	-1.134	-0.828	-1.948
Extinction coefficient	0.0049(8)	0.0040(7)	0.0072(9)
^a R(<i>F</i>) for $F_{o}^{2} > 2\sigma(F_{o}^{2})$	0.0288	0.0334	0.0396
^b $\mathbf{R}_{w}(F_{o}^{2})$	0.0749	0.0766	0.0949

Table 5.1Crystallographic Data for Rb₄Mn(MoO₄)₃

 $\overline{{}^{a} R_{1}(F)} = \sum ||F_{0}| - |F_{c}|| / \sum |F_{0}|$

^b $R_w(F_o^2) = \sum [w(F_o^2 - F_c^2)^2] / \sum [w(F_o^2)^2]^{1/2}$; where $w = 1/[\sigma^2(F_0^2) + (0.0421P)^2 + 0.7989P]$,

 $w = 1/[\sigma^2(F_0^2) + (0.0419P)^2], w = 1/[\sigma^2(F_0^2) + (0.0568P)^2]$ for dixie67, dixie68, and dixie69 respectively.

Atom	Wyckoff site	x	у	Z.	$U_{\rm eq}({ m \AA}^2)^a$	Occupancy
dixie67	7 – 298 K					
Rb1	4f	1/3	2/3	0.15755(3)	0.0344(3)	1
Rb2	4f	2/3	1/3	0.02849(3)	0.0283(3)	1
Mn1	2a	0	0	1/4	0.0281(4)	1
Mo1	4e	0	0	0.09016(2)	0.0196(2)	1
Mo2	4f	2/3	1/3	0.22782(6)	0.0255(5)	0.48
01	4e	0	0	0.1645(2)	0.056(2)	1
O2	12k	0.1555(3)	0.3109(6)	0.06565(15)	0.0406(9)	1
03	4f	2/3	1/3	0.1557(4)	0.047(6)	0.50
O4	12 <i>j</i>	0.3859(12)	0.3283(13)	1/4	0.041(2)	0.51
dixie68	3 – 270 K					
Rb1	4f	1/3	² / ₃	0.15755(3)	0.0306(3)	1
Rb2	4f	2/3	1/3	0.02850(4)	0.0244(3)	1
Mn1	2a	0	0	1/4	0.0240(5)	1
Mo1	4e	0	0	0.09006(3)	0.0167(2)	1
Mo2	4f	² / ₃	1/3	0.22787(7)	0.0216(6)	0.48
01	4e	0	0	0.1647(2)	0.053(2)	1
O2	12k	0.1556(3)	0.3112(7)	0.06566(16)	0.0352(10)	1
O3	4f	2/3	1/3	0.1556(4)	0.037(6)	0.50
O4	12 <i>j</i>	0.3840(13)	0.3286(14)	1⁄4	0.037(3)	0.52
dixie69	9 – 100 K					
Rb1	4f	1/3	2/3	0.15728(4)	0.0176(4)	1
Rb2	4f	² / ₃	1/3	0.02879(4)	0.0143(4)	1
Mn1	2a	0	0	1/4	0.0164(6)	1
Mo1	4e	0	0	0.08945(3)	0.0113(3)	1
Mo2	4f	² / ₃	1/3	0.22778(9)	0.0160(8)	0.48
01	4e	0	0	0.1649(3)	0.033(3)	1
O2	12k	0.1568(5)	0.3136(10)	0.0649(2)	0.0233(13)	1
O3	4f	2/3	1/3	0.1551(6)	0.016(6)	0.46
O4	12 <i>j</i>	0.385(2)	0.332(2)	1⁄4	0.028(3)	0.50

 Table 5.2
 Atomic Positions and Displacement Parameters for Rb₄Mn(MoO₄)₃

 ${}^{a}U_{eq}$ is defined as one-third of the trace of the orthogonalized U_{ij} tensor.

Figure 5.2 displays the structure of $Rb_4Mn(MoO_4)_3$ as well as the coordination around the Mn1 atom. The structure consists of MnO₅ trigonal bipyramids surrounded by five Mo tetrahedra: two Mo2 tetrahedra in the capping positions and three Mo1 tetrahedra in the basal plane. $Rb_4Mn(MoO_4)_3$ is isostructural to $Cs_4Cu(MoO_4)_3$.⁹ There are several atoms in this structure that are disordered. The three O4 atoms in the basal plane of the Mn trigonal bipyramid and each Mo2, O3, and O4 atoms that comprise the Mo2 tetrahedra are disordered. This disorder is displayed by $\frac{1}{2}$ occupied sites in the atomic positions. The Mo2 tetrahedra seem to be inverted

and staggered as seen in Figure 5.2, however each Mo2 and surrounding O atoms are ¹/₂ occupied throughout the entire extended structure.



Figure 5.2 (a) Crystal structure of $Rb_4Mn(MoO_4)_3$ where the blue, green, purple, and red spheres refer to Rb, Mn, Mo, and O atoms respectively. (b) The Mn bonding environment of $Rb_4Mn(MoO_4)_3$.

5.2.2 Rb₄Zn(MoO₄)₃

The lattice (a = 10.90, b = 22.42, and c = 6.271 Å) and space group ($Pn2_1a$) were previously reported for β -Rb₄Zn(MoO₄)₃ however, no full structural determination was reported.¹⁰ The crystal structure of Rb₄Zn(MoO₄)₃ was determined by X-ray diffraction and based on our experimentation, Rb₄Zn(MoO₄)₃ crystallizes in the orthorhombic space group *Pbca* (# 61) and adopts a new structure type with lattice parameters of a = 12.574(2) Å, b =10.9130(10) Å, and c = 22.3320(10) Å at room temperature. A crystal coated with Paratone-N oil and dimensions of ~ 0.05 x 0.10 x 0.125 mm³ was measured at 290 K and 100 K. After collecting full data at 290 K, the crystal was slowly cooled and scans at a rotation of 15 ° φ were taken in 20 K increments and no temperature induced structural transitions were observed for $Rb_4Zn(MoO_4)_3$. Crystallographic information for $Rb_4Zn(MoO_4)_3$ is located in Table 5.3 and the atomic parameters are located in Table 5.4.

Sample	dixie75	dixie76
Formula	$Rh_{2}Tn(M_{0}O_{1})$	Rh.Zn(MoQ.).
Formula units (amu)	887 07	887 07
Space Group	Phoa	Phca
$a(\dot{A})$	12574(2)	12485(2)
$h(\dot{\Lambda})$	12.374(2) 10.9130(10)	10.8750(10)
$c(\dot{A})$	22 3320(10)	22 2660(10)
$V(\dot{A}^3)$	3064 4(6)	3023 2(6)
Crystal size (mm ³)	0.05/0.10/0.125	0.05/0.10/0.125
Z	8	8
Temperature (K)	290	100
Density $(g \text{ cm}^{-1})$	3.845	3.898
θ Range (°)	2.44-30.04	2.45-30.02
$u (\text{mm}^{-1})$	16.617	16.843
R _{int}	0.0703	0.0535
Collected Reflections	8345	8235
Unique Reflections	2478	2922
h	$-17 \le h \le 17$	$-17 \le h \le 17$
k	$-15 \le k \le 15$	$-15 \le k \le 15$
l	-31 < <i>l</i> < 31	-31 < l < 31
$\Delta \rho_{\rm max}$ (e Å ⁻³)	4.515	2.495
$\Delta \rho_{\rm min}$ (e Å ⁻³)	-2.607	-1 940
Extinction coefficient	0.00052(4)	0 000134(18)
^a R(F) for $F_{0}^{2} > 2\sigma(F_{0}^{2})$	0.0537	0.0456
${}^{b}R_{w}(F_{0}^{2})$	0.1132	0.0919
$\frac{a}{a} \mathbf{p}(\mathbf{E}) = \sum \left\ \mathbf{E} \right\ + \left\ \mathbf{E} \right\ / \sum \left\ \mathbf{E} \right\ $		
$\operatorname{Ki}(\mathbf{F}) = \sum \ \mathbf{F}\ - \mathbf{F}_c\ /2$		
$^{\text{D}} R_{w}(F_{*}^{2}) = \sum [w(F_{*}^{2} - F_{*}^{2})]$	$(F_{r}^{2})^{2}]/\sum [w(F_{r}^{2})^{2}]^{1/2}$; where	$w = 1/[\sigma^2(F_c^2) + (0.0579P)^2],$

Table 5.3Crystallographic Data for Rb₄Zn(MoO₄)₃

^b $R_w(F_o^2) = \sum [w(F_o^2 - F_c^2)^2] / \sum [w(F_o^2)^2]^{1/2}$; where $w = 1 / [\sigma^2(F_0^2) + (0.0579P)^2]$, $w = 1 / [\sigma^2(F_0^2) + (0.0394P)^2 + 9.0735P]$ for dixie75 and dixie76 respectively.

Table 5.4Atomic Positions and Displacement Parameters for Rb₄Zn(MoO₄)₃

Atom	Wyckoff site	x	у	Z.	$U_{ m eq}({ m \AA}^2)^a$	
dixie75	5 – 290 K					
Rb1	8c	0.62666(7)	0.91895(7)	0.97177(4)	0.0217(2)	
Rb2	8c	0.87590(7)	0.08521(7)	0.03049(4)	0.0277(2)	
Rb3	8c	0.10741(7)	0.57137(8)	0.83923(3)	0.0281(2)	
Rb4	8c	0.62284(7)	0.59654(8)	0.84237(3)	0.0297(2)	

1 able 5.4 (Cont.)	Table	5.4	(cont.)
---------------------------	-------	-----	---------

Atom	Wyckoff site	x	у	Z	$U_{ m eq}({ m \AA}^2)^a$
Zn1	8 <i>c</i>	0.32058(8)	0.71852(9)	0.75362(4)	0.0210(2)
Mo1	8c	0.37569(6)	0.74745(6)	0.90548(3)	0.01751(18)
Mo2	8c	0.87314(6)	0.75371(6)	0.90623(3)	0.01718(17)
Mo3	8c	0.37405(6)	0.42351(6)	0.73335(3)	0.02164(19)
01	8c	0.3700(5)	0.7450(6)	0.6745(3)	0.0362(16)
O2	8c	0.4974(5)	0.4610(6)	0.7621(3)	0.0361(15)
O3	8c	0.3952(5)	0.7523(5)	0.8246(2)	0.0340(16)
O4	8c	0.5129(5)	0.1799(5)	0.9321(2)	0.0325 (15)
O5	8c	0.2805(5)	0.5423(5)	0.7539(2)	0.0301(15)
06	8c	0.1731(5)	0.7797(5)	0.7613(2)	0.0308(14)
O7	8c	0.2597(5)	0.6703(6)	0.9237(2)	0.0424(17)
08	8c	0.3684(5)	0.8973(5)	0.9332(3)	0.0385(17)
09	8c	0.3829(6)	0.4163(6)	0.6567(2)	0.0429(19)
O10	8c	0.4835(5)	0.6722(6)	0.9368(2)	0.0380(16)
011	8c	0.6239(5)	0.4062(5)	0.9300(2)	0.0320(15)
O12	8c	0.7604(5)	0.6837(5)	0.9353(2)	0.0328(15)
dixie76	б – 100 К				
Rb1	8c	0.62709(5)	0.91860 (6)	0.97183(3)	0.01378(15)
Rb2	8c	0.87567(5)	0.08440(6)	0.03151(3)	0.01385(15)
Rb3	8c	0.10545(6)	0.57003(6)	0.83948(3)	0.01477(15)
Rb4	8c	0.62453(5)	0.59903(6)	0.84265(3)	0.01486(16)
Zn1	8c	0.32067(7)	0.71724(7)	0.75429(3)	0.01259(18)
Mo1	8c	0.37662(4)	0.74717(5)	0.90582(2)	0.00993(13)
Mo2	8c	0.87294(4)	0.75407(5)	0.90704(2)	0.01007(13)
Mo3	8c	0.37491(5)	0.42223(5)	0.73384(3)	0.01156(14)
01	8c	0.3690(4)	0.7428(4)	0.6740(2)	0.0205(11)
O2	8c	0.4986(4)	0.4614(4)	0.7629(2)	0.0165(10)
O3	8c	0.3980(4)	0.7525(4)	0.82513(19)	0.0167(11)
O4	8c	0.5121(4)	0.1802(4)	0.9333(2)	0.0188 (11)
05	8c	0.2808(4)	0.5400(4)	0.75474(19)	0.0168(10)
06	8c	0.1704(4)	0.7760(4)	0.7622(2)	0.0178(10)
O7	8c	0.2594(4)	0.6681(5)	0.9229(2)	0.0224(12)
08	8c	0.3683(4)	0.8969(4)	0.9333(2)	0.0201(11)
09	8c	0.3833(4)	0.4173(4)	0.65647(19)	0.0195(11)
O10	8c	0.4851(4)	0.6700(4)	0.9381(2)	0.0206(11)
011	8c	0.6227(4)	0.4084(4)	0.92981(19)	0.0167(11)
012	8 <i>c</i>	0.7585(4)	0.6840(4)	0.93782(19)	0.0174(11)

 $^{a}U_{eq}$ is defined as one-third of the trace of the orthogonalized U_{ij} tensor.

Figure 5.3 displays the crystal structure of $Rb_4Zn(MoO_4)_3$ as well as the Zn subunit. The layered structure consists of slightly distorted ZnO_4 tetrahedral units surrounded by four slightly less distorted Mo tetrahedra. The Zn tetrahedra form chains with Mo3 tetrahedra along the *b*axis and are capped by Mo1 and Mo3 tetrahedra in the *c*-direction. The O-Mo-O angles range


Figure 5.3 (a) Crystal structure of $Rb_4Zn(MoO_4)_3$ as viewed down the *a* axis where the blue, green, purple, and red spheres refer to Rb, Zn, Mo, and O atoms respectively. (b) Zn bonding environment of $Rb_4Zn(MoO_4)_3$.

from 107.9 ° - 111.1 ° for Mo1, 108.8 ° - 110.1 ° for Mo2, and 108.7 ° - 112.1 ° for Mo3 indicating a slight deviation from the expected angle of 109.5 °. The O-Zn-O angles range from 103.5 ° - 126.4 ° for the ZnO₄ tetrahedra indicating more distortion than the MoO₄ units. Selected interatomic distances and bond angles are located in Table 5.5. The distances are consistent with the ionic radii of Rb^{1+} , Zn^{2+} , and $Mo^{6+,11}$ The notable difference between this structure and the $Rb_4Mn(MoO_4)_3$ structure is the lack of disorder and the bonding environment of the transition metal. The Mn analogue consists of a Mn trigonal bipyramid while the Zn analogue contains slightly distorted Zn tetrahedra.

Mo1 – O7	1.740(5)	Rb1 – O9	2.860(4)	Rb2 – O10	2.866(5)
Mo1 – O8	1.742(5)	Rb1 – O8	2.915(5)	Rb2 – O12	2.886(5)
Mo1 – O10	1.748(5)	Rb1 – O4	2.939(5)	Rb2 – O11	2.965(4)
Mo1 – O3	1.817(4)	Rb1 – O7	3.018(5)	Rb2 - O8	3.152(5)

Table 5.5Selected Interatomic Distances (Å) for Rb₄Zn(MoO₄)₃

					Table 5.5 (cont.)
		Rb1 – O12	3.126(5)	Rb2 – O10	3.159(5)
Mo2 - O4	1.746(5)	Rb1 – O11	3.263(5)	Rb2 - O4	3.173(5)
Mo2 – O11	1.754(4)	Rb1 – O4	3.300(5)	Rb2 – O11	3.203(5)
Mo2 – O12	1.758(5)	Rb1 – O12	3.309(5)	Rb2 – O7	3.268(5)
Mo2 - O1	1.808(5)	Rb1 – O10	3.319(5)	Rb2 – O7	3.334(5)
		Rb1 – O8	3.352(5)		
Mo3 – O9	1.727(4)			Rb4 - O2	2.805(4)
Mo3 - O2	1.727(5)	Rb3 – O4	2.820(5)	Rb4 – O11	2.840(4)
Mo3 - O5	1.800(5)	Rb3 – O8	2.830(5)	Rb4 – O10	2.853(5)
Mo3 – O6	1.802(5)	Rb3 – O7	2.878(5)	Rb4 – O12	2.853(5)
		Rb3 – O2	2.893(5)	Rb4 - O5	2.986(5)
Zn1 – O3	1.889(5)	Rb3 – O5	2.908(5)	Rb4 – O6	3.079(5)
Zn1 – O1	1.908(5)	Rb3 – O6	2.939(4)	Rb4 – O3	3.307(5)
Zn1 – O6	1.990(5)	Rb3 – O9	3.234(5)		
Zn1 – O5	1.991(5)				

5.2.3 Rb₄Cu(MoO₄)₃

Rb₄Cu(MoO₄)₃ undergoes two temperature dependent phase transitions.¹² Above room temperature the structure adopts a hexagonal structure, at room temperature the crystal adopts an orthorhombic structure, and around 103 K the crystal is reported to adopt a monoclinic structure.¹² Based on current experiments at 298 K, the compound adopts an orthorhombic structure (*Pnma* #62) with a lattice of *a* = 10.581(2) Å, *b* = 23.213(4) Å, and *c* = 6.078(1) Å. One sample batch yielded a crystal that adopted the hexagonal structure (6.1 x 23.2 Å), however this result was not found in other batches of Rb₄Cu(MoO₄)₃ crystals. The crystallographic information for both the hexagonal and orthorhombic phases of Rb₄Cu(MoO₄)₃ are located in Table 5.6 and the atomic coordinates and displacement parameters are located in Table 5.7. A similar orthorhombic lattice was also reported for β -Rb₄Zn(MoO₄)₃ which adopts the *Pn*2₁*a* space group, however no other structural information was reported for this compound.¹⁰ The lattice is similar to the orthorhombic compound K₄Zn(MoO₄)₃ which crystallizes in the space group *P*2₁2₁2₁.^{13,14} The space groups *P*2₁2₁2₁ and *Pnma* also has a mirror, glide planes, and an

Sample	dixie51	dixie78
Formula	$Rb_4Cu(MoO_4)_3$	$Rb_4Cu(MoO_4)_3$
Formula units (amu)	885.24	885.24
Crystal System	hexagonal	orthorhombic
Space Group	$P6_3/mmc$	Pnma
<i>a</i> (Å)	6.088(5)	10.581(2)
<i>b</i> (Å)	6.088(5)	23.213(4)
<i>c</i> (Å)	23.157(4)	6.078(1)
$V(\text{\AA}^3)$	743.3(9)	1492.9(5)
Crystal size (mm ³)	0.05/0.125/0.125	0.075/0.15/0.175
Ζ	2	4
Temperature (K)	298	298
Density (g cm ⁻¹)	3.383	3.939
θ Range (°)	3.86-29.95	3.46-30.02
$\mu (\text{mm}^{-1})$	16.873	16.872
R _{int}	0.0578	0.0295
Collected Reflections	2499	3948
Unique Reflections	467	1582
h	$-8 \le h \le 8$	$-14 \le h \le 14$
k	$-6 \le k \le 6$	$-32 \le k \le 32$
l	$-29 \le l \le 32$	$-8 \le l \le 8$
$\Delta \rho_{\rm max}$ (e Å ⁻³)	1.095	2.333
$\Delta \rho_{\rm min} ({\rm e}{\rm \AA}^{-3})$	-1.201	-1.226
Extinction coefficient	0.0036(9)	0.00084(11)
^a R(<i>F</i>) for $F_{o}^{2} > 2\sigma(F_{o}^{2})$) 0.0538	0.0508
^b $\mathbf{R}_{w}(F_{o}^{2})$	0.1250	0.1103

Гable 5.6	Crystallographic	c Information	for the Phases	of $Rb_4Cu(MoO_4)_3$

^a $R_1(F) = \sum ||F_0| - |F_c|| / \sum |F_0|$

^b $R_w(F_o^2) = \sum [w(F_o^2 - F_c^2)^2] / \sum [w(F_o^2)^2]^{1/2}$; where, $w = 1/[\sigma^2(F_0^2) + (0.0320P)^2 + 15.9950P]$ and $w = 1/[\sigma^2(F_0^2) + (0.00207P)^2 + 31.5979P]$ for dixie51 and dixie78 respectively.

inversion center. Because of the similarities in both the lattice and space groups, an attempt was made to refine the structural model of $Rb_4Cu(MoO_4)_3$ using the structural information from the $K_4Zn(MoO_4)_3$. An acceptable R-value was obtained, however the thermal parameters for multiple atoms were extremely large. Also, the intensities of the observed structure factors were generally higher than the calculated values indicating either a twinned or incorrect absolute structure. Also, the Zn in $K_4Zn(MoO_4)_3$ adopts a tetrahedral bonding environment, while the Cu

in $Rb_4Cu(MoO_4)_3$ adopts a distorted square planar environment. These differences all contribute to choosing the higher symmetry *Pnma* model over the published $P2_12_12_1$ model.

Atom	Wyckoff site	X	у	Z	$U_{ m eq}({ m \AA}^2)^a$	Occupancy
dixie51	l – 298 K					
Rb1	4f	1/3	2/3	0.16065(9)	0.0481(7)	1
Rb2	4f	2/3	1/3	0.02880(7)	0.0248(5)	1
Cu1	2a	0	0	1⁄4	0.0219(7)	1
Mo1	4e	0	0	0.09259(5)	0.0187(4)	1
Mo2	4f	2/3	1/3	0.22984(17)	0.0605(19)	0.54
01	4e	0	0	0.1695(6)	0.048(4)	1
O2	12k	0.1547(8)	0.3094(15)	0.0672(4)	0.043(2)	1
O3	4f	2/3	1/3	0.1561(11)	0.048(12)	0.54
O4	12 <i>j</i>	0.380(5)	0.313(5)	1⁄4	0.087(13)	0.51
dixie78	8 – 298 K					
Rb1	8d	0.33338(8)	0.47125(3)	0.50086(12)	0.0258(2)	1
Rb2	8d	0.33349(10)	0.66056(3)	0.47298(16)	0.0378(2)	1
Mo1	8d	0.00050(6)	0.59262(2)	0.50809(10)	0.01809(17)	1
Mo2	8d	0.16952(16)	0.73000(6)	0.9616(3)	0.0285(2)	0.48
Cu1	4c	0.00041(14)	1⁄4	0.5088(2)	0.0223(3)	1
01	8d	0.4181(6)	0.5647(3)	0.2159(10)	0.0361(15)	1
O2	4c	0.4590(12)	1⁄4	0.603(3)	0.075(4)	1
O3	8d	0.4280(7)	0.5690(3)	0.7497(11)	0.0410(16)	1
O4	8d	-0.0003(8)	0.6692(3)	0.4940(14)	0.054(2)	1
05	8d	0.1542(6)	0.5672(3)	0.5002(11)	0.0388(15)	1
06	4c	0.8410(11)	1/4	0.325(2)	0.057(3)	1
O7	4c	0.6865(11)	1/4	0.927(2)	0.070(4)	1
08	8 <i>d</i>	0.1736(13)	0.6559(5)	0.983(2)	0.044(4)	0.51

 Table 5.7
 Atomic Coordinates and Anisotropic Displacement Parameters for Rb₄Cu(MoO₄)

 ${}^{a}U_{eq}$ is defined as one-third of the trace of the orthogonalized U_{ij} tensor.

The orthorhombic structure of $Rb_4Cu(MoO_4)_3$ is shown in Figure 5.4 and consists of distorted square planar CuO₄ bonded to two slightly distorted MoO₄ tetrahedral units in the *c*-direction. This square planar CuO₄ environment is also seen in other oxide structures such as La_2CuO_4 .¹⁵ Along the *a*-axis, disordered, slightly distorted MoO₄ tetrahedral units link the CuO₄ subunits. Table 5.8 lists selected interatomic distances and bond angles for $Rb_4Cu(MoO_4)_3$. Cu – O interatomic distances range from 1.876(6) – 2.023(11) Å and the in plane O – Cu – O angles

are $157.6(5)^{\circ}$ and $179.0(5)^{\circ}$ which indicate that the CuO₄ is highly distorted. Mo1 adopts a slightly distorted tetrahedral environment with interatomic distances ranging from 1.731(6) - 1.780(6) Å. Mo2 is also a slightly distorted tetrahedron with interatomic distances ranging from 1.674(13) - 1.805(12) Å. Mo2 is only half occupied which induces disorder throughout the structure. Rb1 is coordinated to ten oxygen atoms with bond distances ranging from 2.905(6) - 3.294(7) Å. Rb2 is coordinated to six oxygen atoms with bond distances ranging from 2.862(6) - 3.205(11) Å. The Rb polyhedra are disbursed throughout the unit cell. Cu superexchange is possible because the layers of Cu atoms are connected by Mo2 and O atoms.



Figure 5.4 (a) Crystal structure of $Rb_4Cu(MoO_4)_3$ as viewed down the *c*-axis where the blue, green, purple, and red spheres refer to Rb, Cu, Mo, and O atoms respectively. (b) Cu distorted square planar bonding environment of $Rb_4Cu(MoO_4)_3$.

Table 5.8Selected Interatomic Distances (Å) and Angles for Orthorhombic Rb₄Cu(MoO₄)₃

$\overline{Cu - O4(x2)}$	1.876(6)	Rb2 – O1	2.862(6)	O4 - Cu - O6(x2)	89.7(3) °
Cu - O7	2.007(12)	Rb2 – O5	2.884(7)	O4 - Cu - O7(x2)	90.1(3) °

					Table 5.8 (cont.)
Cu – O6	2.023(11)	Rb2 – O3	2.889(7)	O6 - Cu - O7	157.6(5) °
		Rb2 – O6	3.038(9)	O4 - Cu - O4	179.0(5) °
Rb1 – O3	2.905(6)	Rb2 - O2	3.057(10)		
Rb1 – O1	2.918(6)	Rb2 - O7	3.205(11)	O5 - Mo1 - O1	108.8(3) °
Rb1 – O5	2.926(6)			O1 - Mo1 - O3	108.8(3) °
Rb1 – O8	2.954(11)	Mo1 - O5	1.731(6)	O5 - Mo1 - O3	109.2(3) °
Rb1 – O1	3.080(7)	Mo1 – O1	1.741(6)	O1 - Mo1 - O4	109.3(3) °
Rb1 – O3	3.093(7)	Mo1 – O3	1.748(6)	O5 - Mo1 - O4	110.1(4) °
Rb1 – O5	3.166(7)	Mo1 - O4	1.780(6)	O3 - Mo1 - O4	110.6(4) °
Rb1 – O5	3.174(7)				
Rb1 – O1	3.252(7)	Mo2 - O2	1.674(13)	O8 - Mo2 - O7	102.5(5) °
Rb1 – O3	3.294(7)	Mo2 - O8	1.726(11)	O2 - Mo2 - O8	104.9(5) °
		Mo2 - O7	1.730(11)	O8 - Mo2 - O6	109.4(5) °
		Mo2 - O6	1.805(12)	O7 - Mo2 - O6	111.2(6) °
				O2 - Mo2 - O6	111.9(6) °
				O2 - Mo2 - O7	116.1(6) °

5.3 References:

- (1) Hill, N. A. Annu. Rev. Mater. Res. 2002, 32, 1-37.
- (2) Ederer, C.; Spaldin, N. A. *Nature Mater.* **2004**, *3*, 849-851.
- (3) Cheong, S. W.; Mostovoy, M. Nature Mater. 2007, 6, 13-20.
- (4) Kimura, T.; Goto, T.; Shintani, H.; Ishizaka, K.; Arima, T.; Tokura, Y. *Nature* **2003**, *426*, 55-58.
- (5) Arima, T. J. Phys. Soc. Jpn. 2007, 76.
- (6) Kimura, T.; Sekio, Y.; Nakamura, H.; Siegrist, T.; Ramirez, A. P. *Nature* **2008**, *7*, 291-294.
- Altomare, A.; Burla, M. C.; Camalli, M.; Cascarno, G. L.; Giacovazzo, A.; Guagliardi, A.; Moliterni, A. G. G.; Polidori, G.; Spagna, R. J. J. Appl. Crystallogr. 1999, 32, 115-119.
- (8) Sheldrick, G. M.; University of Gottingen: Germany, 1997.
- (9) Solodovnikov, S. F.; Klevtsova, R. F.; Glinskaya, L. A.; Klevtsov, P. V. Sov. Phys. Crystallogr. 1988, 33, 820-824.
- (10) Trunov, K.; Efremov, V. A.; Velikodnyi, Y. A. Crystal Chemistry and Properties of Double Molybdates and Tungstates [In Russian]; Nauka: Leningrad, 1986.
- (11) Shannon, R. D. Acta. Cryst. 1976, 32A, 751-767.

- (12) Klevtsov, P. V.; Kim, V. G.; Kruglik, A. I.; Klevtsova, R. F. Sov. Phys. Crystallogr. **1989**, *34*, 384-386.
- (13) Gicquel-Mayer, C.; Mayer, M. M.; Perez, G. Chimie Minerale 1976, 283, 533-535.
- (14) Gicquel-Mayer, C.; Mayer, M.; Perez, G. Rev. Chem. Min. 1980, 17, 445-457.
- (15) Chaillout, C.; Cheong, S. W.; Fisk, Z.; Lehmann, M. S.; Marezio, M.; Morosin, B.; Schirber, J. E. *Physica Scripta*. **1989**, *T29*, 97-99.

CHAPTER 6 – CONCLUSION

One of the primary goals of this dissertation was to gain a better understanding of structural effects on the physical properties of highly correlated compounds. Identifying structural features in extended solids that favor a desired behavior will help with the design of future materials. More correlations of structure and properties are needed to understand the complex physical properties and to predict the properties of new materials. By growing high-quality single crystals of compounds, detailed structural analyses and physical property measurements can be done. For example, it is well known that layered compounds typically display magnetic anisotropy. It would be beneficial to be able to identify a certain structural features that could lead to desired or unconventional behavior. The key is simply knowing where to look.

The dominant theme of this dissertation revolves around layered antimonide compounds which typically possess unique structural features, unusual bonding, and interesting physical properties. Antimony resides along the metal – insulating border making this phase space attractive to investigate. A systematic study of the orthorhombic CeNiSb₃ structure type was conducted in an attempt to correlate structure and properties. By using Sn to grow larger single crystals of CeNiSb₃, a new pseudo-ternary compound, $LnNi(Sn,Sb)_3$, was discovered. The substitution of the magnetic rare earth element allows for the study of structural changes as well as physical property effects. Another study was done by the substitution of the transition metal Ni with Co or Cu of LnNiSb₂ i.e. what happens to the structure and physics when changing carrier density. It was discovered that Cu's coordination preferentially occupies the tetrahedral environment seen in the tetragonal CeCuSb₂ structure.

Another important part of this work is the structural study of the double molybdates $Rb_4M(MoO_4)_3$ (M = Mn, Zn, Cu) compounds. These materials were chosen for investigation

because they have frustrated triangular lattices which may lead to polarization. Also the Cu analogue is expected to be a $S = \frac{1}{2}$ system which exhibits both frustration and quantum fluctuation. Research of multiferroic materials is extremely attractive because of the promise of new practical applications. Crystal symmetry plays an integral role in predicting and understanding multiferroic behavior in materials. Rb₄ $M(MoO_4)_3$ (M = Mn, Zn, Cu) compounds have promising magnetic and electrical behaviors. The Zn and Cu analogues adopt different, orthorhombic structures which are both new structure types. The detailed structural study provided here will be vital in understanding and formulating a mechanism for any multiferroic behavior.

The appendices which follow this chapter provide information on collaborative projects. Structural details of compounds such as $LnPdSb_3$, EuCu₉Sn₄, VB₂, and Y_{2-x}Ce_xTi₂O₇ are discussed within. These projects also follow the structure-property correlation theme that is seen throughout this dissertation.

APPENDIX 1 – STRUCTURE DETERMINATION OF *Ln***PdSb**₃ (*Ln* = La, Ce)

A1.1 Introduction

There are seven ternary compounds in the Ce–Pd–Sb system that have been reported thus far: CePdSb,² CePd₂Sb₂,³ CePdSb₃,⁴ CePdSb₂,⁵ Ce₃Pd₆Sb₅,⁶ Ce₈Pd₂₄Sb,⁷ and Ce₂Pd₉Sb₃.⁸ Some of these phases show heavy fermion behavior. Heavy fermions possess conduction electrons that have larger effective masses one-hundred times the mass of a free-electron.⁹ This leads to a Sommerfeld coefficient (γ) greater than 100 mJ mol⁻¹ K⁻². The Sommerfeld coefficient is obtained through a fit from heat capacity measurements after subtracting from the phonon contribution. Ce₈Pd₂₄Sb, has a γ of ~400 mJ mol⁻¹ K⁻², ¹⁰ while CePdSb₂ possesses a relatively large enhanced mass with γ of ~100 mJ mol⁻¹ K⁻².¹¹ CePdSb₃, of the CaBe₂Ge₂ structure type,¹² shows no evidence of magnetic ordering and has a γ of ~250 mJ mol⁻¹ K⁻².⁴

LaPdSb₃ and CePdSb₃ grown using flux growth rather than arc melting, crystallize in a different structure type than the previously reported tetragonal CePdSb₃ phase.⁴ More recently, magnetic, transport and heat capacity data CePdSb₃ was reported and shown to exhibit Kondo lattice behavior and ordered antiferromagnetically below 3.1 K.¹³ However, Thamizhavel *et al* described the structure as having different Wyckoff positions from CeNiSb₃.¹ This is not the case, as the orthorhombic CePdSb₃ is in fact an entirely new structure type and is not the same structure type as CeNiSb₃. *Ln*Ni(Sn,Sb)₃ discussed in Chapter 2 adopts this structure type. The crystal growth and structural determination of *Ln*PdSb₃ (*Ln* = La or Ce) are discussed herein.

A1.2 Experimental

A1.2.1 Synthesis Optimization

Single crystals of LaPdSb₃ and CePdSb₃ were grown using excess Sb flux growth

¹ Portions of this chapter reprinted by permission of The International Union of Crystallography: Thomas, E.L.; Gautreaux, D.P.; Chan, J.Y.; "The Layered Intermetallic Compound LaPdSb₃", *Acta Cryst.* **2006**, *E62*, 196-198.

method. La or Ce ingots (99.9% purity, Alfa Aesar), Pd powder (99.999% purity, Alfa Aesar), and Sb shot (99.9999% purity, Alfa Aesar) were placed into alumina crucibles in a 1:1:10 (*Ln*:Pd:Sb) molar ratio. Each crucible was then sealed into a fused silica tube under vacuum. The samples were heated to 1150 °C where the temperature was held constant for 10 h then cooled at 5°C h⁻¹ to 670 °C. After dwelling at 670 °C for approximately 24 h, the excess liquid Sb flux was removed by centrifugation. Silvery plate-shaped crystals with dimensions up to 1 x 2 x 2 mm³ were extracted. Both the La and Ce analogues of each compound show little or no surface degradation when exposed to air and moisture for extended periods. The crystal growth method listed above was the optimal synthetic conditions. Table A1.1 lists the attempted crystal growth conditions for CePdSb₃ before the best experimental conditions were discovered.

Sample	Elements	Ratio	Temperature Profile	Results
DPG011	Ce:Pd:Sb	1:2:20	1150 °C for 8 hrs	CeSb ₂
			5 °C/hr to 670 °C	
DPG013	Ce:Pd:Sb	1:1:20	1150 °C for 8 hrs	CeSb ₂
			5 °C/hr to 670 °C	
DPG019	Ce:Pd:Sb	1:1.5:20	1150 °C for 8 hrs	CeSb ₂
			5 °C/hr to 670 °C	
DPG020	Ce:Pd:Sb	1:1:20	1150 °C for 10 hrs	CeSb ₂
			5 °C/hr to 670 °C	
DPG021	Ce:Pd:Sb	1:1:10	1150 °C for 10 hrs	CePdSb ₃
			5 °C/hr to 670 °C	

Table A1.1Attempted Crystal Growths for CePdSb3

A1.2.2 Single crystal and Powder X-ray diffraction

The samples were identified by both powder and single crystal X-ray diffraction. The powder pattern of the product revealed the presence of a small amount of $CeSb_2$. This phase can be identified by visual inspection and removed manually from the *Ln*PdSb₃ crystals. Single

crystal X-ray diffraction data were collected by mounting a block-shaped, silver fragment of each of the La and Ce analogues onto a glass fiber of a goniometer. Data collection parameters and crystallographic data are located in Table A1.2. Atomic positions and displacement parameters are located in Table A1.3.

Formula	LaPdSb ₃	CePdSb ₃
Space Group	Pbcm	Pbcm
<i>a</i> (Å)	12.9210(4)	12.7850(3)
<i>b</i> (Å)	6.3450(9)	6.3210(7)
<i>c</i> (Å)	12.5030(9)	12.4500(6)
$V(\text{\AA}^3)$	1025.04(17)	1006.13(12)
Crystal dimensions (mm ³)	0.080 x 0.100 x 0.100	0.030 x 0.080 x 0.080
Ζ	8	8
Temperature (K)	298	298
Crystal Density (g/cm ³)	7.913	10.097
θ range (°)	3.15 - 30.0	3.19 - 30.03
μ (mm ⁻¹)	27.091	35.105
Collected reflections	2790	2738
Unique reflections	1557	1523
R _{int}	0.0625	0.0692
h	$-18 \le h \le 18$	$-17 \le h \le 17$
k	$-8 \le k \le 8$	$-8 \le k \le 8$
l	$-17 \le l \le 17$	$-17 \le l \le 17$
$\Delta \rho_{\rm max} ({\rm e}{\rm \AA}^{-3})$	3.425	7.597
$\Delta \rho_{\min} (e \text{ Å}^{-3})$	-3.279	-4.626
Extinction coefficient	0.00011(4)	0.00061(11)
^a $R[F^2 > 2\sigma(F^2)]$	0.0443	0.0593
$b w R_2(F^2)$	0.0885	0.1534

Table A1.2Crystallographic Data for LaPdSb3 and CePdSb3

 ${}^{a}R_{1} = \sum ||F_{o}| - |F_{c}|| / \sum |F_{o}|$ ${}^{b}wR_{2} = \left[\sum [w(F_{o}^{2} - F_{c}^{2})] / \sum [w(F_{o}^{2})^{2}]\right]^{1/2} \text{ where } w = 1/[\sigma^{2}F_{0}^{2} + (0.0401P)^{2} + 11.4063P] \text{ for LaPdSb}_{3} \text{ and } w = 1/[\sigma^{2}F_{0}^{2} + (0.0187P)^{2}] \text{ for CePdSb}_{3}.$

Atom	Wyckoff site	x	У	Z	$U_{ m eq}({ m \AA}^2)^a$
La1	4 <i>c</i>	0.69911(8)	1⁄4	0	0.0135(2)
La2	4d	0.30822(8)	0.27462(17)	3⁄4	0.0142(3)
Pd1	8 <i>e</i>	0.10190(7)	0.04697(17)	0.86579(8)	0.0180(3)
Sb1	4c	0.97482(9)	1⁄4	0	0.0168(3)
Sb2	4d	0.77702(9)	0.2635(2)	3⁄4	0.0155(3)
Sb3	8 <i>e</i>	0.50306(6)	0.51263(14)	0.87808(6)	0.0156(2)
Sb4	4c	0.23291(9)	1⁄4	0	0.0150(3)
Sb5	4d	0.93812(9)	0.9219(2)	3⁄4	0.0165(3)
Ce1	4 <i>c</i>	0.69815(9)	1/4	0	0.0099(3)
Ce2	4d	0.30869(9)	0.27673(19)	3⁄4	0.0099(3)
Pd1	8 <i>e</i>	0.10344(8)	0.0475(2)	0.86583(9)	0.0136(3)
Sb1	4c	0.97381(11)	1⁄4	0	0.0128(4)
Sb2	4d	0.77250(11)	0.2645(2)	3⁄4	0.0119(4)
Sb3	8 <i>e</i>	0.50336(7)	0.51373(16)	0.87743(7)	0.0120(3)
Sb4	4c	0.23642(12)	1⁄4	0	0.0111(3)
Sb5	4d	0.93723(10)	0.9225(2)	3⁄4	0.0125(4)

Table A1.3Atomic Positions and Displacement Parameters for $LnPdSb_3$ (Ln = La or Ce)

 $^{a}U_{eq}$ is defined as one-third of the trace of the orthogonalized U_{ij} tensor.

A1.3 Results and Discussion

A1.3.1 Structure

CePdSb₃ adopts two polymorphic forms, the tetragonal CaBe₂Ge₂-type¹² and the orthorhombic CePdSb₃-type.^{1,13} The two polymorphs were synthesized by different methods: arc-melting⁴ and flux growth.^{1,13} The arc-melted CaBe₂Ge₂-type was only characterized by powder X-ray diffraction,⁴ while the CePdSb₃ type was characterized by both powder and single crystal X-ray diffraction. From here on, CePdSb₃ will refer to the new orthorhombic compound synthesized in our lab unless otherwise noted. The structure of CePdSb₃ is shown in Figure A1.1. This compound consists of layers of nearly square nets of Sb atoms and layers of slightly distorted face- and edge-sharing PdSb₆ octahedra. Between the Sb nets and Pd octahedra are

crystallographically inequivalent Ce atoms which adopt a square anti-prismatic and a monocapped square anti-prismatic geometry.



Figure A1.1 Crystal structure of $LnPdSb_3$ where the yellow spheres refer to the La or Ce atoms, the maroon spheres refer to the Sb atoms and the purple polyhedral refer to the distorted Pd octahedra.

The *Ln* atoms occupy two inequivalent crystallographic sites and are located above and below the Sb square nets. *Ln*1 atoms adopt an 8-coordinate square anti-prismatic geometry comprised of 4 Sb3 atoms as the base, and 2 Sb2 and 2 Sb4 atoms from the PdSb₆ octahedra forming a second square as shown in Figure 3.2 for the La analogue. The *Ln*2 atoms in CePdSb₃ adopt a similar geometry as the *Ln*1 however there is an Sb5 capping the top of the square anti-prism. There is a capping atom present near the *Ln*1, however it is located at 3.5629(15) Å and 3.5244(17) Å away for the La and Ce analogues respectively. This is considered too far away for strong bonding/interactions to be considered between *Ln*1 and Sb1.

The nearly square Sb nets are along the *bc*-plane and are composed of Sb3 atoms. The Sb3—Sb3 distances for LaPdSb₃ range from 3.0539(16) Å and 3.2028(16) Å. For CePdSb₃, the Sb3—Sb3 distances range from 3.0582(18) Å and 3.1730(18) Å. There is a slight distortion to

the nets, but they are not as distorted as CeNiSb₃.¹⁴ The distorted angles in the Sb nets are $86.96(3)^{\circ}$ and $92.95(3)^{\circ}$ for LaPdSb₃, and $86.71(4)^{\circ}$ and $93.21(4)^{\circ}$ for CePdSb₃. In the similar structure CeCrSb₃, the Sb net angles are perfect 90.00° .¹⁵

The Pd environment of $LnPdSb_3$ is a distorted octahedral environment. The Pd—Sb distances range from 2.6781(13) – 2.8725(15) Å for LaPdSb₃ and 2.6786(14) – 2.8228(18) Å for CePdSb₃. They are comparable to those found in the binary compound PdSb (NiAs-type) of 2.737 Å, in which Pd adopts an octahedral coordination.¹⁶ The Pd-centered octahedra in LaPdSb₃ and CePdSb₃ are highly distorted with Sb—Pd—Sb angles as acute as 73.87(3)° and 73.79(3)°. The PdSb₆ octahedra are edge sharing in the *b*-direction and are face-sharing in the *c*-direction. The Pd—Pd distances are 2.895(2) Å in LaPdSb₃ and 2.884(2) Å in CePdSb₃ which are comparable to the Pd-Pd distance of 2.751 Å in Pd metal.¹⁷

A1.4 References

- (1) Thomas, E. L.; Gautreaux, D. P.; Chan, J. Y. Acta Crystallogr. Sect. E: Struct. Rep. Online 2006, E62, i96-i98.
- (2) Marazza, R.; Rossi, D.; Ferro, R. J. Less-Common Metals 1980, 75, P25-P28.
- (3) Hofmann, W. K.; Jeitschko, W. Monatsh. Chem. 1985, 116, 569-580.
- (4) Cava, R. J.; Ramirez, A. P.; Takagi, H.; Krajewski, J. J.; Peck, W. F. J. Magn. Magn. Mater. **1993**, 128, 124-128.
- (5) Sologub, O.; Hiebl, K.; Rogl, P.; Noël, H.; Bodak, O. J. Alloys Compd. **1994**, 210, 153-157.
- (6) Gordon, R. A.; DiSalvo, F. J.; Poettgen, R. J. Alloys Compd. 1995, 228, 16-22.
- (7) Gordon, R. A.; DiSalvo, F. J. Z. Naturforsch. 1996, 51, 52-56.
- (8) Gordon, R. A.; DiSalvo, F. J.; Poettgen, R.; Brese, N. E. J. Chem. Soc., Faraday Trans. 1996, 92, 2167-2171.
- (9) Fisk, Z.; Hess, D. W.; Pethick, C. J.; Pines, D.; Smith, J. L.; Thompson, J. D.; Willis, J. O. Science 1988, 239, 33-42.

- (10) Cho, B. K.; Gordon, R. A.; Jones, C. D. W.; DiSalvo, F. J.; Kim, J. S.; Stewart, G. R. *Phys. Rev. B* **1998**, *57*, 15191-15196.
- (11) Muro, Y.; Takeda, N.; Ishikawa, M. J. Alloys Compd. 1997, 257, 23-29.
- (12) Eisenmann, B.; Schaefer, H.; May, N.; Müller, W. Z. Naturforsch. B: Chem. Sci. 1972, 27, 1155-1157.
- (13) Thamizhavel, A.; Nakashima, H.; Shiromoto, T.; Obiraki, Y.; Matsuda, T. D.; Haga, Y.; Ramakrishnan, S.; Takeuchi, T.; Settai, R.; Onuki, Y. J. Phys. Soc. Jpn. 2005, 74, 2617-2621.
- (14) Macaluso, R. T.; Wells, D. M.; Sykora, R. E.; Albrecht-Schmitt, T. E.; Mar, A.; Nakatsuji, S.; Lee, H.; Fisk, Z.; Chan, J. Y. J. Solid State Chem. 2004, 177, 293-298.
- (15) Brylak, M.; Jeitschko, W. Z. Naturforsch. B: Chem. Sci. 1995, 50, 899-904.
- (16) Pratt, J. N.; Myles, K. M.; Darby, J. B. J.; Mueller, M. H. J. Less-Common Metals 1968, 14, 427-433.
- (17) Donohue, P. C. J. Solid State Chem. 1975, 12, 80-3.

APPENDIX 2 – EuCu₉Sn₄

A2.1 Introduction

Many compounds of the NaZn₁₃ structure type have received attention because of the remarkable properties they exhibit. UBe₁₃, a heavy fermion superconductor, has an enormous specific heat coefficient of $\gamma = 1100$ mJ mol⁻¹ K^{-2,1} LaCo₁₃ possesses the large ordering temperature $T_{\rm N} = 1290$ °C.² In 1994, a tetragonal derivative of the NaZn₁₃ structure was discovered in LaFe₉Si₄.³ Many analogues adopting this tetragonal structure have been studied. Magnetic properties of *Ln*Cu₉Sn₄ compounds (*Ln* = La – Nd) all order ferromagnetically from 5 – 15 while no magnetic ordering is observed down to 1.5 K in *Ln*Cu_{9.4}Sn_{3.6}, which adopts the cubic NaZn₁₃ structure type.⁴ The atomic ordering of the tetragonal structure leads to magnetic ordering, while the disorder in the cubic *Ln*Cu_{9.4}Sn_{3.6} hinders any magnetic order down to 2 K.⁴ Recently, the structure and magnetic properties of EuCu₉Sn₄, EuCu₄Sn₂, and EuCuSn₂ were reported.⁵ In our effort to continue the exploration of the *Ln* – Cu – Sn phase space, high quality single crystals of EuCu₉Sn₄ are discussed herein.

A2.2 Experimental

A2.2.1 Synthesis

Single crystals of EuCu₉Sn₄ were synthesized using a Sn flux growth method. Eu pieces (99.9%, Alfa Aesar), Cu powder (99.999%, Alfa Aesar), and Sn shot (99.99%, Alfa Aesar) were placed into an alumina crucible in a 1:1:20 stoichiometric ratio. After sealing the crucible into an evaculated fused-silica tube, the entire reaction vessel was placed into a furnace for heat treatment. The sample was heated at 1150 °C for 48 h followed by a slow-cooling at 5 °C/h down to 300 °C. After the sample temperature reached 300 °C, the excess flux was removed by

centrifugation. The sample contained thin metallic plates, which were determined to be $EuCu_9Sn_4$. There is no surface degradation to the crystal visible over a period of months. Some of the crystals contained small amounts of Sn present on the surface which were removed mechanically.

A2.2.2 Single Crystal X-Ray Diffraction

Single crystal X-ray diffraction was performed on a crystal with dimensions of 0.025 x 0.1 x 0.125 mm³. The crystal was mounted onto the glass fiber of the goniometer with epoxy and data were collected on a Nonius Kappa CCD X-ray diffractometer (MoK_{α} = 0.71073 Å). The unit cell parameters were determined from images taken at a rotation of 15 ° φ . The structural model was solved by direct methods using SIR92 ⁶ and refined using SHELXL97.⁷ The data were corrected for absorption and the displacement parameters were refined as anisotropic. Crystallographic data and data collection parameters are listed in Table A2.1 and atomic positions and anisotropic displacement parameters are listed in Table A2.2.

Formula	$EuCu_9Sn_4$
Formula Units (amu)	1198.58
Space Group	I4/mcm
<i>a</i> (Å)	8.641(2)
<i>c</i> (Å)	12.433(3)
$V(\text{\AA})$	928.3(4)
Crystal Size (mm ³)	0.03/0.10/0.13
Ζ	4
Temperature (°C)	20(2)
Density (g cm ⁻¹)	8.576
θ Range (°)	3.28-30.03
μ (mm ⁻¹)	37.254
R _{int}	0.0455
Collected Reflections	1058
Unique Reflections	390
h	$-12 \le h \le 12$
k	$-8 \le k \le 8$
l	$-17 \le l \le 13$

Table A2.1Crystallographic Data for EuCu₉Sn₄

$\Delta \rho_{\rm max}$ (e Å ⁻³)	2.569
$\Delta \rho_{\min} (e \text{ Å}^{-3})$	-2.425
Extinction coefficient	0.0038(5)
^a $R[F^2 > 2\sigma(F^2)]$	0.0441
^b $wR_2(F^2)$	0.1282

a	$R_{1}(F) = \sum \left\ F_{0} \right\ - \left F_{c} \right\ / \sum \left F_{0} \right $
b	$R_{w}(F_{0}^{2}) = \sum [w(F_{0}^{2} - F_{c}^{2})] / \sum [w(F_{0}^{2})^{2}]^{1/2}; \text{ where } w = 1/[\sigma^{2}(F_{0}^{2}) + (0.0850P)^{2} + 12.4528P]$

 Table A2.2
 Atomic Positions and Displacement Parameters for EuCu₉Sn₄

		-			
Atom	Wyckoff Site	x	у	Z.	$U_{\rm eq}({\rm \AA}^2)^{\rm a}$
Eu1	4 <i>a</i>	0	0	1⁄4	0.01318
Cu1	16 <i>l</i>	0.108912	0.608912	0.174330	0.01376
Cu2	16 <i>k</i>	0.798244	0.944009	0	0.01561
Cu3	4d	0	1/2	0	0.01186
Sn1	16 <i>l</i>	0.315068	0.815065	0.125358	0.01106

^a U_{eq} is defined as one-third of the trace of the orthogonalized U_{ij} tensor.

A2.2.3 Physical Property Measurements

Magnetic measurements on single crystals of EuCu₉Sn₄ were performed using a Quantum Desing MPMS Superconducting Quantum Interference Device (SQUID) magnetometer. Temperature-dependent susceptibility data were measured at an applied field of 0.1 T from 2 K – 300 K and the field-dependent magnetization data were measured at 2 K up to 7 T. Transport property measurements were conducted using a Quantum Design Physical Property Measurement System (PPMS) at ambient pressure. Resistivity data were measured at 0 T, 0.5 T and 9 T while magnetoresistance data up to 9 T were measured at 2 K.

A2.3 Results and Discussion

A2.3.1 Structure

EuCu₉Sn₄ crystallizes in the tetragonal space group I4/mcm (# 140) with lattice parameters of a = 8.641(2) Å and c = 12.433(3) Å. This is in agreement with the EuCu₉Sn₄

lattice parameters a = 8.633(2) Å and c = 12.425(2) Å reported by Mazzone *et al.*⁵ The current work was all ready in progress before the Mazzone paper was published in early 2008. EuCu₉Sn₄ adopts the LaFe₉Si₄ structure type which is a distorted variation of the cubic NaZn₁₃ structure type.^{3,8} There are five atomic positions in the EuCu₉Sn₄ structure: Eu1, Cu1, Cu2, Cu3, and Sn1 which are listed in Table A2.2 with the displacement parameters. The structure shown in Figure A2.1 consists of alternating layers of Cu3 icosahedra and slightly irregular Eu snub-cubes. Figure A2.1 (b) highlights the Cu3 and Eu environments. Table A2.3 displays selected interatomic distances within the Cu3 and Eu subunits. Though similar, the distances vary slightly confirming that both the Cu3 iscoahedra and Eu snub-cubes are somewhat distorted. The Eu analogue does not follow the lanthanide contraction seen in other *Ln*Cu₉Sn₄ compounds. (*Ln* = La – Nd) suggesting that Eu may have an oxidation state of +2 in this compound.⁴



Figure A2.1 (a) Crystal structure of $EuCu_9Sn_4$ viewed down the *b* axis. (b) Images of environments of Cu3 icosahedra and Eu distorted snub-cubes.

I dole I late De	feeted interatorine Di		4 54641116	
Eu Irregular Snut	o Cube	Cu3-Icosahedra		
Eu1-Sn1(x8)	3.5167(8)	Cu3-Sn1(x4)	2.7453(9)	
Eu1-Cu1(x8)	3.6320(10)	Cu3-Cu1(x4)	2.5434(15)	
Eu1-Cu2(x8)	3.5965(10)	Cu3-Cu2(x4)	2.6222(15)	

 Table A2.3
 Selected Interatomic Distances (Å) of EuCu₉Sn₄ Subunits

A2.3.2 Physical Properties

The magnetic susceptibility of $EuCu_9Sn_4$ was measured from 2 – 300 K with an applied field of 0.1 T for several single crystals aligned side-by-side. Figure A2.2 displays the



Figure A2.2 Magnetic Susceptibility of $EuCu_9Sn_4$ measured with an applied field of 0.1 T from 2 – 300 K. Data from 2 – 50 K were shown to enhance the ordering seen below 20 K. The inset displays the inverse susceptibity.

susceptibility data from 2 – 50 K and the inset shows the inverse susceptibility plot. EuCu₉Sn₄ orders ferromagnetically at ~ 10 K. This is in agreement with the published magnetic data where this compound also shows ferromagnetic ordering at 10 K.⁵ The experimental effective magnetic moment was determined from a Curie-Weiss fit of the inverse data from 50 – 300 K. The experimental moment of 6.48 $\mu_{\rm B}$ is close to the calculated moment for Eu²⁺ of 7.93. This is

further evidence that this compound is divalent and is in agreement structure. The Weiss temperature (θ) is 6.5 K is of ferromagnetic fluctuations. Mazzone *et al* reported a $\mu_{eff} = 7.96 \,\mu_{B}$ and a Weiss temperature of $\theta = 7$ K which is consistent with this work.⁵

The magnetization as a function of field measured at 2 K for EuCu₉Sn₄ is shown in Figure A2.3. The magnetization increases sharply up to 1 T then begins to saturate. The experimental saturation moment is ~ 4.4 $\mu_{\rm B}$ which is well below the calculated saturation moment for Eu²⁺ is 7 $\mu_{\rm B}$. This behavior is typical for rare earth compounds and can be explained by partial screening of the moments by the conduction electrons. The shape of the magnetization follows the behavior of a classical ferromagnet.



Figure A2.3 Magnetization of EuCu₉Sn₄ as a function of field measured at 2 K.

Resistivity measurements as a function of temperature were performed at 0 T, 0.05 T and 9 T and are shown in Figure A2.4. The resistivity at all fields shows simple metallic behavior. There is a slight downturn in the resistivity at 0 T at \sim 3.3 K which coincides with the superconducting transition of Sn. Data were collected in the presence of field to destroy the

critical field of Sn and at 0.05 T, the slight downturn is eliminated from the resistivity data indicating the presence of a small amount of topical Sn. The increase in resistivity seen at 9 T is an indication of a change in resistance with the application of a magnetic field so



Figure A2.4 Resistivity measurements of $EuCu_9Sn_4$ as a function of temperature measured at 0 T, 0.05 T, and 9 T.



Figure A2.5 Change in resistivity of $EuCu_9Sn_4$ from 0 T to 9 T measured with field oriented in two directions: parallel to the *ab* plane and parallel to the *c* axis.

magnetoresistance was measured. Figure A2.5 shows the change in resistivity from 0 T to 9 T as a function of temperature. When the magnetic field is applied parallel to the c axis of the crystal, the magnetoresistance is ~ 40 % at 2 K. When the magnetic field is applied parallel to the ab-plane of the crystal, the change in resistivity is not as large. This is further evidence of the highly anisotropic nature of these crystals.

A2.4 References

- (1) Ott, H. R.; Rudigier, H.; Fisk, Z.; Smith, J. L. Phys. Rev. Lett. 1983, 50, 1595-1598.
- (2) Velge, W. A. J. J.; Buschow, K. H. J. J. Appl. Phys. **1968**, 39, 1717-1720.
- (3) Tang, W.; Liang, J.; Chen, X.; Rao, G. J. Appl. Phys. **1994**, 76, 4095-4098.
- (4) Singh, S.; Fornasini, M. L.; Manfrinetti, P.; Palenzona, A.; Dhar, S. K.; Paulose, P. L. J. *Alloys Compd.* **2001**, *317-318*, 560-566.
- (5) Mazzone, D.; Paulose, P. L.; Dhar, S. K.; Fornasini, M. L.; Manfrinetti, P. J. Alloys Compd. **2008**, 2008.
- (6) Altomare, A.; Cascarno, G. L.; Giacovazzo, A.; Guagliardi, A. J. Appl. Crystallogr. **1993**, 26, 343-350.
- (7) Sheldrick, G. M.; University of Gottingen: Germany, 1997.
- (8) Shoemaker, D. P.; Marsh, R. E.; Ewing, F. J.; Pauling, L. Acta Cryst. 1952, 5, 637-644.

APPENDIX 3 – STRUCTURAL DETERMINATION OF VB2

A3.2 Introduction

Transition metal diborides have been extensively studied for many years. However the recent discovery of superconducting behavior of MgB₂ at 39 K has refueled the interest in these simple diborides.² Transition metal diborides exist for all first row transition metals between Sc – Fe. The wide range of isostructural compounds make this structure type intriguing because of the chance to study the property changes throughout all the isostructural compounds. Recently, our collaborators discovered that VB₂ has a very large magnetoresistance of ~ 1100 % at low temperatures.¹ This extremely large magnetoresistive behavior is highly dependent on the quality of the single crystals measured.¹ To gain better insight into the properties of this structure, very accurate lattice parameters were needed for energy band calculations and to determine the Fermi surface of VB₂. Therefore the single crystals and the results are reported herein.

A3.2 Experimental and Results

High quality single crystals of VB₂ were synthesized by Al flux by collaborators in the Department of Physics and Astronomy at Louisiana State University.¹ The crystals grew as both rods and plates and powder X-ray diffraction was used to confirm that the sample was single phase. Powder X-ray diffraction data were collected on a Bruker D8 Advance Diffractometer with monochromatic Cu K_{α} radiation ($\lambda = 1.540562$ Å) at room temperature and it was determined that both crystal morphologies are VB₂. Accurate lattice parameters were needed for energy band calculations, therefore the single crystal X-ray diffraction data were collected at 293

¹ Portions of this chapter reprinted by permission of The Institute of Physics: Karki, A.B.; Gautreaux, D.P.; Chan, J.Y.; Harrison, N.; Browne, D.A.; Goodrich, R.G.; Young, D.P.; "Magnetotransport Properties and the Fermi Surface of Single Crystal VB₂", *J.Phys: Condens. Matter.* **2008**, *20*, 035209.

K and 90 K. A 0.05 x 0.075 x 0.125 mm³ crystal fragment was glued to a glass fiber with epoxy and mounted on the goniometer of a Nonius Kappa CCD diffractometer equipped with Mo K α radiation ($\lambda = 0.71073$ Å). For low temperature data collections, the crystal was mounted onto the fiber using vacuum grease and no epoxy was used. The temperature was regulated with a cooled nitrogen gas stream produced by an Oxford Cryostream Cooler. Initial unit cell parameters were determined from images taken at a rotation of 15 $^{\circ}\varphi$. The structural model was solved by direct methods using SIR97³ and refined using SHELXL97.⁴ The data were corrected for absorption and the displacement parameters were refined as anisotropic. Selected crystallographic data and data collection parameters are listed in Table A3.1. Atomic positions and anisotropic displacement parameters are listed in Table A3.2 for both data collections. VB₂ adopts the well known AlB₂ structure type and is displayed in Figure A3.1. The structure consists of alternating layers of vanadium atoms and graphite like sheets of boron. There are no structural discrepancies between our VB₂ structure and the known AlB₂ structure type. The structural information obtained from this study was used for energy band calculations and the results are reported in the Journal of Physics: Condensed Matter.

Sample	AK104		AK104
Space Group	P6/mmm		P6/mmm
Temperature (K)	293		90
a (Å)	3.0000(4)		2.9980(10)
<i>b</i> (Å)	3.0000(4)		2.9980(10)
<i>c</i> (Å)	3.0620(8)		3.044(2)
$V(\text{\AA}^3)$	23.866(8)		23.69(2)
Ζ	1		1
Density $(g \text{ cm}^{-1})5.049$		5.085	
θ Range (°)	7.86-29.55		6.70-29.57
$\mu (\text{mm}^{-1})$	9.274		9.341
$\Delta \rho_{\rm max}$ (e Å ⁻³)	0.697		0.690
$\Delta \rho_{\min} (e \text{ Å}^{-3})$	-0.428		-0.521

Table A3.1Crystallographic Data for VB2

^a $R[F^2 > 2\sigma(F^2)]$	0.0188	0.0252	
^b $wR_2(F^2)$	0.0400	0.0563	
$\overline{{}^{\mathrm{a}} R_{\mathrm{I}}(F)} = \sum \left\ F_{\mathrm{o}} \right\ - \left F_{\mathrm{c}} \right\ $	$/\sum F_0 $		
^b $R_w(F_0^2) = \sum [w(F_0^2 -$	$[F_c^2)]/\sum [w(F_0^2)^2]$	$^{1/2}$; where $w = 1/[\sigma^2(F_0^2) + (0.016)]$	$(7P)^{2}]$
$w = 1/[\sigma^2(F_0^2) + (0.10)]$	$(00P)^2$], for 293	K and 90 K respectively	

 Table A3.2
 Atomic Positions and Displacement Parameters for VB₂

	Atom	Wyckoff Site	x	у	z	$U_{ m eq}({ m \AA}^2)^{ m a}$
293 K						
	V1	1 <i>a</i>	0	0	1⁄4	0.0033(16)
	B1	2d	1/3	2/3	1⁄2	0.000(2)
90 K						
	V1	1 <i>a</i>	0	0	1⁄4	0.0033(16)
	B1	2d	1/3	2/3	1⁄2	0.0036(19)

^a U_{eq} is defined as one-third of the trace of the orthogonalized U_{ij} tensor.



Figure A3.1 (a) Layered crystal structure of VB_2 viewed in the [110] direction. (b) View down the *c*-axis of the crystal structure of VB_2 .

A3.2 References

- (1) Karki, A. B.; Gautreaux, D. P.; Chan, J. Y.; Harrison, N.; Browne, D.; Goodrich, R. G.; Young, D. P. J. Phys.: Condens. Matter 2008, 20, 035209.
- (2) Nagamatsu, J.; Nakagawa, N.; Muranaka, T.; Zenitani, Y.; Akimitsu, J. *Nature* **2001**, *410*, 63-64.

- (3) Altomare, A.; Burla, M. C.; Camalli, M.; Cascarno, G. L.; Giacovazzo, A.; Guagliardi, A.; Moliterni, A. G. G.; Polidori, G.; Spagna, R. J. *J. Appl. Crystallogr.* **1999**, *32*, 115-119.
- (4) Sheldrick, G. M.; University of Gottingen: Germany, 1997.

APPENDIX 4 – Y_{2-x}Ce_xTi₂O₇

A4.1 Introduction

Many research groups are focused on finding alternative fuel sources because of the uncertainty of the world's supply of fossil fuels. An appealing alternative fuel source is hydrogen because it is abundantly found in H₂O. Splitting of H₂O by means such as photocatalysis or electrocatalysis would yield the desired H₂ product. CeO₂ is used in automobile catalytic converters and has the ability to release O₂ (2 CeO₂ \leftrightarrow Ce₂O₃ + ¹/₂ O₂).¹ This ability to release O₂ might suggest applications of CeO₂ as a water oxidation catalyst. Solid oxides are ideal materials for water oxidation electrodes because they are likely to be inert under the high positive potentials required.

There are very few practical electrocatalytic materials for generating H₂ by the oxidation of H₂O and catalysts of this reaction are of great interest. The introduction of Ce into Y₂Ti₂O₇ may also introduce redox activity, therefore, samples of Y_{2-x}Ce_xTi₂O₇ were synthesized for the investigation of their electrocatalytic behavior. A complete solid solution is not expected because the end members of the series, Y₂Ti₂O₇ and Ce₂Ti₂O₇, adopt cubic and monoclinic structure respectively.^{2,3} Powder neutron diffraction data and physical properties are reported herein for Y_{2-x}Ce_xTi₂O₇ (nominal x = 0, 0.15, 0.35).

A4.2 Experimental and Results

A4.2.1 Synthesis

 $Y_{2-x}Ce_xTi_2O_7$ (x = 0, 0.15, 0.35) compounds have been synthesized using solid state ceramic synthesis. Samples are prepared using a combination of grinding and mixing the constituent oxide powders, then pressing a pellet of the resulting mixture. The amounts of reactant oxide powders needed to make ~7 g of product were obtained using the following reaction: $2 TiO_2 + x CeO_2 + (\frac{2-x}{2}) Y_2O_3 \rightarrow Y_{2-x}Ce_xTi_2O_7$. Each sample was mixed and pressed into a pellet with a diameter of ~ 10 mm. The pellets were then dwelled at temperatures of 1000 $^{\circ}$ C, 1100 $^{\circ}$ C, 1300 $^{\circ}$ C, 1400 $^{\circ}$ C, and 1450 $^{\circ}$ C. The samples remained at each temperature for ~ 2 days with intermittent grinding and repressing of the pellet between each heat treatment. Powder X-ray diffraction patterns were measured between each heat treatment to determine if the phase assemblage has reached equilibrium.

A4.2.2 Neutron Powder Diffraction

Neutron powder diffraction (NPD) data were collected for all samples on BT-1 with a Cu(311) monochromator ($\lambda = 1.5403$ Å). Experimental and statistical data are provided in Table A4.1. The NPD data were refined using Rietveld refinement. The observed NPD data are in very good agreement with the calculated NPD data and are shown in Figure A4.1. There are some small impurity peaks (< 4%), which can be attributed to a rutile TiO₂ impurity. The Y₂. $_xCe_xTi_2O_7$ (x = 0, 0.34, and 0.62) compounds crystallize in the cubic space group $Fd\overline{3}m$ (No. 227, origin choice 2). The atomic positions and thermal parameters for all three compounds are shown in Table A4.2. There are no oxygen deficiencies in any of the pyrochlore compounds. The Ce atoms occupy the 16*c* site which was expected based on the ionic radii of the atoms in the compound. Although Ce₂Ti₂O₇ adopts a monoclinic structure type, the introduction of Ce ions at *x* < 0.63 into the cubic pyrochlore structure does not induce any structural phase changes.

 Table A4.1
 Experimental and Statistical Neutron Data for Y_{2-x}Ce_xTi₂O₇

Nominal Composition	$Y_2Ti_2O_7$	Y _{1.85} Ce _{0.15} Ti ₂ O ₇	Y _{1.65} Ce _{0.35} Ti ₂ O ₇
Observed Composition	$Y_2Ti_2O_7$	Y _{1.66} Ce _{0.34} Ti ₂ O ₇	Y _{1.37} Ce _{0.63} Ti ₂ O ₇
Chi ²	1.849	2.223	2.285
R_p	3.96	3.82	4.05
wR_p	4.82	4.49	5.04
a (Å)	10.09983(18)	10.10634(17)	10.11409(5)
TiO ₂ (% wt)	3.21	1.95	0.18221



Figure A4.1 Neutron powder diffraction patterns of (a) $Y_2Ti_2O_7$, (b) $Y_{1.66}Ce_{0.34}Ti_2O_7$, and (c) $Y_{1.37}Ce_{0.63}Ti_2O_7$ where the red crosses are the observed NPD pattern, solid black tick marks are the calculated NPD profiles of $Y_{2-x}Ce_xTi_2O_7$, solid red tick marks are the calculated NPD profiles of rutile TiO₂, and magenta patterns are the difference NPD profiles for $Y_{2-x}Ce_xTi_2O_7$.

Atom	Wyckoff Site	x	у	z	Occupancy	$U_{ m iso}$	
Y ₂ Ti ₂ O ₇							
Y	16 <i>c</i>	0	0	0	1.0	0.00859(18)	
Ti	16 <i>d</i>	1/2	1⁄2	1⁄2	1.0	0.00506(30)	
01	48f	0.420986(61)	1/8	1/8	1.0	0.00811(13)	
O2	8a	1/8	1/8	1/8	1.0	0.00564(28)	
$\overline{Y_{1.66}Ce_{0.34}T}$	i ₂ O ₇						
Y	16 <i>c</i>	0	0	0	0.830(11)	0.00779(22)	
Ce	16 <i>c</i>	0	0	0	0.170(11)	0.00779(22)	
Ti	16 <i>d</i>	1/2	1⁄2	1⁄2	1.0	0.00593(27)	
01	48f	0.421195(51)	1/8	1/8	1.0	0.00884(13)	
O2	8a	1/8	1/8	1/8	1.0	0.00579(24)	
$\overline{Y_{1.37}Ce_{0.63}T}$	i ₂ O ₇						
Y	16 <i>c</i>	0	0	0	0.686(12)	0.00921(28)	
Ce	16 <i>c</i>	0	0	0	0.314(12)	0.00921(28)	
Ti	16 <i>d</i>	1/2	1⁄2	1⁄2	1.0	0.00762(33)	
01	48f	0.420986(61)	1/8	1/8	1.0	0.01082(15)	
O2	8 <i>a</i>	1/8	1/8	1/8	1.0	0.00659(28)	

Table A4.2Atomic Positions and Thermal Parameters of $Y_{2-x}Ce_xTi_2O_7$

A4.2.3 Physical Properties

The magnetic susceptibility and electrical resistivity of $Y_{2.x}Ce_xTi_2O_7$ (x = 0, 0.34, 0.63) were measured. $Y_{2.x}Ce_xTi_2O_7$ (x = 0, 0.34, 0.63) were all insulators. The magnetic susceptibility data was measured at 0.1 T for $Y_{1.66}Ce_{0.34}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ and are displayed in Figure A4.2. Both $Y_{1.66}Ce_{0.34}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ are paramagnetic down to 2 K and $Y_2Ti_2O_7$ is not magnetic. Effective moments of 0.44 μ_B and 0.55 μ_B were obtained from a modified Curie-Weiss fit of the data from 2 – 275 K for $Y_{1.66}Ce_{0.34}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ respectively. A modified Curie-Weiss fit was used because the inverse susceptibility plots were not linear. The calculated magnetic moment for a Ce³⁺ ion is 2.54 μ_B , while Ce⁴⁺is not magnetic. Weiss temperatures (θ) of -0.81 K and -1.01 K were obtained for $Y_{1.66}Ce_{0.34}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ respectively. The field-dependent magnetization data were measured for both compounds at 3 K and are shown in Figure A4.3. The magnetization of both compounds do not saturate in magnetic fields up to 9 T. The magnetization is well below the saturation moment for Ce³⁺ of 2.14 μ_B .



Figure A4.2 Magnetic susceptibility of $Y_{1.66}Ce_{0.3394}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ measured at 0.1 T where the red triangles and blue circles are $Y_{1.66}Ce_{0.34}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ respectively.



Figure A4.3 Magnetization of $Y_{1.66}Ce_{0.3394}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ measured at 3 K where the red triangles and blue circles are $Y_{1.66}Ce_{0.34}Ti_2O_7$ and $Y_{1.37}Ce_{0.63}Ti_2O_7$ respectively.

A4.3 References

- (1) Dresselhaus, M. S.; Thomas, I. L. *Nature* **2001**, *414*, 332-337.
- (2) Brixner, L. H. Inorg. Chem. 1964, 3, 1065-1067.
- (3) Zakharov, N. A.; Stefanovich, S. Y.; Kustov, E. F.; Venevtsev, Y. N. *Kristall und Technik* **1980**, *15*, 29-33.
- (4) Milanova, M. M.; Kakihana, M.; Arima, M.; Yashima, M.; Yoshimura, M. J. Alloys. *Compds.* **1996**, 242, 6-10.

APPENDIX 5 – UNPUBLISHED CRYSTALLOGRAPHIC INFORMATION FILES

A5.1 Rb₄Mn(MoO₄)₃

```
data dixie67
audit creation method
                                    SHELXL-97
chemical name systematic
;
 ?
;
_chemical_name_common
                                      ?
_chemical_melting_point
_chemical_formula_moiety
                                      ?
                                     'Rb4Mn (MoO4) 3'
_chemical_formula_sum
'Mn Mo3 O12 Rb4'
_chemical_formula_weight 876.64
loop
 _atom_type_symbol
 _atom_type_description
 _atom_type_scat_dispersion real
_atom_type_scat_dispersion_imag
_atom_type_scat_source
'Mn' 'Mn' 0.3368 0.7283
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
 'Mo' 'Mo' -1.6832 0.6857
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
 'O' 'O' 0.0106 0.0060
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
 'Rb' 'Rb' -0.9393 2.9676
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
_symmetry_cell_setting
                                      'hexagonal'
_symmetry_space_group_name_H-M
                                      'P63/mmc'
loop_
 _symmetry_equiv_pos_as_xyz
'x, y, z'
 '-x, -y, z+1/2'
 '-y, -x, -z+1/2'
 'y, x, -z'
 'x-y, -y, -z'
 '-x+y, y, -z+1/2'
 'x, x-y, -z+1/2'
 '-x, -x+y, -z'
 '-y, x-y, z'
 'y, -x+y, z+1/2'
 'x-y, x, z+1/2'
 '-x+y, -x, z'
 '-x, -y, -z'
 'x, y, -z-1/2'
 'y, x, z-1/2'
 '-y, -x, z'
 '-x+y, y, z'
 'x-y, -y, z-1/2'
 '-x, -x+y, z-1/2'
 'x, x-y, z'
 'y, -x+y, -z'
'-y, x-y, -z-1/2'
 '-x+y, -x, -z-1/2'
 'x-y, x, -z'
_cell_length a
                                    6.0990(10)
                                   6.0990(10)
23.711(3)
90.00
_cell_length_b
_cell_length_c
_cell_angle_alpha
_cell_angle_beta
                                     90.00
_cell_angle_gamma
                                     120.00
```

_cell volume 763.8(2) _cell_formula_units Z 2 cell measurement temperature 293(2) _cell_measurement_reflns_used ? cell measurement theta min ? cell measurement theta max ? _exptl_crystal description 'plate shaped fragment' _exptl_crystal_colour 'light brown' _exptl_crystal_size_max 0.075 exptl crystal size mid 0.075 _exptl_crystal_size_min 0.025 _exptl_crystal_density_meas
_exptl_crystal_density_diffrn ? 3.812 _exptl_crystal_density_method 'not measured' _exptl_crystal_F_000 790 _exptl_absorpt_coefficient_mu _exptl_absorpt_correction_type 15.922 `multi-scan' exptl absorpt correction T min ? _exptl_absorpt_correction_T_max _exptl_absorpt_process_details 'HKL Scalepack (Otwinowski & Minor 19' _exptl_special_details ; ? ; _diffrn_ambient_temperature _diffrn_radiation_wavelength 293(2) 0.71073 _diffrn_radiation_type MoK\a 'fine-focus sealed tube' diffrn radiation source _diffrn_radiation_monochromator graphite 'KappaCCD' _diffrn_measurement_device type _diffrn_measurement_method ' \w scans \k offsets' 2 diffrn detector area resol mean diffrn standards number 0 _diffrn_standards_interval_count ? _diffrn_standards_interval_time ? diffrn standards decay % none diffrn reflns number 2762 _diffrn_reflns_av_R_equivalents 0.0531 diffrn reflns av sigmaI/netI 0.0379 diffrn reflns limit h min -8 _diffrn_reflns_limit_h_max 8 -6 6 _diffrn_reflns_limit_l_min -32 _diffrn_reflns_limit_l_max _diffrn_reflns_theta_min 32 3.44 diffrn reflns theta max 29.98 reflns number total 489 _reflns_number_gt 376 reflns threshold expression >2sigma(I) 'COLLECT (Nonius, 2000)' $_computing_data_collection$ computing cell refinement 'Denzo and Scalepack (Otwinowski & Minor, 1997)' _computing_data reduction 'Denzo and Scalepack (Otwinowski & Minor, 1997)' _computing_structure_solution 'SHELXS-97 (Sheldrick, 1990)' _computing_structure refinement 'SHELXL-97 (Sheldrick, 1997)' ? computing_molecular_graphics _computing_publication_material 'SHELXL-97 (Sheldrick, 1997)' refine special details Refinement of $F^{2^{-}}$ against ALL reflections. The weighted R-factor wR and goodness of fit S are based on F^2^, conventional R-factors R are based on F, with F set to zero for negative F^2 . The threshold expression of $F^{2^{>}} > 2sigma(F^{2^{+}})$ is used only for calculating R-factors(gt) etc. and is not relevant to the choice of reflections for refinement. R-factors based on ${\tt F}^2{\tt ^}$ are statistically about twice as large as those based on F, and Rfactors based on ALL data will be even larger.

_refine_ls_structure_factor_coef Fsqd
refine ls matrix type full refine ls weighting scheme calc _refine_ls_weighting_details 'calc $\overline{w}=1/[\s^2^{(50^2^+)}+(0.0421P)^2^{+0.7989P}]$ where $P=(Fo^2^{+2Fc^2})/3'$ _atom_sites_solution_primary direct _atom_sites_solution_secondary difmap atom sites solution hydrogens geom refine ls hydrogen treatment none refine_ls_extinction method SHELXL refine ls extinction coef 0.0049(8)_refine_ls_extinction expression 'Fc^*^=kFc[1+0.001xFc^2^\1^3^/sin(2\q)]^-1/4^' _refine_ls_number reflns 489 refine ls number parameters 37 _refine_ls_number_restraints 0 0.0396 _refine_ls_R_factor_all _refine_ls_R_factor_gt 0.0288 __refine_ls_wR_factor_ref 0.0810 _refine_ls_wR_factor_gt 0.0749 _refine_ls_goodness_of_fit ref 1.061 refine ls restrained S all 1.061 _refine_ls_shift/su_max_ 0.000 refine_ls_shift/su_mean 0.000 loop_ atom site label _atom_site_type symbol _atom_site_fract_x atom site fract y _atom_site_fract_z _atom_site_U_iso_or_equiv _atom_site_adp_type _atom_site_occupancy _atom_site_symmetry multiplicity _atom_site_calc_flag _atom_site_refinement flags _atom_site_disorder assembly atom_site_disorder_group Rb1 Rb 0.3333 0.6667 0.15755(3) 0.0344(3) Uani 1 6 d S . . Rb2 Rb 0.6667 0.3333 0.02849(3) 0.0283(3) Uani 1 6 d S . . Mn1 Mn 0.0000 0.0000 0.2500 0.0281(4) Uani 1 12 d S . . Mol Mo 1.0000 0.0000 0.09016(2) 0.0196(2) Uani 1 6 d S . . Mo2 Mo 0.6667 0.3333 0.22782(6) 0.0255(5) Uani 0.481(3) 6 d SP . . 01 0 0.0000 0.0000 0.1645(2) 0.056(2) Uani 1 6 d S . . 02 0 0.1555(3) 0.3109(6) 0.06565(15) 0.0406(9) Uani 1 2 d S . . O3 O 0.6667 0.3333 0.1557(4) 0.047(6) Uani 0.50(2) 6 d SP . 04 0 0.3859(12) 0.3283(13) 0.2500 0.041(2) Uani 0.506(9) 2 d SP . . loop _atom_site_aniso_label atom site aniso U 11 _atom_site_aniso_U_22 _atom_site_aniso_U_33 _atom_site_aniso_U_23 _atom_site_aniso_U_13 atom site aniso U 12 Rb1 0.0391(4) 0.0391(4) 0.0250(5) 0.000 0.000 0.01957(18) Rb2 0.0279(3) 0.0279(3) 0.0290(4) 0.000 0.000 0.01396(15) Mn1 0.0360(6) 0.0360(6) 0.0123(8) 0.000 0.000 0.0180(3) Mo1 0.0224(3) 0.0224(3) 0.0140(4) 0.000 0.000 0.01119(14) Mo2 0.0281(6) 0.0281(6) 0.0203(6) 0.000 0.000 0.0140(3) 01 0.076(4) 0.076(4) 0.015(3) 0.000 0.000 0.0380(18) 02 0.0463(17) 0.0235(18) 0.0444(19) 0.0056(17) 0.0028(9) 0.0117(9) 03 0.062(8) 0.062(8) 0.017(7) 0.000 0.000 0.031(4) 04 0.034(4) 0.041(4) 0.045(4) 0.000 0.000 0.017(3) _geom_special_details

;

All esds (except the esd in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell esds are taken into account individually in the estimation of esds in distances, angles and torsion angles; correlations between esds in cell parameters are only

used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell esds is used for estimating esds involving l.s. planes.

loop _geom_bond_atom_site_label_1 _geom_bond_atom_site_label_2 _geom_bond_distance _geom_bond_site_symmetry_2 geom_bond_publ_flag Rb1 02 2.877(3) . ? Rb1 02 2.877(3) 20 565 ? Rb1 02 2.877(3) 16 665 ? Rb1 04 3.135(5) 9 665 ? Rb1 04 3.135(5) 7 565 ? Rb1 04 3.135(5) 23_566 ? Rb1 04 3.135(5) 17? Rb1 04 3.135(5) 3_665 ? Rb1 04 3.135(5) . ? Rb1 03 3.5215(6) 1_455 ? Rb1 03 3.5215(6) 1_565 ? Rb1 03 3.5215(6) . ? Rb2 O2 2.918(3) 8_655 ? Rb2 02 2.918(3) 4? Rb2 O2 2.918(3) 13_665 ? Rb2 03 3.016(10) . ? Rb2 O2 3.1765(11) 1_655 ? Rb2 02 3.1765(11) 16_655 ? Rb2 02 3.1765(11) 20 665 ? Rb2 02 3.1765(11) 20 ? Rb2 O2 3.1765(11) 16_665 ? Rb2 02 3.1765(11) . ? Rb2 Rb2 3.7715(8) 13 655 ? Rb2 Rb2 3.7715(8) 13 765 ? Mn1 01 2.028(6) 14 556 ? Mn1 01 2.028(6) . ? Mn1 04 2.199(7) 3 ? Mn1 04 2.199(7) . ? Mn1 04 2.199(6) 23 556 ? Mn1 04 2.199(6) 7 ? Mn1 04 2.199(6) 9 ? Mn1 04 2.199(6) 17 ? Mn1 Rb1 4.1478(6) 14 546 ? Mn1 Rb1 4.1478(7) 14_556 ? Mn1 Rb1 4.1478(6) 1 545 ? Mn1 Rb1 4.1478(6) 1 445 ? Mol 02 1.742(3) 16 655 ? Mo1 02 1.742(3) 20 655 ? Mo1 O2 1.742(3) 1_655 ? Mo1 01 1.762(6) 1 655 ? Mo1 Rb2 3.8128(6) 1 545 ? Mo1 Rb2 3.8128(7) 1_655 ? Mo1 Rb1 3.8669(6) 1_645 ? Mo1 Rb1 3.8669(7) 1 655 ? Mo1 Rb1 3.8669(7) 1_545 ? Mo2 Mo2 1.052(3) 14 556 ? Mo2 O3 1.710(10) . ? Mo2 04 1.777(6) 17_655 ? Mo2 04 1.777(6) 9 655 ? Mo2 04 1.777(7) 23 666 ? Mo2 04 1.777(7) 7 ? Mo2 04 1.777(6) 3_665 ? Mo2 04 1.777(6) . ? Mo2 Rb1 3.8955(9) 1 545 ? Mo2 Rb1 3.8955(9) 1 655 ? O1 Mo1 1.762(6) 1_455 ? O1 Rb1 3.5251(6) 1_545 ? 01 Rb1 3.5251(6) 1 445 ?

O2 Mo1 1.742(3) 1 455 ? 02 Rb2 2.918(3) 13 665 ? O2 Rb2 3.1765(11) 1 455 ? O3 Rb1 3.5215(6) 1_655 ? O3 Rb1 3.5215(6) 1_545 ? 04 04 1.651(14) 7 ? 04 04 1.743(13) 3_665 ? O4 Mo2 1.777(6) 14 556 ? 04 Rb1 3.135(5) 14 556 ?

O4 Rb1 O3 125.37(18) . 1_565 ? O3 Rb1 O3 119.984(7) 1_455 1_565 ? 02 Rb1 03 70.37(13) . . ? O2 Rb1 O3 130.05(18) 20 565 . ? 02 Rb1 03 70.37(13) 16_665 . ? 04 Rb1 03 95.59(17) 9 665 . ? 04 Rb1 03 125.37(17) 7 565 . ? 04 Rb1 03 125.37(17) 23 566 . ? 04 Rb1 03 95.59(17) 17 . ? O4 Rb1 O3 49.48(18) 3_665 . ?

<text><text>

O4 Mo2 O4 145.53(16) 17 655 . ? O4 Mo2 O4 111.63(7) 9 655 . ? O4 Mo2 O4 111.63(7) 23 666 . ? 04 Mo2 04 55.4(4) 7 . ? O4 Mo2 O4 58.7(4) 3 665 . ? Mo2 Mo2 Rb1 115.32(2) 14_556 1_545 ? O3 Mo2 Rb1 64.68(2) . 1 545 ? O4 Mo2 Rb1 96.5(2) 17 655 1 545 ? 04 Mo2 Rb1 52.09(14) 9 655 1 545 ? 04 Mo2 Rb1 151.8(2) 23 666 1 545 ? 04 Mo2 Rb1 52.09(14) 7 1 545 ? O4 Mo2 Rb1 151.8(2) 3_665 1_545 ? 04 Mo2 Rb1 96.5(2) . 1 545 ? Mo2 Mo2 Rb1 115.32(2) 14 556 1 655 ? O3 Mo2 Rb1 64.68(2) . 1 655 ? O4 Mo2 Rb1 52.09(14) 17 655 1 655 ? O4 Mo2 Rb1 96.5(2) 9_655 1_655 ? O4 Mo2 Rb1 52.09(14) 23_666 1_655 ? O4 Mo2 Rb1 151.8(2) 7 1_655 ? O4 Mo2 Rb1 96.5(2) 3_665 1_655 ? O4 Mo2 Rb1 151.8(2) . 1_655 ? Rb1 Mo2 Rb1 103.04(3) 1 545 1 655 ? Mo2 Mo2 Rb1 115.32(2) 14_556 . ? O3 Mo2 Rb1 64.68(2) . . ? O4 Mo2 Rb1 151.8(2) 17 655 . ? O4 Mo2 Rb1 151.8(2) 9_655 . ? 04 Mo2 Rb1 96.5(2) 23 666 . ? 04 Mo2 Rb1 96.5(2) 7 . ? O4 Mo2 Rb1 52.09(14) 3_665 . ? O4 Mo2 Rb1 52.09(14) . . ? Rb1 Mo2 Rb1 103.04(3) 1 545 . ? Rb1 Mo2 Rb1 103.04(3) 1_655 . ? Mol Ol Mnl 180.0 1 455 . ? Mo1 O1 Rb1 87.34(10) 1 455 1 545 ? Mn1 O1 Rb1 92.66(10) . 1 545 ? Mol Ol Rb1 87.34(10) 1 455 1 445 ? Mn1 01 Rb1 92.66(10) . 1_445 ? Rb1 01 Rb1 119.786(16) 1 545 1 445 ? Mol Ol Rb1 87.34(10) 1 455 . ? Mn1 01 Rb1 92.66(10) . . ? Rb1 O1 Rb1 119.786(16) 1_545 . ? Rb1 O1 Rb1 119.786(16) 1_445 . ? Mo1 02 Rb1 111.29(16) 1_455 . ? Mo1 O2 Rb2 149.57(17) 1 455 13 665 ? Rb1 02 Rb2 99.14(9) . 13 665 ? Mo1 O2 Rb2 97.33(6) 1_455 1_455 ? Rb1 02 Rb2 100.71(6) . 1 455 ? Rb2 O2 Rb2 76.34(6) 13 665 1 455 ? Mol O2 Rb2 97.33(6) 1 455 . ? Rb1 02 Rb2 100.71(6) . . ? Rb2 O2 Rb2 76.34(6) 13 665 . ? Rb2 02 Rb2 147.49(12) 1 455 . ? Mo2 O3 Rb2 180.0 . . ? Mo2 O3 Rb1 89.28(16) . 1 655 ? Rb2 O3 Rb1 90.72(16) . 1_655 ? Mo2 O3 Rb1 89.28(16) . 1 545 ? Rb2 O3 Rb1 90.72(16) . 1 545 ? Rb1 O3 Rb1 119.984(8) 1_655 1_545 ? Mo2 O3 Rb1 89.28(16) . . ? Rb2 03 Rb1 90.72(16) . . ? Rb1 O3 Rb1 119.984(8) 1 655 . ? Rb1 03 Rb1 119.984(8) 1_545 . ? 04 04 04 120.000(2) 7 3_665 ? 04 04 Mo2 62.3(2) 7 14 556 ? 04 04 Mo2 60.6(2) 3_665 14_556 ? 04 04 Mo2 62.3(2) 7 . ? O4 O4 Mo2 60.6(2) 3 665 . ? Mo2 O4 Mo2 34.43(15) 14 556 . ? 04 04 Mn1 67.95(18) 7 . ? O4 O4 Mn1 172.05(18) 3 665 . ? Mo2 O4 Mn1 126.8(3) 14 556 . ?

Mo2 04 Mn1 126.8(3) . . ? 04 04 Rb1 135.18(9) 7 14_556 ? 04 04 Rb1 73.86(12) 3_665 14_556 ? Mo2 04 Rb1 101.34(15) 14_556 14_556 ? Mo2 04 Rb1 127.6(3) . 14_556 ? Mn1 04 Rb1 100.62(18) . 14_556 ? 04 04 Rb1 135.18(9) 7 . ? 04 04 Rb1 73.86(11) 3_665 . ? Mo2 04 Rb1 127.6(3) 14_556 . ? Mo2 04 Rb1 101.34(15) . . ? Mn1 04 Rb1 100.62(18) . . ? Rb1 04 Rb1 88.73(18) 14_556 . ? diffrn_measured_fraction_theta_max 0.996 _diffrn_reflns_theta_full 29.98

diffrn measured fra	action theta full	0.996
refine diff density	7 max 0.892	
refine diff density		
_refine_diff_density	rms 0.150	

A5.2 Rb₄Zn(MoO₄)₃

data dixie76

```
SHELXL-97
_audit_creation_method
;
 ?
;
                                    2
_chemical_name_common
?
_chemical_formula_moiety
                                     'Rb<sub>4</sub>Zn (MoO<sub>4</sub>) <sub>3</sub>'
_chemical_formula_sum
'Mo3 O12 Rb4 Zn'
chemical formula weight
                                    887.07
loop_
 _atom_type_symbol
 _atom_type_description
 _atom_type_scat_dispersion real
 _atom_type_scat_dispersion_imag
 _atom_type_scat_source
'0' '0' 0.0106 0.0060
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
 'Zn' 'Zn' 0.2839 1.4301
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
 'Rb' 'Rb' -0.9393 2.9676
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
 'Mo' 'Mo' -1.6832 0.6857
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
_symmetry cell setting
                                     'orthorhombic'
                                     'Pbca'
_symmetry_space_group_name_H-M
loop
  _symmetry_equiv_pos_as_xyz
 'x, y, z'
 '-x+1/2, -y, z+1/2'
 'x+1/2, -y+1/2, -z'
 '-x, y+1/2, -z+1/2'
 '-x, -y, -z'
 'x-1/2, y, -z-1/2'
 '-x-1/2, y-1/2, z'
 'x, -y-1/2, z-1/2'
_cell_length_a
                                    12.485(2)
_cell_length_b
                                    10.8750(10)
_cell_length_c
_cell_angle_alpha
                                    22.2660(10)
                                    90.00
_cell_angle_beta
                                    90.00
_cell_angle_gamma
                                    90.00
_cell_volume
cell formula units Z
                                    3023.2(6)
                                    8
cell_measurement_temperature
                                    293(2)
_cell_measurement_reflns_used
_cell_measurement_theta_min
                                     ?
                                     2
_cell_measurement_theta_max
                                     ?
_exptl_crystal_description
                                     'plate-shaped fragment'
_____exptl_crystal_colour
                                    'blue-green'
_exptl_crystal_size max
                                    0.13
_exptl_crystal_size_mid
                                    0.10
_exptl_crystal_size_min
                                    0.05
_exptl_crystal_density meas
                                    2
_exptl_crystal_density_diffrn
                                    3.898
_exptl_crystal_density_method
_exptl_crystal_F_000
                                    'not measured'
                                     3200
_exptl_absorpt_coefficient mu
                                    16.843
_exptl_absorpt_correction_type
                                     ?
exptl absorpt correction T min
                                    0.2273
```

```
exptl absorpt correction T max
                                  0.4864
exptl absorpt process details
                                   ?
_exptl_special_details
;
?
;
_diffrn_ambient_temperature
                                  293(2)
_diffrn_radiation_wavelength
                                   0.71073
diffrn radiation type
                                  MoK\a
_diffrn_radiation_source
                                   'fine-focus sealed tube'
_diffrn_radiation_monochromator
                                   graphite
 diffrn measurement device type
                                   'KappaCCD'
diffrn_measurement method
                                   ' \w scans \k offsets'
_diffrn_detector_area_resol mean
                                  ?
 diffrn standards number
                                   0
?
_diffrn_standards_interval_time
                                   ?
_diffrn_standards_decay_%
                                   none
diffrn reflns number
                                   8235
diffrn reflns av R equivalents
                                   0.0535
                                   0.0624
_diffrn_reflns_av_sigmaI/netI
_diffrn_reflns_limit_h_min
_diffrn_reflns_limit_h_max
                                   -17
                                  17
diffrn reflns limit k min
                                  -15
15
                                   -31
_diffrn_reflns_limit_l_max
                                   31
_diffrn_reflns_theta_min
                                   2.45
                                   30.02
 diffrn reflns theta max
_reflns_number_total
                                   4419
reflns number gt
                                  2922
_reflns_threshold expression
                                  >2sigma(I)
_computing data collection
                                  'COLLECT (Nonius, 2000)'
_computing_cell_refinement
                              'Denzo and Scalepack (Otwinowski & Minor, 1997)'
_computing_data reduction
                              'Denzo and Scalepack (Otwinowski & Minor, 1997)'
                                   'SHELXS-97 (Sheldrick, 1990)'
computing structure solution
computing structure refinement
                                   'SHELXL-97 (Sheldrick, 1997)'
                                   ?
_computing_molecular_graphics
computing publication material
                                   'SHELXL-97 (Sheldrick, 1997)'
_refine_special_details
;
 Refinement of F^2^ against ALL reflections. The weighted R-factor wR and
 goodness of fit S are based on F^{2^{,}}, conventional R-factors R are based
 on F, with F set to zero for negative F^{2^{-}}. The threshold expression of
 F^2^> > 2sigma(F^2^) is used only for calculating R-factors(gt) etc. and is
 not relevant to the choice of reflections for refinement. R-factors based
 on F^{2^{-}} are statistically about twice as large as those based on F, and R-
 factors based on ALL data will be even larger.
;
_refine_ls_structure_factor_coef Fsqd
 refine ls matrix type
                                   full
refine_ls_weighting_scheme
                                  calc
_refine_ls_weighting_details
 'calc \overline{w}=1/[(s^{2}(Fo^{2})+(0.0394P)^{2}+9.0735P]] where P=(Fo^{2}+2Fc^{2})/3'
_atom_sites_solution_primary
                                  direct
atom sites solution secondary
                                   difmap
_atom_sites_solution_hydrogens
                                   geom
_refine_ls_hydrogen_treatment
                                   none
refine ls extinction method
                                   SHELXL
refine ls extinction coef
                                   0.000134(18)
_refine_ls_extinction_expression
_Fc^*^=kFc[1+0.001xFc^2^\l^3/sin(2\q)]^-1/4^'
_refine_ls number reflns
                                  4419
_refine_ls_number_parameters
                                  182
_refine_ls_number_restraints
                                   0
refine ls R factor all
                                   0.0873
```

```
101
```

refine ls R factor gt 0.0456 refine ls wR factor ref 0.1062 refine_ls_wR_factor_gt 0.0919 _refine_ls_goodness_of_fit_ref 1.032 _refine_ls_restrained_S_all 1.032 _refine_ls_shift/su_max 0.002 refine ls shift/su mean 0.000 loop _atom_site label atom site type symbol _atom_site_fract x _atom_site_fract_y atom site fract z _atom_site_U_iso_or equiv _atom_site_adp_type _atom_site_occupancy _atom_site_symmetry_multiplicity _atom_site_calc flag _atom_site_refinement_flags _atom_site_disorder assembly atom site disorder group Mo01 Mo 0.37662(4) 0.74717(5) 0.90582(2) 0.00993(13) Uani 1 1 d . . . Mo02 Mo 0.87294(4) 0.75407(5) 0.90704(2) 0.01007(13) Uani 1 1 d . . . Mo03 Mo 0.37491(5) 0.42223(5) 0.73384(3) 0.01156(14) Uani 1 1 d . . . Rb01 Rb 0.62709(5) 0.91860(6) 0.97183(3) 0.01378(15) Uani 1 1 d . . . Rb02 Rb 0.87567(5) 1.08440(6) 1.03151(3) 0.01385(15) Uani 1 1 d . . . Rb03 Rb 0.10545(6) 0.57003(6) 0.83948(3) 0.01477(15) Uani 1 1 d . . . Rb04 Rb 0.62453(5) 0.59903(6) 0.84265(3) 0.01486(16) Uani 1 1 d . . . Zn01 Zn 0.32067(7) 0.71724(7) 0.75429(3) 0.01259(18) Uani 1 1 d . . . 01 0 0.3690(4) 0.7428(4) 0.6740(2) 0.0205(11) Uani 1 1 d . . . O2 O 0.4986(4) 0.4614(4) 0.7629(2) 0.0165(10) Uani 1 1 d . . . O3 O 0.3980(4) 0.7525(4) 0.82513(19) 0.0167(11) Uani 1 1 d . . . 04 0 0.5121(4) 0.1802(4) 0.9333(2) 0.0188(11) Uani 1 1 d . . . O5 O 0.2808(4) 0.5400(4) 0.75474(19) 0.0168(10) Uani 1 1 d . . 06 0 0.1704(4) 0.7760(4) 0.7622(2) 0.0178(10) Uani 1 1 d . . . 07 0 0.2594(4) 0.6681(5) 0.9229(2) 0.0224(12) Uani 1 1 d . . . 08 0 0.3683(4) 0.8969(4) 0.9333(2) 0.0201(11) Uani 1 1 d . . . 09 0 0.3833(4) 0.4173(4) 0.65647(19) 0.0195(11) Uani 1 1 d . . . 010 0 0.4851(4) 0.6700(4) 0.9381(2) 0.0206(11) Uani 1 1 d . . . 011 0 0.6227(4) 0.4084(4) 0.92981(19) 0.0167(11) Uani 1 1 d . . . 012 0 0.7585(4) 0.6840(4) 0.93782(19) 0.0174(11) Uani 1 1 d . . . loop _atom_site aniso label _atom_site_aniso_U_11 _atom_site_aniso_U_22 _atom_site_aniso_U_33 _atom_site_aniso_U 23 _atom_site_aniso_U_13 atom site aniso U 12 $M_{0}01 \ 0.0118(3) \ 0.0101(3) \ 0.0080(3) \ 0.00017(19) \ -0.0003(2) \ -0.0005(2)$ Mo02 0.0117(3) 0.0103(3) 0.0082(3) 0.0001(2) -0.0008(2) 0.0000(2) Mo03 0.0122(3) 0.0101(3) 0.0124(3) -0.0004(2) -0.0004(2) -0.0001(2) Rb01 0.0155(4) 0.0144(3) 0.0114(3) -0.0003(2) 0.0004(2) 0.0001(3) Rb02 0.0141(4) 0.0142(3) 0.0132(3) 0.0010(2) -0.0005(2) 0.0001(3) Rb03 0.0160(3) 0.0175(3) 0.0108(3) 0.0005(2) 0.0007(2) -0.0008(3) Rb04 0.0171(4) 0.0176(3) 0.0099(3) -0.0003(2) 0.0004(3) -0.0029(3) Zn01 0.0147(4) 0.0126(4) 0.0105(3) -0.0007(3) -0.0008(3) 0.0005(3) 01 0.028(3) 0.025(3) 0.009(2) 0.001(2) -0.002(2) -0.004(2) 02 0.014(3) 0.016(2) 0.020(2) -0.003(2) -0.004(2) -0.0019(19) 03 0.023(3) 0.021(2) 0.006(2) 0.0009(18) -0.001(2) -0.007(2) 04 0.017(3) 0.024(3) 0.016(2) -0.003(2) -0.001(2) -0.007(2) 05 0.016(3) 0.013(2) 0.020(2) 0.0008(19) 0.004(2) 0.000(2) 06 0.022(3) 0.012(2) 0.019(2) 0.002(2) 0.005(2) 0.000(2) 07 0.018(3) 0.030(3) 0.020(2) 0.003(2) 0.000(2) -0.015(2) 08 0.030(3) 0.014(2) 0.016(2) 0.0005(19) 0.005(2) 0.003(2) 09 0.023(3) 0.023(3) 0.013(2) 0.000(2) -0.002(2) -0.003(2) 010 0.022(3) 0.025(3) 0.015(2) 0.002(2) 0.001(2) 0.010(2) 011 0.027(3) 0.008(2) 0.015(2) -0.0008(18) 0.002(2) 0.001(2) 012 0.019(3) 0.023(3) 0.010(2) 0.004(2) -0.001(2) -0.003(2)

_geom_special_details;

All esds (except the esd in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell esds are taken into account individually in the estimation of esds in distances, angles and torsion angles; correlations between esds in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell esds is used for estimating esds involving l.s. planes.

loop

_geom_bond_atom_site_label_1 _geom_bond_atom_site_label_2 _geom_bond_distance _geom_bond_site_symmetry_2 geom_bond_publ_flag Mo01 07 1.740(5) . ? Mo01 08 1.742(5) . ? Mo01 010 1.748(5) . ? Mo01 03 1.817(4) . ? Mo01 Rb04 3.7621(10) . ? Mo01 Rb03 3.8157(9) 7_665 ? Mo01 Rb02 3.8665(9) 3 467 Mo01 Rb02 3.9018(9) 5 677 ? Mo01 Rb01 3.9261(9) . ? Mo01 Rb03 4.1660(10) . ? Mo02 04 1.746(5) 7_765 ? Mo02 011 1.754(4) 7_765 ? Mo02 012 1.758(5) . ? Mo02 01 1.808(5) 6 657 ? Mo02 Rb04 3.8102(9) . ? Mo02 Rb03 3.8334(9) 1_655 ? Mo02 Rb01 3.8347(9) . ? Mo02 Rb02 3.8482(9) 5_777 ? Mo02 Rb01 3.9230(9) 7 755 ? Mo02 Rb04 4.0163(9) 7_765 ? Mo03 09 1.727(4) . ? Mo03 02 1.727(5) . ? Mo03 O5 1.800(5) . ? Mo03 06 1.802(5) 7 655 ? Mo03 Rb03 3.6787(10) 6 657 ? Mo03 Rb04 3.9055(9) 4 646 ? Mo03 Rb04 4.0459(9) 6 557 ? Rb01 09 2.860(4) 4 656 ? Rb01 08 2.915(5) 5_677 ? Rb01 04 2.939(5) 5 667 ? Rb01 07 3.018(5) 3_567 ? Rb01 012 3.126(5) . ? Rb01 011 3.263(5) 7 765 ? Rb01 04 3.300(5) 1 565 ? Rb01 012 3.309(5) 7_765 ? Rb01 010 3.319(5) . ? Rb01 08 3.352(5) . ? Rb01 Rb02 3.8274(10) . ? Rb02 010 2.866(5) 7 765 ? Rb02 012 2.886(5) 7 765 ? Rb02 011 2.965(4) 7_765 ? Rb02 08 3.152(5) 5 677 ? Rb02 010 3.159(5) 3 567 ? Rb02 04 3.173(5) 3 567 ? Rb02 011 3.203(5) 3 567 ? Rb02 07 3.268(5) 3 567 ? Rb02 07 3.334(5) 5 677 ? Rb02 Mo02 3.8482(9) 5 777 ? Rb02 Mo01 3.8665(9) 3 567 ? Rb03 04 2.820(5) 7 665 ? Rb03 08 2.830(5) 7_655 ? Rb03 07 2.878(5) . ? Rb03 02 2.893(5) 6_557 ? Rb03 05 2.908(5) . ?

Rb03 06 2.939(4) . ? Rb03 09 3.234(5) 6_557 ? Rb03 03 3.468(5) 7_655 ? Rb03 01 3.512(5) 6_557 ? Rb03 Zn01 3.6581(11) . ? Rb03 Mo03 3.6787(10) 6_557 ? Rb03 Mo01 3.8157(9) 7_655 ?
Rb04 02 2.805(5) ? Rb04 011 2.840(4) ? Rb04 012 2.853(5) ? Rb04 05 2.986(5) 6 657 ? Rb04 01 3.450(5) 6 657 ? Rb04 09 3.463(5) 4 656 ? Rb04 201 3.5083(11) 6 657 ?
21101 0.3 1.889(3) 1 2n01 0.1 1.908(5) . 2n01 0.6 1.990(5) . 2n01 0.5 1.991(5) . 2n01 Rb04 3.5083(10) 6_557 01 Mo02 1.808(5) 6_557 01 Rb04 3.450(5) 6_557 01 Rb03 3.512(5) 6_657 02 Rb03 2.893(5) 6_657 03 Rb03 3.468(5) 7_655 04 Mc02 1 746(5)
O4 MoO2 1.746(5) 7_755 ? O4 RbO3 2.820(5) 7_655 ? O4 RbO1 2.939(5) 5_667 ? O4 RbO2 3.173(5) 3_467 ? O4 RbO1 3.300(5) 1_545 ? O5 RbO4 2.986(5) 6_557 ? O6 RbO4 3.079(5) 6_557 ? O7 RbO1 3.018(5) 3_467 ? O7 RbO2 3_268(5) 3_467 ?
07 Rb02 3.234(5) 5_407 ? 07 Rb03 2.830(5) 7_665 ? 08 Rb01 2.915(5) 5_677 ? 08 Rb02 3.152(5) 5_677 ? 09 Rb01 2.860(4) 4_646 ? 09 Rb03 3.234(5) 6_657 ? 09 Rb03 3.463(5) 4_646 ? 09 Rb03 3.234(5) 6_657 ? 09 Rb03 3.463(5) 4_646 ? 09 Rb03 3.463(5) 4_646 ? 010 Rb02 2.866(5) 7_755 ? 010 Rb02 3 159(5) 3_467 2
011 Mo02 1.754(4) 7_755 ? 011 Rb02 2.965(4) 7_755 ? 011 Rb02 3.203(5) 3_467 ? 011 Rb01 3.263(5) 7_755 ? 012 Rb01 3.309(5) 7_755 ? 100p
_geom_angle_atom_site_label_1 _geom_angle_atom_site_label_2 _geom_angle_atom_site_label_3 _geom_angle_site_symmetry_1 _geom_angle_site_symmetry_3 _geom_angle_publ_flag 07 Mo01 08 109.6(2) ?
07 Mo01 010 109.0(2) ? 08 Mo01 010 110.5(2) ? 07 Mo01 03 110.9(2) ? 08 Mo01 03 109.0(2) ? 010 Mo01 03 107.9(2) ? 07 Mo01 Rb04 124.23(18) ? 08 Mo01 Rb04 125.49(17) ? 010 Mo01 Rb04 46.42(15) ? 03 Mo01 Rb04 61.52(16) ?

07 M	1001 R)	b03 1	26.0)7(18)		7	6	65	3	?			
08 M	1001 RJ	b03 4	3.88	3(1	5)		7	66	5	?				
010	Mo01 1	Rb03	123.	74	(17)	•	7_	66	5	?			
03 M	1001 R)	b03 6	5.11	(1	5)	•	7_	66	5	?				
Rb04	Mo01	Rb03	101	. 6	0(2)	•	7_	66	5	?			
07 №	1001 RI	b02 5	7.15	5(1)	8)	·	3_	46	7	?				
08 M	1001 RJ	b02 1	38.1	.5 (15)	•	3	-4	67	3	2			
010	MOUL I	Rb02	53.5	08(. 70()	17)	•	3	-4	67					
03 M	No01	DUZ I	12.1	01	13) 0 (1	•	3	-4 2	6/	6-	,	2		
RDU4 Ph03	Mo01	RDUZ Ph02	174	. O T (0 (⊥ 1 / 2	0) \	- ·	د ۵۵	_4 5	3	́л.	: 67	2	
07 1	0001 B	h02 5	8 20) •) (1)	1 (2 8)	,	′—	67	7	2-		07	·	
08 1	1001 R	602 5 602 5	2 23	x (1)	5) 7)	•	5 5	67	7	• ?				
010	Mo01 1	8602 J. Rh02	134	74	(15))		5	, 67	7	?			
03 1	1001 R	b02_1	17.2	21 (16)	<i>′</i> .	• 5	6	77	,				
Rb04	Mo01	Rb02	177	1.3	1(2)		5	67	7	?			
Rb03	Mo01	Rb02	75.	75	1 (1	, 8)	7	6	65	5	5	67	7	?
Rb02	Mo01	Rb02	107	. 8	31(18)	3	46	7	5	6	77	?
07 M	1001 RJ	b01 1	45.3	37 (15)			?			-	_		
08 M	1001 RJ	b01 5	8.17	/(1	7)			?						
010	Mo01 1	Rb01	57.1	0(17)			?						
03 M	1001 RJ	b01 1	03.7	6(15)		•	?						
Rb04	Mo01	Rb01	71.	82	3(1	9)	·	•	?					
Rb03	Mo01	Rb01	70.	19	9(1	7)	7	_6	65			?		
Rb02	Mo01	Rb01	108	3.0	69(19)	3_	46	7	·	?		
Rb02	MOUI	Rb01	106	. 6.	3(2)	5_	67	1	·	3			
07 M	IOUL RI	603 3 603 1	3.42	(1) 2)	5) 17)	·	·	?						
08 1	Mo01 I	003 I. 073 I	20.: 1 2 3) Z (. 61	⊥/) /17	\cdot	·	:	2					
010	MOUL 1 1001 PI	KDU3 603 7	123. 751	(1)	(⊥/ 5))	•	•	÷					
8604	. Mo01	8703 1	100	- (±·	5) 612	``	•	•	2					
Rb03	Mo01	Rb03	100	9.6	291	, 18)	7	66	5		?		
Rb02	Mo01	Rb03	72.	19	6(1	7)	́3	4	67	Č.		?		
Rb02	Mo01	Rb03	71.	80	9(1	8)	5	-6	77			?		
Rb01	Mo01	Rb03	178	3.3	7 (2)	•		?					
04 M	1002 0	11 10	8.5	(2)	7	76	5	7	76	5	?			
04 M	1002 0	12 10	9.8	(2)	7	76	5		?					
011	Mo02 (012 1	09.1	. (2) 7	_7	65	•	?					
04 M	1002 0	1 109	.0(2	2)	7_7	65	6	_6	57	3	?			
011	Mo02 (D1 11	0.7	(2)	7_	76	5	6_	65	7	?			
012	Mo02 (01 10	9.7	(2)	•	6_	65	7	?					
04 M	louz Ri	604 I. 51-04	26.2	29(.	16) (16	<u>,</u> 7	_'/	65	· ·		?			
011	MoU2 I	RDU4	123. 45 (88	(16 14))	′_	/6	5	·	?			
012	MOUZ 1 1002 D1	KDU4 604 6	43.0)4(.	14) 6)	۰.	•	: 7		2				
01 M	1002 N	604 0 603 4	2 90) (± ') (1 '	5) 5)	7-	05 76	5	•	:	55	2		
011	Mo02 10	8603 -	126	12)) (16	<u>`</u> -	70	5 76	5	1	6	55	2	
012	Mo02 1	Rb03	122.	84	(16	ý	<u> </u>	1	65	5	-?		•	
01 M	1002 RJ	b03 6	6.03	3(1	6)	, 6	65	7	1	65	55	?		
Rb04	Mo02	Rb03	103	3.7	, 5 (2) _		1	65	5	?			
04 M	1002 RJ	b01 1	38.3	32 (15)	7	_7	65	•	3	?			
011	Mo02 1	Rb01	57.9	97 (16)	7	_7	65		3	?			
012	Mo02 1	Rb01	53.4	8(16)	•	·	?						
01 M	1002 RJ	b01 1	12.0	55(16)	6	_6	57	•	3	2			
Rb04	Mo02	Rb01	72.	32	9(1	9)	•	·	?					
Rb03	Mo02	Rb01	175	5.8	6(2)	1	65	5	•	?			
04 M	1002 RJ	b02 5	4.50)(1)	6)	'/	76	5	5-	. / .	/ /	?	_	
011	MoU2 I	RDUZ	55.K 120)⊥(. ⊃⊃	16) (14	、 [/] ·	_′	65	כ דד	<u></u>	11	/	2	
012	MOUZ 1 1002 D1	KDUZ	130. 17 (22	(14 16))	•	5 57	// 5	′-	י רי	7	2	
Ph0/	Mo02 RJ	002 I Ph02	179	2 5	10) 6(2	<u>ر</u>	_0	5/	נ רר	7	2	/	:	
Rb03	Mo02	Rb02	76	13	(2)	1	• 6	55	, , 5		• 77	7	?	
Rb01	Mo02	Rb02	107	7.8	$\frac{2}{2}(2)$)	_ `	5	77	7	?	'	•	
04 №	1002 RI	b01 5	6.58	3(1	6)	, 7	, 76	5	7	7.5	55	?		
011	Mo02 1	Rb01	141.	58	(14) —	7	76	5	7	7	55	?	
012	Mo02 1	Rb01	56.9	90 (16)	•	7	7	55	1	2			
01 M	1002 RJ	b01 1	07.0	58 (16)	6	_6	57	7	_7	75	5	?	
Rb04	Mo02	Rb01	74.	14	5(1	7)		7	_7	55	5	?		
Rb03	Mo02	Rb01	70.	05	3(1	7)	1	_6	55	7	/	75	5	?
Rb01	Mo02	Rb01	107	.1	89(18)	·	7_	75	55	?		
Rb02	Mo02	Rb01	107	.0	88(19)	5_	77	7	7	_7	55	?

```
      04 M002 Rb04 122.87(17) 7_765 7_765 ?
      011 Rb01 08 147.90(12) 7_765 . ?

      011 M002 Rb04 37.74(14) 7_765 7_765 ?
      04 Rb01 08 64.82(11) 1_565 . ?

      012 M002 Rb04 123.37(16) . 7_765 ?
      012 Rb01 08 114.78(12) 7_765 . ?

      011 M002 Rb04 72.99(16) 6_657 7_765 ?
      012 Rb01 08 144.78(12) 7_765 . ?

      010 Rb01 Rb02 Rb04 106.581(18) . 7_765 ?
      010 Rb01 08 50.94(11) . . ?

      Rb04 M002 Rb04 109.976(19) 1_655 7_765 ?
      09 Rb01 Rb02 112.70(10) 4_656 . ?

      Rb01 M002 Rb04 72.826(17) . 7_765 ?
      04 Rb01 Rb02 113.71(9) 5_667 . ?

      Rb01 M002 Rb04 72.190(16) 5_777 7_765 ?
      07 Rb01 Rb02 92.47(9) . . ?

      09 M003 02 109.1(2) . . ?
      011 Rb01 Rb02 92.12(8) 1_565 . ?

    Bito Mool Mood 119, 2110, 110, 150, 170, 1765, 1
    Bito Mool And 119, 2112, 1705, 1765, 1
    Bito Mool And 119, 2112, 1755, 1765, 1
    Bito Mool And 110, 2110, 1, 155, 1
    Bito Mool And 110, 1310, 10, 155, 155, 1
    Bito Mool And 110, 1310, 10, 155, 155, 1
    Bito Mool And 110, 1310, 10, 155, 155, 1
    Bito Mool And 110, 1310, 10, 155, 155, 1
    Bito Mool And 110, 1310, 10, 155, 155, 1
    Bito Mool And 110, 1310, 10, 155, 155, 1
    Bito Mool And 110, 1310, 10, 155, 155, 1
    Bito Mool And 110, 1310, 10, 155, 155, 1
    Bito Mool And 110, 1310, 10, 155, 15, 1
    Bito Mool And 110, 1310, 10, 155, 155, 1
    Bito Mool And 110, 1310, 10, 155, 15, 1
    Bito Mool And 110, 1310, 10, 155, 15, 1
    Bito Mool And 110, 1310, 10, 155, 15, 1
    Bito Mool And 110, 1310, 10, 155, 155, 1
    Bito Mool And 110, 1310, 10, 155, 15, 1
    Bito Mool And 110, 1310, 10, 155, 15, 1
    Bito Mool And 110, 1310, 10, 165, 15, 15, 1
    Bito Mool And 110, 1310, 165, 155, 1
    Bito Mool And 110, 1310, 10, 165, 1, 155, 1
    Bito Mool And 110, 1310, 10, 155, 1, 155, 1
    Bito Mool And 110, 1310, 10, 175, 155, 1
    Bito Mool And 110, 1310, 10, 175, 155, 1
    Bito Mool And 110, 1310, 10, 175, 155, 1
    Bito Mool And 110, 1310, 10, 175, 155, 1
    Bito Mool And 111, 134, 110, 1, 155, 155, 1<
```

<text>

```
O11 Rb04 Mo02 94.15(10) . . ?
012 Rb04 Mo02 25.86(9) . . ?
010 Rb04 Mo02 95.54(10) . . ?
O5 Rb04 Mo02 80.60(9) 6 657 .
O6 Rb04 Mo02 81.79(9) 6_657 .
                                 ?
O3 Rb04 Mo02 121.14(8) . ?
O1 Rb04 Mo02 28.29(8) 6_657 . ?
09 Rb04 Mo02 65.07(8) 4 656 . ?
Zn01 Rb04 Mo02 60.078(19) 6_657 . ?
Mo01 Rb04 Mo02 109.85(2) . . ?
O3 Zn01 O1 126.3(2) . . ?
O3 Zn01 O6 110.1(2) . . ?
O1 Zn01 O6 109.5(2) . . ?
O3 Zn01 O5 108.69(19) . . ?
O1 Zn01 O5 103.00(19) . . ?
O6 Zn01 O5 94.28(19) . . ?
O3 Zn01 Rb04 160.92(15) . 6 557 ?
O1 Zn01 Rb04 72.39(15) . 6557 ?
O6 Zn01 Rb04 60.91(14) . 6_557 ?
O5 Zn01 Rb04 58.24(13) . 6_557 ?
O3 Zn01 Rb03 91.80(14) . . ?
O1 Zn01 Rb03 141.46(15) . . ?
O6 Zn01 Rb03 53.29(13) . . ?
05 Zn01 Rb03 52.40(13) . . ?
Rb04 Zn01 Rb03 69.26(2) 6 557 . ?
Mo02 O1 Zn01 162.4(3) 6_557 . ?
Mo02 01 Rb04 87.01(17) 6_557 6_557 ?
Zn01 O1 Rb04 75.78(15) . 6_557 ?
Mo02 O1 Rb03 85.90(17) 6_557 6_657 ?
Zn01 01 Rb03 105.53(19) . 6 657 ?
Rb04 01 Rb03 119.48(14) 6_557 6_657 ?
Mo03 O2 Rb04 150.4(2) . . ?
Mo03 O2 Rb03 102.59(19) . 6 657 ?
Rb04 02 Rb03 91.27(13) . 6 657 ?
Mo01 O3 Zn01 138.1(3) . . ?
Mo01 03 Rb04 89.60(17) . . ?
Zn01 O3 Rb04 115.7(2) . . ?
Mo01 03 Rb03 86.51(16) . 7_665 ?
Zn01 O3 Rb03 105.83(18) . 7_665 ?
Rb04 03 Rb03 120.16(14) . 7_665 ?
Mo02 O4 Rb03 112.0(2) 7 755 7 655 ?
Mo02 O4 Rb01 153.5(2) 7 755 5 667 ?
Rb03 O4 Rb01 93.99(14) 7 655 5 667 ?
Mo02 O4 Rb02 98.80(19) 7 755 3 467 ?
Rb03 O4 Rb02 104.28(15) 7 655 3 467 ?
Rb01 04 Rb02 78.48(12) 5 667 3 467 ?
Mo02 04 Rb01 97.2(2) 7 755 1 545 ?
Rb03 04 Rb01 93.01(13) 7 655 1 545 ?
Rb01 04 Rb01 75.83(11) 5 667 1 545 ?
Rb02 04 Rb01 149.86(16) 3_467 1_545 ?
Mo03 O5 Zn01 121.6(3) . . ?
Mo03 05 Rb03 137.7(2) . . ?
Zn01 05 Rb03 94.75(17) . . ?
Mo03 05 Rb04 113.07(19) . 6 557 ?
Zn01 05 Rb04 87.23(16) . 6 557 ?
Rb03 05 Rb04 87.44(13) . 6 557 ?
Mo03 06 Zn01 123.3(2) 7_665 . ?
Mo03 O6 Rb03 142.3(2) 7 665 . ?
Zn01 06 Rb03 93.84(16) . ?
Mo03 06 Rb04 103.17(19) 7 665 6 557 ?
Zn01 06 Rb04 84.71(15) . 6_557 ?
Rb03 06 Rb04 85.19(12) . 6 557 ?
Mo01 07 Rb03 127.1(2) . . ?
Mo01 07 Rb01 141.7(2) . 3 467 ?
Rb03 07 Rb01 91.14(13) . 3_467 ?
Mo01 07 Rb02 96.3(2) . 3 467 ?
Rb03 07 Rb02 100.70(14) . 3 467 ?
Rb01 07 Rb02 74.89(11) 3 467 3 467 ?
Mo01 07 Rb02 95.4(2) . 5_677 ?
Rb03 07 Rb02 99.09(15) . 5 677 ?
Rb01 07 Rb02 74.88(11) 3 467 5 677 ?
```

Ph02	07	ph02	1/3 0	5 / 1	5١	3	167	5	677	2	
Mo 0 1	07	DP02	110 0	/2) /2)	5)	7-	665	2	- 0 / /	•	
Mo01	00	Ph01	153 7	(2)	·	<u>_</u> _	677	2			
Ph03	00	Ph01	Q1 2Q	(2) (1)	\·-	7 6	65	• 56	77	2	
Mo01	00	Ph02	101 0	(2)	, ,	<u>_</u>	677	20	/ /	•	
PP03	00	RDUZ Rh02	101.9	(2) A (1	۰ 5\	7-	665	: 5	677	2	
RDUS Db01	00	RDUZ	70 12	4 (⊥ /11	5)	; ' <u>-</u>	77	5	77	÷ 2	
KDU1	00	RDUZ	10.13	(11)) ~	_0	2	5_0	//	:	
MOU1	08	RDUI Dh01	95.62	(19) -		: (E	~			
RDU3	08	RDUI	91.75	(13) /	<u> </u>	00	• :			
RDUI	08	RDUI	15.32	(<u> </u>) :	ہ_ہ	//	• ?	~		
Rb02	08	Rb01	149.6	9 (I	5)	5_	677	÷	2		
Mo03	09	Rb01	173.6	(3)	•	4_	646	-?-			
Mo03	09	Rb03	90.48	(18) .	. 6	_65	7 ?		_	
Rb01	09	Rb03	93.68	(13) 4	1_6	46	6_6	57	?	
Mo03	09	Rb04	91.35	(18) .	. 4	_64	6?			
Rb01	09	Rb04	90.53	(12) 4	1_6	46	4_6	46	?	
Rb03	09	Rb04	122.5	0(1	5)	6_	657	4_	646	?	
Mo01	010	Rb04	107.	2 (2) .		?				
Mo01	010	Rb02	157.	6(2) .	. 7	_75	5 ?			
Rb04	010	Rb02	94.7	5(1	4)	•	7_7	55	?		
Mo01	010	Rb02	100.	0(2) .	. 3	46	7 ?			
Rb04	010	Rb02	100.	75(14)	•	3_	467	?		
Rb02	010	Rb02	79.7	7(1	2)	7_	755	3_	467	?	
Mo01	010	Rb01	. 96.6	5(1	9)	•	. ?				
Rb04	010	Rb01	93.6	2(1	4)		. ?				
Rb02	010	Rb01	77.0	9(1	2)	7	755		?		
Rb02	010	Rb01	153.	63 (16)	3	46	7.	?		
Mo02	011	Rb04	120.	0(2) 7	77	55	. ?			
Mo02	011	Rb02	147.	0(2) 7	77	55	77	55	?	
Rb04	011	Rb02	92.9	0(1	2)	•	77	55	?		
Mo02	011	Rb02	97.5	3(1	8)	7	755	3	467	?	
Rb04	011	Rb02	100.	00 (14)	• •	3	467	?		
Rb02	011	Rb02	77.6	1(1	1)	7	755	3	467	?	
Mo02	011	Rb01	94.9	2(1	8)	7	755	7	755	?	
Rb04	011	Rb01	99.4	0(1	3)	. –	77	55	?		
Rb02	011	Rb01	75.6	7(1	0)	7	755	7	755	?	
Rb02	011	Rb01	147.	56(15)	3	46	7 7	75	5?	
Mo02	012	Rb04	109.	10 (19)			?	-		
Mo02	012	Rb02	156.	3 (2) .	. 7	75	5 ?			
Rb04	012	Rb02	94.3) (1	4)	•	77	55	?		
Mo02	012	Rb01	. 99.6	4 (1	9)		. ?				
Rb04	012	Rb01	97.8	6 (1	4)		. ?				
Rb02	012	Rb01	80.0	2 (1	2)	7	755		?		
Mo02	012	Rb01	96.6	6 (1	9)		77	55	?		
Rb04	012	Rb01	98.0	7 (1	3)		77	55	?		
Rb02	012	Rb01	75.9	7 (1	0)	7	755	7	755	?	
Rb01	012	Rb01	152.	02(15)	_	7	755	?		
				```	- /	•	-		-		
dift	Ern	measu	red f	rac	tic	on	the	ta	max		1.000
dift	frn	refln	is the	ta	ful	 L1		_	-		30.02
dift	frn	measu	ired f	rac	tic	on	the	ta	fu]	1	1.000
refi	ine_	diff	densi	ty	max	< —	2	.49	5		
	-						_		-		

refine diff density min

_refine_diff_density_rms

-1.940

0.317

### A5.3 Orthorhombic Rb₄Cu(MoO₄)₃

```
data dixie78
_audit_creation_method
 SHELXL-97
_chemical_name_systematic
;
 ?
;
_chemical_name common
 ?
?
 'Rb<sub>4</sub>Cu (MoO<sub>4</sub>) 3'
 'Cu Mo3 012 Rb4'
_chemical formula weight
 885.24
loop
 _atom_type_symbol
 _atom_type_description
 _atom_type_scat_dispersion real
 _atom_type_scat_dispersion_imag
 _atom_type_scat_source
'0' '0' 0.0106 0.0060
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
 'Cu' 'Cu' 0.3201 1.2651
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
 'Rb' 'Rb' -0.9393 2.9676
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
 'Mo' 'Mo' -1.6832 0.6857
 'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
_symmetry_cell_setting
 'orthorhombic'
'Pnma'
loop
 _symmetry_equiv_pos_as_xyz
 -<sup>Symma</sup>
'x, y, z'
 '-x+1/2, -y, z+1/2'
 'x+1/2, -y+1/2, -z+1/2'
 '-x, y+1/2, -z'
 '-x, -y, -z'
 'x-1/2, y, -z-1/2'
 '-x-1/2, y-1/2, z-1/2'
'x, -y-1/2, z'
_cell_length_a
 10.581(2)
_cell_length_b
_cell_length_c
 23.213(4)
 6.0780(10)
_cell_angle_alpha
 90.00
_cell_angle_beta
_cell_angle_gamma
 90.00
 90.00
1492.9(5)
_cell_formula_units_Z
 4
_cell_measurement_temperature
 298(2)
 cell_measurement_reflns_used
 ?
_cell_measurement_theta_min
 ?
_cell_measurement_theta_max
 ?
_exptl_crystal_description
 'plate-shaped fragment'
_exptl_crystal_colour
 'blue green'
_exptl_crystal_size_max
_exptl_crystal_size_mid
 0.17
 0.15
_exptl_crystal_size_min
 0.08
_exptl_crystal_density_meas
 ?
_exptl_crystal_density_diffrn
_exptl_crystal_density_method
 3.939
 'not measured'
_exptl_crystal_F_000
 1596
_exptl_absorpt_coefficient_mu
_exptl_absorpt_correction_type
 16.872
 ?
```

```
exptl absorpt correction T min 0.1562
_exptl_absorpt_correction_T_max 0.3643
exptl absorpt process details
 ?
exptl special details
;
 ?
;
_diffrn_ambient_temperature
 298(2)
diffrn radiation wavelength
 0.71073
_diffrn_radiation_type
 MoK∖a
_diffrn_radiation_source
 'fine-focus sealed tube'
 diffrn radiation monochromator
 graphite
_diffrn_measurement_device_type
 'KappaCCD'
_diffrn_measurement_method
 '

 w scans

 k offsets'
 diffrn detector area resol mean
0
_diffrn_standards_interval count
 ?
_diffrn_standards_interval_time
 ?
diffrn_standards_decay_%
 none
diffrn reflns number
 3948
_diffrn_reflns_av_R_equivalents
 0.0295
diffrn_reflns_av_sigmal/netI
diffrn_reflns_limit_h_min
 0.0401
 -14
diffrn reflns limit h max
 14
_diffrn_reflns_limit_k_min
diffrn_reflns_limit_k_max
 -32
 32
diffrn reflns limit 1 min
 -8
_diffrn_reflns_limit_l_max
 8
 diffrn reflns theta min
 3.46
30.02
_reflns_number_total
 2222
_reflns_number_gt
 1582
reflns threshold expression
 >2sigma(I)
_computing_data_collection
 'COLLECT (Nonius, 2000)'
_computing_cell_refinement
 'Denzo and Scalepack (Otwinowski & Minor, 1997)'
computing data reduction
 'Denzo and Scalepack (Otwinowski & Minor, 1997)'
computing structure solution
 'SHELXS-97 (Sheldrick, 1990)'
 'SHELXL-97 (Sheldrick, 1997)'
_computing_structure_refinement
 computing molecular_graphics
 2
_computing_publication material
 'SHELXL-97 (Sheldrick, 1997)'
refine special details
 Refinement of {\rm F}^2{\rm ^{\rm a}} against ALL reflections. The weighted R-factor wR and
 goodness of fit S are based on F^{2}, conventional R-factors R are based
 on F, with F set to zero for negative F^{2^{-}}. The threshold expression of
 F^2^> 2sigma(F^2^>) is used only for calculating R-factors(gt) etc. and is
 not relevant to the choice of reflections for refinement. R-factors based
 on F^2^ are statistically about twice as large as those based on F, and R-
 factors based on ALL data will be even larger.
;
_refine_ls_structure_factor_coef Fsqd
 refine ls matrix type
 full
refine_ls_weighting_scheme
 calc
_refine_ls_weighting_details
 v_{calc} w=1/[\s^2^{(Fo^2^)+(0.0207P)^2+31.5979P]} where P=(Fo^2^+2Fc^2)/3'
_atom_sites_solution_primary
 direct
atom sites solution secondary
 difmap
_atom_sites_solution_hydrogens
 geom
_refine_ls_hydrogen_treatment
 none
refine ls extinction method
 SHELXL
refine ls extinction coef
 0.00084(11)
_refine_ls_extinction_expression
_'Fc^*^=kFc[1+0.001xFc^2^\l^3/sin(2\q)]^-1/4^'
_refine_ls number reflns
 2222
_refine_ls_number_parameters
 107
_refine_ls_number_restraints
 0
refine ls R factor all
 0.0729
```

```
109
```

```
refine ls R factor gt
 0.0508
refine ls wR factor ref
 0.1188
refine_ls_wR_factor_gt
 0.1103
_refine_ls_goodness_of_fit_ref
 1.052
_refine_ls_restrained_S_all
 1.052
_refine_ls_shift/su_max
 0.001
refine ls shift/su mean
 0.000
loop
 _atom_site label
 atom site type symbol
_atom_site_fract x
_atom_site_fract_y
 atom site fract z
 _atom_site_U_iso_or equiv
_atom_site_adp_type
_atom_site_occupancy
 _atom_site_symmetry_multiplicity
_atom_site_calc flag
_atom_site_refinement_flags
 _atom_site_disorder assembly
 atom site disorder group
Mol Mo 0.00050(6) 0.59262(2) 0.50809(10) 0.01809(17) Uani 1 1 d . . .
Mo2 Mo 0.16952(16) 0.73000(6) 0.9616(3) 0.0285(3) Uani 0.48 1 d P . .
Rb1 Rb 0.33338(8) 0.47125(3) 0.50086(12) 0.0258(2) Uani 1 1 d . . .
Rb2 Rb 0.33349(10) 0.66056(3) 0.47298(16) 0.0378(2) Uani 1 1 d . . .
Cul Cu 0.00041(14) 0.2500 0.5088(2) 0.0223(3) Uani 1 2 d S . .
01 0 0.4181(6) 0.5647(3) 0.2159(10) 0.0361(15) Uani 1 1 d . . .
02 0 0.4590(12) 0.2500 0.603(3) 0.075(4) Uani 1 2 d S . .
O3 O 0.4280(7) 0.5690(3) 0.7497(11) 0.0410(16) Uani 1 1 d . . .
04 0 -0.0003(8) 0.6692(3) 0.4940(14) 0.054(2) Uani 1 1 d . . .
O5 O 0.1542(6) 0.5672(3) 0.5002(11) 0.0388(15) Uani 1 1 d . . .
06 0 0.8410(11) 0.2500 0.325(2) 0.057(3) Uani 1 2 d S . .
07 0 0.6865(11) 0.2500 0.927(2) 0.070(4) Uani 1 2 d S . .
08 0 0.1736(13) 0.6559(5) 0.983(2) 0.044(4) Uani 0.51 1 d P . .
loop
 _atom_site_aniso label
 atom site aniso U 11
_atom_site_aniso_U_22
_atom_site_aniso_U_33
 atom site aniso U
 23
_atom_site_aniso_U_13
 atom site aniso U 12
M_{01} 0.0208(3) 0.0120(3) 0.0215(3) 0.0003(2) -0.0009(3) -0.0003(2)
Mo2 0.0306(7) 0.0183(5) 0.0367(9) -0.0010(5) -0.0027(7) 0.0000(5)
Rb1 0.0263(4) 0.0255(4) 0.0255(3) 0.0008(3) 0.0022(3) -0.0005(3)
Rb2 0.0461(5) 0.0228(4) 0.0445(5) -0.0002(3) 0.0065(5) -0.0011(4)
Cul 0.0269(6) 0.0118(5) 0.0281(6) 0.000 -0.0024(6) 0.000
01 0.040(3) 0.030(3) 0.038(3) 0.003(3) 0.017(3) -0.005(3)
02 0.053(7) 0.084(10) 0.089(10) 0.000 -0.007(7) 0.000
03 0.044(4) 0.041(4) 0.038(3) -0.007(3) -0.015(3) 0.000(3)
04 0.065(5) 0.010(2) 0.087(6) 0.000(3) -0.022(5) -0.012(3)
05 0.024(3) 0.037(3) 0.056(4) 0.004(3) 0.002(3) 0.006(3)
06 0.046(6) 0.061(7) 0.063(7) 0.000 -0.013(6) 0.000
07 0.034(6) 0.091(10) 0.083(9) 0.000 -0.017(6) 0.000
08 0.038(7) 0.020(6) 0.073(10) 0.011(6) -0.002(8) -0.009(5)
_geom_special_details
;
 All esds (except the esd in the dihedral angle between two l.s. planes)
 are estimated using the full covariance matrix. The cell esds are taken
 into account individually in the estimation of esds in distances, angles
 and torsion angles; correlations between esds in cell parameters are only
 used when they are defined by crystal symmetry. An approximate (isotropic)
 treatment of cell esds is used for estimating esds involving l.s. planes.
;
loop
 _geom_bond_atom_site_label 1
 geom bond atom site label 2
geom bond distance
```

_geom_bond_site_symmetry 2 geom bond publ flag Mol 05 1.731(6) · ? Mo1 01 1.741(6) 6 556 ? Mo1 O3 1.748(6) 6_557 ? Mol 04 1.780(6) . ? Mo1 Rb2 3.7629(12) 6 556 ? Mo1 Rb1 3.7759(11) 2 565 ? Mol Rb1 3.8316(12) 5 566 ? Mo1 Rb1 3.8460(11) 2_564 ? Mo1 Rb2 3.8661(14) . ? Mo1 Rb2 3.9443(13) 6 557 ? Mo2 Mo2 0.929(3) 8 575 ? Mo2 O2 1.674(13) 2_565 ? Mo2 O8 1.726(11) . ? Mo2 07 1.730(11) 5 667 ? Mo2 06 1.805(12) 5_666 ? Mo2 Rb2 3.798(2) . ? Mo2 Rb2 3.908(2) 1 556 ? Mo2 Rb2 3.924(2) 6 557 ? Mo2 Rb2 4.2761(19) 8 575 ? Rb1 03 2.905(6) . ? Rb1 01 2.918(6) . ? Rb1 05 2.926(6) . ? Rb1 08 2.954(11) 2 564 ? Rb1 01 3.080(7) 2 565 ? Rb1 O3 3.093(7) 5_666 ? Rb1 05 3.166(7) 2 565 ? Rb1 05 3.174(7) 2 564 ? Rb1 01 3.252(7) 5 666 ? Rb1 O3 3.294(7) 2_564 ? Rb1 Rb1 3.7591(10) 2 565 ? Rb1 Rb1 3.7591(10) 2_564 ? Rb2 01 2.862(6) . ? Rb2 05 2.884(7) . ? Rb2 O3 2.889(7) . ? Rb2 06 3.038(9) 5 666 ? Rb2 02 3.057(10)  $\overline{5}$  666 ? Rb2 07 3.205(11) 5 666 ? Rb2 04 3.345(8) 6 656 ? Rb2 08 3.425(15) 1_554 ? Rb2 08 3.535(15) . Rb2 04 3.540(9) . ? Rb2 08 3.610(14) 6 657 ? Rb2 Mo1 3.7629(12) 6 656 ? Cu1 04 1.876(6) 4 546 ? Cul 04 1.876(6) 5 566 ? Cul 07 2.007(12) 6_557 ? Cu1 06 2.023(11) 1 455 ? Cul 02 2.400(15) 6 557 ? Cu1 Rb2 3.9191(15) 2 565 ? Cu1 Rb2 3.9191(15) 7_656 ? Cu1 Rb2 4.0994(17) 4_546 ? Cul Rb2 4.0994(17) 5 566 ? Cu1 Rb2 4.2433(16) 7_655 ? Cul Rb2 4.2433(16) 2 564 ? O1 Mo1 1.741(6) 6 656 ? O1 Rb1 3.080(7) 2 564 ? O1 Rb1 3.252(7) 5_666 ? O2 Mo2 1.674(13) 7_655 ? O2 Mo2 1.674(13) 2 564 ? O2 Cu1 2.400(15) 6_657 ? 02 Rb2 3.057(10) 5 666 ? 02 Rb2 3.057(10) 4 646 ? O3 Mo1 1.748(6) 6 657 ? O3 Rb1 3.093(7) 5_666 ? O3 Rb1 3.294(7) 2_565 ? O4 Cu1 1.876(6) 5 566 ? O4 Rb2 3.345(8) 6_556 ? O5 Rb1 3.166(7) 2_564 ? O5 Rb1 3.174(7) 2_565 ?

O6 Mo2 1.805(12) 4 646 ? O6 Mo2 1.805(12) 5_666 ? 06 Cu1 2.023(11) 1 655 ? O6 Rb2 3.038(9) 4_646 ? O6 Rb2 3.038(9) 5 666 ? 07 Mo2 1.730(11) 5 667 ? O7 Mo2 1.730(11) 4_647 ? 07 Cu1 2.007(12) 6 657 ? 07 Rb2 3.205(11) 4 646 ? 07 Rb2 3.205(11) 5_666 ? 08 Rb1 2.954(11) 2_565 ? 08 Rb2 3.425(15) 1 556 ? 08 Rb2 3.610(14) 6 557 ? loop_ _geom_angle_atom_site_label_1 _geom_angle_atom_site_label_2 _geom_angle_atom_site_label 3 _geom_angle _geom_angle_site_symmetry 1 _geom_angle_site_symmetry_3 geom angle publ flag 05 Mol 01 108.8(3) . 6_556 ? O5 Mo1 O3 109.2(3) . 6 557 ? O1 Mo1 O3 108.8(3) 6_556 6_557 ? O5 Mo1 O4 110.1(4) . . ? O1 Mo1 O4 109.3(3) 6 556 . ? O3 Mo1 O4 110.6(4) 6_557 . ? O5 Mo1 Rb2 124.2(2) . 6 556 ? O1 Mo1 Rb2 46.6(2) 6 556 6 556 ? O3 Mo1 Rb2 125.4(2) 6 557 6 556 ? O4 Mo1 Rb2 62.7(3) . 6 556 ? O5 Mo1 Rb1 56.7(2) . 2 565 ? O1 Mo1 Rb1 135.0(2) 6 556 2 565 ? O3 MO1 Rb1 54.1(2) 6_557 2_565 ? O4 MO1 Rb1 115.6(3) . 2_565 ? Rb2 MO1 Rb1 178.21(2) 6_556 2_565 ? O5 Mo1 Rb1 137.3(2) . 5 566 ? O1 Mo1 Rb1 51.9(2) 6_556 5_566 ? O3 Mo1 Rb1 59.1(2) 6_557 5_566 ? O4 Mo1 Rb1 112.4(3) . 5 566 ? Rb2 Mo1 Rb1 73.63(2) 6_556 5_566 ? Rb1 Mo1 Rb1 106.77(2) 2 565 5 566 ? O5 Mo1 Rb1 54.3(2) . 2 564 ? O1 Mo1 Rb1 57.2(2) 6 556 2 564 ? O3 Mo1 Rb1 139.0(2) 6_557 2_564 ? O4 Mo1 Rb1 110.4(3) . 2 564 ? Rb2 Mo1 Rb1 75.72(3) 6 556 2 564 ? Rb1 Mo1 Rb1 105.77(3) 2 565 2 564 ? Rb1 Mo1 Rb1 105.12(2) 5 566 2 564 ? 05 Mol Rb2 44.0(2) . . ? O1 Mo1 Rb2 124.4(2) 6 556 . ? O3 Mo1 Rb2 125.0(2) 6_557 . ? O4 Mo1 Rb2 66.1(3) . . ? Rb2 Mo1 Rb2 102.36(2) 6 556 . ? Rb1 Mo1 Rb2 77.27(2) 2 565 . ? Rb1 Mo1 Rb2 175.80(3) 5 566 . ? Rb1 Mo1 Rb2 72.33(2) 2_564 . ? O5 Mo1 Rb2 125.4(2) . 6 557 ? O1 Mo1 Rb2 123.3(2) 6 556 6 557 ? O3 Mo1 Rb2 41.9(2) 6_557 6_557 ? O4 Mo1 Rb2 68.7(3) . 6_557 ? Rb2 Mo1 Rb2 104.09(3) 6_556 6 557 ? Rb1 Mo1 Rb2 74.41(2) 2 565 6 557 ? Rb1 Mo1 Rb2 75.70(2) 5 566 6 557 ? Rb1 Mo1 Rb2 179.02(2) 2 564 6 557 ? Rb2 Mo1 Rb2 106.82(2) . 6 557? Mo2 Mo2 O2 73.89(14) 8 575 2 565 ? Mo2 Mo2 O8 175.4(5) 8 575 . ? O2 Mo2 O8 104.9(5) 2_565 . ? Mo2 Mo2 O7 74.43(12) 8 575 5 667 ?

 03
 Rb1
 05
 68.22(19)
 .
 ?

 01
 Rb1
 05
 68.39(18)
 .
 ?

 03
 Rb1
 08
 143.9(3)
 .
 2_564
 ?

 01
 Rb1
 08
 136.8(3)
 .
 2_564
 ?

 03
 Rb1
 08
 138.1(3)
 .
 2_564
 ?

 03
 Rb1
 01
 106.79(19)
 .
 .
 2_565
 ?

 04
 Pb1
 01
 135
 26(10)
 .
 .
 2_565
 ?

O1 Rb2 O2 102.7(2) . 5_666 ? O5 Rb2 O2 172.4(3) . 5_666 ?

00 (kb 2 04 59.5 (k) . . ? (kb 2 04 52.5 (k)

 Rb2 07 Rb2 80.7(3) 4_646 5_666 ?

 Mo2 08 Rb1 176.3(8) . 2_565 ?

 Mo2 08 Rb2 92.7(5) . 1_556 ?

 Rb1 08 Rb2 90.7(3) 2_565 1_556 ?

 Mo2 08 Rb2 85.1(5) . . ?

 Rb1 08 Rb2 94.3(4) 2_565 . ?

 Rb2 08 Rb2 121.7(4) 1_556 . ?

 Mo2 08 Rb2 87.2(5) . 6_557 ?

 Rb1 08 Rb2 90.1(3) 2_565 6_557 ?

 Rb2 08 Rb2 115.3(4) 1_556 6_557 ?

 Rb2 08 Rb2 122.7(4) . 6_557 ?

 diffrn_measured_fraction_theta_max

 __diffrn_measured_fraction_theta_full

 __diffrn_measured_fraction_theta_full

 __diffrn_measured_fraction_theta_full

 __diffrn_measured_fraction_theta_full

 __diffrn_measured_fraction_theta_full

 __refine_diff_density_max
 2.333

 __refine_diff_density_rms
 0.228

### **APPENDIX 6 – LETTERS OF PERMISSION**

#### 04/24/2008 15:31 FAX 2027768112

2001/002



TO

Publications Division Copyright Office

VIA FAX: 225-578-3458 DATE: April 24, 2008

1155 Sixteenih Street. NW Washington. DC 20036 Phone: (1) 202-872-4368 or -4367 Fax: (1) 202-776-8112 E-mail: copyright@acs.org

American Chemical Society

232 Choppin Hall, Baton Rouge, LA 70803-1804 FROM: C. Arleen Courtney, Copyright Associate C. Chlue Courtney,

Dixie Gautreaux, Department of Chemistry, Louisiana State University

Thank you for your request for permission to include your paper(s) or portions of text from your paper(s) in your thesis. Permission is now automatically granted; please pay special attention to the implications paragraph below. The Copyright Subcommittee of the Joint Board/Council Committees on Publications approved the following:

Copyright permission for published and submitted material from theses and dissertations ACS extends blanket permission to students to include in their theses and dissertations their own articles, or portions thereof, that have been published in ACS journals or submitted to ACS journals for publication, provided that the ACS copyright credit line is noted on the appropriate page(s).

Publishing implications of electronic publication of theses and dissertation material Students and their mentors should be aware that posting of theses and dissertation material on the Web prior to submission of material from that thesis or dissertation to an ACS journal <u>may</u> affect publication in that journal. Whether Web posting is considered prior publication may be evaluated on a case-by-case basis by the journal's editor. If an ACS journal editor considers Web posting to be "prior publication", the paper will not be accepted for publication in that journal. If you intend to submit your unpublished paper to ACS for publication, check with the appropriate editor prior to posting your manuscript electronically.

If your paper has not yet been published by ACS, we have no objection to your including the text or portions of the text in your thesis/dissertation in print and microfilm formats; please note, however, that electronic distribution or Web posting of the unpublished paper as part of your thesis in electronic formats might jeopardize publication of your paper by ACS. Please print the following credit line on the first page of your article; "Reproduced (or 'Reproduced in part') with permission from [JOURNAL NAME], in press (or 'submitted for publication'). Unpublished work copyright [CURRENT YEAR] American Chemical Society." Include appropriate information.

If your paper has already been published by ACS and you want to include the text or portions of the text in your thesis/dissertation in print or microfilm formats, please print the ACS copyright credit line on the first page of your article: "Reproduced (or 'Reproduced in part') with permission from [FULL REFERENCE CITATION.] Copyright [YEAR] American Chemical Society." Include appropriate information.

Submission to a Dissertation Distributor: If you plan to submit your thesis to <u>UMI or to another dissertation</u> <u>distributor</u>, you should not include the unpublished ACS paper in your thesis if the thesis will be disseminated electronically, until ACS has published your paper. After publication of the paper by ACS, you may release the <u>entire</u> thesis (not the individual ACS article by itself) for electronic dissemination through the distributor; ACS's copyright credit line should be printed on the first page of the ACS paper.

Use on an Intranet: The inclusion of your ACS unpublished or published manuscript is permitted in your thesis in print and microfilm formats. If ACS has published your paper you may include the manuscript in your thesis on an intranet that is not publicly available. Your ACS article cannot be posted electronically on a publicly available medium (i.e. one that is not password protected), such as but not limited to, electronic archives, Internet, hbrary server, etc. The only material from your paper that can be posted on a public electronic medium is the article abstract, figures, and tables, and you may link to the article's DOI or post the article's author-directed URL link provided by ACS. This paragraph docs not pertain to the dissertation distributor paragraph above.



Dixle P. Gatreaux PhD Candidate Department of Chemistry Louisiana State University 232 Choppin Hall Baton Rouge LA 70603-1804 USA

25 April 2008

### **Copyright Permission**

Dear Dixie

Permission is hereby granted, on behalf of the IUCr, for the reproduction of the material specified In your email subject to the following conditions.

- 1. Reproduction is intended in a primary journal, secondary journal, CD-ROM, book or thesis.
- 2. The original article in which the material appeared is cited.
- IUCr's copyright permission is indicated in print. In electronic form, this acknowledgement must be hyperlinked to Crystallography Journals Online (<u>http://iournals.lucr.org/</u>).

Material to be reproduced:

Title: The Layered Intermatallic Compound LaPdSb₃ Journal: Acta Crystallographica Section E Structural Reports Online Year: 2006 Volume: E62 Pages: 196-198

Yours sincerely

Peter Strickland Managing Editor

Managing Editor: Mr P. R. Strickland, 5 Abbey Square, Chester CH1 2HU, England Telephone: 44 1244 342878 Fax: 44 1244 314888 E-mail: med@iucr.org

Kryssa Roycroft/IOPP	То	Permissions/IOPP@IOPP
25/04/2008 08:40	cc	
	bcc	
	Subject	Fw: Signed Permissions Letter

----- Forwarded by Kryssa Roycroft/IOPP on 25/04/2008 08:40 -----



 "Dixle Gautreaux"
 To

 <dgautr4@isu.edu>
 To

 Sent by: dgautr4@gmail.com
 cc

 24/04/2008 14:42
 Subject
 Signed Permissions Letter

To Whom It May Concern:

I am writing to request a signed letter granting permission to use material from a paper published in the Journal of Physics: Condensed Matter. I am an author of this paper and the citation is as follows:

Karki, A.B., Gautreaux, D.P., Chan, J.Y., Harrison, N., Browne, D.A., Goodrich, R.G., Young, D.P. J. Phys: Condens. Matter 2008, 20, 035209 (5pp).

I am requesting the use of portions of the text refering to the single crystal structure determination. This material will be placed in my dissertation.

Please fax or mail the letter to the address listed below.

Thank you very much.

Dixie P. Gautreaux PhD Candidate Department of Chemistry Louisiana State University 232 Choppin Hall Baton Rouge, LA 70803-1804 Fax: (225)578-3458

PERMISSION TO REPRODUCE AS REQUESTED IS GIVEN PROVIDED THAT:

(a) the consent of the author(s) is obtained

(b) the source of the material including author/editor, title, date and publisher is acknowledged (4)

IOP Publishing Ltd Dirac House Temple Back BRISTOL

25/4/08 VRC

Dease victude mention of the journal's homepage at: <u>www.iop.org/journals/jpcm</u> and provide a link back to the attacks abstract on our website from the electronic version of your theoris (if appropriate). Whank you',

### ELSEVIER LIMITED LICENSE TERMS AND CONDITIONS

This is a License Agreement between Dixie P Gautreaux ("You") and Elsevier Limited ("Elsevier Limited"). The license consists of your order details, the terms and conditions provided by Elsevier Limited, and the payment terms and conditions.

**Elsevier Limited** 

Supplier

	The Boulevard,Langford Lane Kidlington,Oxford,OX5 1GB,UK
Registered Company Number	1982084
Customer name	Dixie P Gautreaux
Customer address	Louisiana State University
	Baton Rouge, LA 70803
License Number	1916550968681
License date	Mar 26, 2008
Licensed content publisher	Elsevier Limited
Licensed content publication	Physica B: Condensed Matter
Licensed content title	Magnetization and transport properties of $\alpha\text{-}$ CeNi_{0.78}Co_{0.22}Sb_3
Licensed content author	Gautreaux Dixie P., Parent Michael, Moldovan Monica, Young David P. and Chan Julia Y.
Licensed content date	1 April 2008
Volume number	403
Issue number	5-9
Pages	2
Type of Use	Thesis / Dissertation
Portion	Full article
Format	Both print and electronic
You are an author of the Elsevier article	Yes
Are you translating?	No
Purchase order number	
Expected publication date	Aug 2008
Elsevier VAT number	GB 494 6272 12
Permissions price	0.00 USD
Value added tax 0.0%	0.0 USD
Total	0.00 USD
Terms and Conditions	

https://s100.copyright.com/CustomerAdmin/PLF.jsp?IID=2008031_1206544928681 (1 of 5)5/21/2008 11:19:40 AM

### INTRODUCTION

The publisher for this copyrighted material is Elsevier. By clicking "accept" in connection with completing this licensing transaction, you agree that the following terms and conditions apply to this transaction (along with the Billing and Payment terms and conditions established by Copyright Clearance Center, Inc. ("CCC"), at the time that you opened your Rightslink account and that are available at any time at <a href="http://myaccount.copyright.com">http://myaccount.copyright.com</a>).

### GENERAL TERMS

Elsevier hereby grants you permission to reproduce the aforementioned material subject to the terms and conditions indicated.

Acknowledgement: If any part of the material to be used (for example, figures) has appeared in our publication with credit or acknowledgement to another source, permission must also be sought from that source. If such permission is not obtained then that material may not be included in your publication/ copies. Suitable acknowledgement to the source must be made, either as a footnote or in a reference list at the end of your publication, as follows:

"Reprinted from Publication title, Vol number, Author(s), Title of article, Pages No., Copyright (Year), with permission from Elsevier [OR APPLICABLE SOCIETY COPYRIGHT OWNER]." Also Lancet special credit - "Reprinted from The Lancet, Vol. number, Author(s), Title of article, Pages No., Copyright (Year), with permission from Elsevier."

Reproduction of this material is confined to the purpose and/or media for which permission is hereby given.

**Thesis/Dissertation**: If your license is for use in a thesis/dissertation your thesis may be submitted to your institution in either print or electronic form. Should your thesis be published commercially, please reapply for permission. These requirements include permission for the Library and Archives of Canada to supply single copies, on demand, of the complete thesis and include permission for UMI to supply single copies, on demand, of the complete thesis. Should your thesis be published commercially, please reapply for permission.

### VITA

Dixie Plaisance Gautreaux was born in April 1982, in Lockport, Louisiana, to her parents Joey and Kate Plaisance. She is the wife of Jarred Gautreaux of Lockport, Louisiana, and mother of Elise Reneé. She has one younger sister, Josie Plaisance Eschete. In May 2000, Dixie graduated sixth in her class from Central Lafourche High School in Mathews, Louisiana. Dixie received numerous academic and music scholarships to universities throughout the state. She attended Tulane University in New Orleans, Louisiana on a full Legislative scholarship from August 2000-May 2001, where she majored in chemistry and was a member of the Tulane Symphonic Winds and Green Wave Basketball Band. In August, 2001, she transferred to Nicholls State University in Thibodaux, Louisiana, where she majored in chemistry and was the president of the Nicholls Chemical Sciences Society. She was also a member of the NSU Concert Band, Symphonic Winds, and the Pride of NSU Marching Band. She received a Bachelor of Science in chemistry (*cum laude*) from Nicholls State University in December 2003.

Dixie began her graduate career at Louisiana State University in August, 2004, and received a Louisiana Board of Regents Fellowship. She joined the Chan group in January 2005, and began her doctoral research on ternary rare earth antimonides. She attended and presented posters at national scientific meetings: the 24th Rare Earth Research Conference in Keystone, Colorado, the 232nd ACS National Meeting & Exposition in San Francisco, California, and the International Conference on Strongly Correlated Electron Systems in Houston, Texas. In 2006, she was chosen to be a member of the US delegation at the 56th Meeting of the Nobel Laureates and Students in Lindau, Germany. In 2007, she was awarded a Strongly Correlated Electron Systems Conference Award. She was awarded another Proctor and Gamble Research award in 2008. She was an officer on the

2005-2006 Chemistry Graduate Student Council. She was also very active in the department's service learning program where she visited nearby schools and performed chemistry demonstrations for the students.

Dixie will graduate from Louisiana State University on August 8, 2008, with a Doctor of Philosophy degree in chemistry. She has chosen a career in academics where she can teach and inspire young minds for years to come.